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PYROLYSIS OF MONO- AND DIMETHYLSILANE

by



PAVEL SLAVOMIR NEUDORFL

A THESIS

SUBMITTED TO THE FACULTY OF GRADUATE STUDIES AND RESEARCH  
IN PARTIAL FULFILMENT OF THE REQUIREMENTS FOR THE DEGREE  
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The undersigned certify that they have read,  
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PYROLYSIS OF MONO- AND DIMETHYLSILANE

submitted by

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in partial fulfilment of the requirements for the degree  
of Doctor of Philosophy.





## ABSTRACT

The initial stages of the pyrolysis of monomethylsilane have been investigated between 340 and 440°C in the pressure range 40 - 400 torr. The major products are hydrogen and 1,2-dimethyldisilane (DMDS) and the minor products are dimethylsilane (DMS) and polymer. The rate of decomposition is strongly dependent on the nature of the reactor surface. In the presence of ca. 10% ethylene the yields of H<sub>2</sub> and DMDS are greatly reduced and DMS is not formed. Under these conditions the only observable reaction is homogeneous unimolecular elimination of H<sub>2</sub> to form silylene,  $\text{CH}_3\text{SiH}_3 \xrightarrow{1} \text{CH}_3\text{SiH:} + \text{H}_2$ , followed by insertion of silylene into the substrate to form DMDS. The rate parameters for reaction (1) are  $\log k_1(\text{s}^{-1}) = (14.95 \pm 0.11) - (63,200 \pm 330)/2.3RT$  from which  $\Delta H_f^\circ(\text{CH}_3\text{SiH:}) \approx 53 \text{ kcal/mol}$  and  $D(\text{CH}_3\text{SiH-H}) \approx 69 \text{ kcal/mol}$ . The preexponential factor is consistent with a three centered transition state. In parallel and in competition with the molecular reaction (1), heterogeneous Si-H cleavage also takes place,  $\text{CH}_3\text{SiH}_3 \xrightarrow{2} \text{CH}_3\text{SiH}_2^\bullet + \text{H}^\bullet$ , followed by a chain mechanism propagated by H<sup>•</sup> and  $\text{CH}_3\text{SiH}_2^\bullet$  and terminated by  $\text{CH}_3\text{SiH}_2^\bullet$  radicals. The average chain length is about 10<sup>6</sup>.





The pyrolysis of dimethylsilane was also briefly investigated between 440 and 500°C and 41 - 395 torr. The yields of the major products, H<sub>2</sub> and 1,1,2,2-tetramethyldisilane (TMDS), and particularly those of the minor products, monomethyl- and trimethylsilane (MMS,TMS) are surface-dependent. Ethylene has no apparent effect on the rates of formation of H<sub>2</sub> and TMDS but suppresses those of MMS and TMS. A reaction mechanism similar to that proposed for the pyrolysis of monomethylsilane is assumed to take place, involving molecular,  $(\text{CH}_3)_2\text{SiH}_2 \xrightarrow{01} (\text{CH}_3)_2\text{Si:} + \text{H}_2$  and radical,  $(\text{CH}_3)_2\text{SiH}_2 \xrightarrow{02} (\text{CH}_3)_2\text{SiH}^\bullet + \text{H}^\bullet$  primary steps. The rate parameters for the molecular reaction are  $\log k_{01}(\text{s}^{-1}) = (14.3 \pm 0.3) - (68,000 \pm 1,000)/(2.3 \text{ RT})$  from which  $D((\text{CH}_3)_2\text{Si-H}) \sim 74 \text{ kcal/mol}$  and  $\Delta H_f^0((\text{CH}_3)_2\text{Si:}) \sim 44 \text{ kcal/mol}$ . The detailed processes occurring in the chain propagation and termination reactions could not be fully elucidated but it appears that reaction (02) is also heterogeneous.

The implications and ramifications of these results with regard to the thermal decomposition of other silicon-containing compounds are discussed.



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## CHAPTER I

### INTRODUCTION

#### A. Silicon Chemistry

Silicon is the second most abundant element on earth and its great technical importance (e.g. silicone oils, rubbers, semiconductors, etc.) has undoubtedly contributed to the rapid growth of silicon chemistry, particularly in the last decade. In particular, significant progress has been achieved with regard to the kinetic-mechanistic aspects of gas phase reactions of silicon-containing compounds where silyl radicals,  $R_3Si^\bullet$ , and silylenes,  $R_2Si:$ , are often important intermediates. It has also become increasingly apparent that there are considerable differences in the chemical properties and reactivities of silicon and carbon analogs.

In this chapter some salient characteristics of the silicon atom and the chemistry of silyl radicals and silylenes will be briefly reviewed. The mechanisms of the thermal decompositions of silicon hydrides and methylated silanes will be discussed in some detail and the theory of unimolecular reactions will be outlined.





## 1. Comparison Between Silicon and Carbon

Silicon belongs to the group IVb elements of the periodic table and lies immediately below carbon; therefore both silicon and carbon have similar ground state electronic configurations,  $ns^2 np^2$ , where  $n = 2$  for carbon and 3 for silicon. Since the main mode of bonding is by  $sp^3$  hybridization, similar types of compounds such as hydrides, halides, ethers etc., exist for both elements.

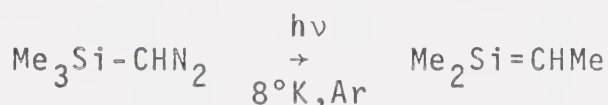
In spite of apparent similarities, there are however some important differences in the physical and chemical properties of analogous carbon and silicon compounds. For example, because the silicon atom is larger than carbon and is less electronegative, it forms weaker bonds with hydrogen and stronger bonds with more electronegative atoms such as Cl, O, N.

A more significant property of silicon is the availability of vacant 3d orbitals by which it can expand its coordination number to five or six to form  $sp^3d$  or  $sp^3d^2$  hybrids, respectively<sup>1a,b</sup>. The vacant 3d orbitals in silicon lie about 130 kcal/mol above the highest occupied orbitals whereas in carbon the energy difference is about 220 kcal/mol<sup>1c</sup>. In carbon, the 3d orbitals are not likely to mix satisfactorily with the 2s and 2p orbitals, not only because they are substantially higher in energy, but also because the radial maximum of the 3d

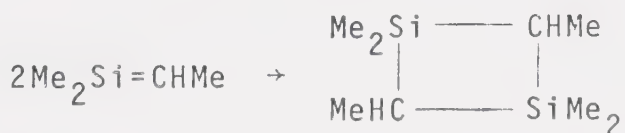


orbitals is not likely to come near that of the 2s and 2p orbitals<sup>2</sup>. Silicon d-orbitals, on the other hand, are more readily available for the formation of additional bonds and stabilization of intermediates and transition states, and may also enter into  $d_{\pi}-p_{\pi}$  interactions with neighboring groups or atoms<sup>2,3</sup>.

Another important difference between silicon and carbon compounds is the stability of  $p_{\pi}-p_{\pi}$  bonds. Although it was long believed that silicon does not form double bonds, convincing evidence has been obtained in the last few years for the transient existence of  $\text{Si}=\text{Si}$ <sup>4</sup>,  $\text{Si}=\text{C}$ <sup>5</sup>,  $\text{Si}=\text{O}$ <sup>5</sup>,  $\text{Si}=\text{N}$ <sup>6</sup> and  $\text{Si}=\text{S}$ <sup>7</sup> bonded reaction intermediates; very recently,  $\text{Me}_2\text{Si}=\text{CHMe}$  has been identified<sup>8</sup> as an intermediate in the irradiation of trimethylsilyldiazomethane in an argon matrix at 8°K:

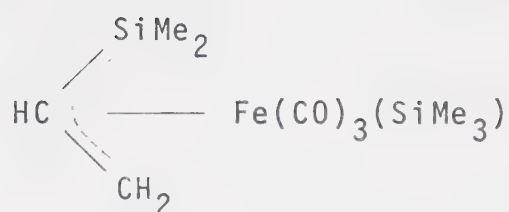


The  $\text{Si}=\text{C}$  bond is highly reactive and trimethylsilaethylene undergoes dimerization above 45°K:



The first stable compound having a  $p_{\pi}-p_{\pi}$  silicon-carbon bond,





has been prepared recently<sup>9</sup>. Stabilization was achieved by coordination with a transition metal. This compound has been found to be stable up to 80°C.

It is not clear why silicon-carbon double bonds are so unstable; several theoretical calculations<sup>10</sup> have predicted, however, that the Si=C bond is very polar  $\overset{+}{\text{Si}}=\overset{-}{\text{C}}$  and this could explain its high reactivity.

## 2. Thermochemistry

Reliable thermochemical data are crucial to the understanding of homogeneous processes. Thermochemical data for silicon compounds however are sparse and often lack internal consistency. Combustion calorimetry does not yield reliable heats of formation for silicon compounds<sup>11</sup> due to the formation of polymeric SiO<sub>2</sub> and the occurrence of uncontrollable explosions; the measurement of heats of hydrolysis appears to be a more suitable method<sup>12</sup>. Several bond interaction schemes have been suggested for calculating heats of formation of silicon compounds<sup>13,14</sup>.



Significant progress has recently been made in the determination of bond dissociation energies  $D(\text{Si-H})$ ,  $D(\text{Si-Si})$  and  $D(\text{Si-C})$  by kinetic<sup>15,16,17</sup> and electron impact studies<sup>13</sup>. Some selected bond dissociation energies of silicon compounds are given in Table I-1; they seem to indicate, first, that the bond dissociation energies  $D(\text{Si-H})$ ,  $D(\text{Si-Si})$  and  $D(\text{Si-C})$  are apparently independent of the number of methyl groups attached to silicon<sup>13</sup> and secondly, that the second bond dissociation energy in  $\text{SiH}_4$  is significantly lower than the first<sup>19</sup>. This is not observed in carbon compounds, e.g.  $D(\text{CH}_3\text{-H}) \approx 104 \pm 1$ ,  $D(\text{CH}_2\text{-H}) \approx 104 \pm 6$ ,  $D(\text{CH-H}) \approx 108 \pm 6$ ,  $D(\text{C-H}) \sim 81 \text{ kcal/mol}$ <sup>26</sup>. Similar large differences between the first and second BDEs were also observed for  $D(\text{Si-Cl})$  in  $\text{SiCl}_4$ <sup>19</sup> and for  $D(\text{Si-C})$  in  $\text{Me}_4\text{Si}$ <sup>27</sup>.

It appears therefore that the stabilities of the divalent species, silylenes, are greater than those of the carbene analogs. Increasing stability of divalent radical species is a general pattern observed in group IVb elements, and thus silylenes are expected to play important roles in many gas phase reactions of silicon compounds.





TABLE I-1  
Selected Bond Dissociation Energies of  
Silicon Compounds

Compound	D(Bond) <sup>a</sup>	Reference
H <sub>3</sub> Si-H	94 <sub>-3</sub>	18
	88	13
H <sub>2</sub> Si-H	59	19
HSi-H	84	19
Si-H	70	19
H <sub>5</sub> Si <sub>2</sub> -H	90	20
MeSiH <sub>2</sub> -H	89 <sub>-4</sub>	13
Me <sub>2</sub> SiH-H	89 <sub>-4</sub>	13
Me <sub>3</sub> Si-H	89 <sub>-4</sub>	13
	88	16
	89.9 <sub>-2.6</sub>	15
Cl <sub>3</sub> Si-H	91.3 <sub>-1.4</sub>	19
H <sub>3</sub> Si-SiH <sub>3</sub>	81 <sub>-4</sub>	21
Me <sub>3</sub> Si-SiMe <sub>3</sub>	81	22
	80.5 <sub>-1.0</sub>	17
Me-SiH <sub>3</sub>	85 <sub>-4</sub>	13
	86 <sub>-4</sub>	18
Me-SiMe <sub>3</sub>	85	23
Me <sub>3</sub> SiCH <sub>2</sub> -H	97	24
Me <sub>5</sub> Si <sub>2</sub> CH <sub>2</sub> -H	96	25

<sup>a</sup> in kcal/mol.



### 3. Silyl Radicals

The structures of alkyl and silyl radicals are different. Whereas the methyl radical  $\text{CH}_3^\bullet$  is planar<sup>28</sup>, the  $\text{SiH}_3^\bullet$  radical is pyramidal<sup>29</sup>. The effects of substituents on the structure of silyl radicals have been reviewed recently<sup>30</sup>.

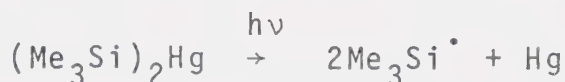
Silyl radicals undergo elementary reactions similar in type to those encountered in the chemistry of alkyl radicals such as dissociation, combination, disproportionation, addition to multiple bonds, atom abstraction, etc.; however, they often proceed with different rates and/or yield different kinds of products.

Information on the thermal stabilities of silyl radicals is still very limited, but in general they appear to be more stable than their carbon analogs: the trimethylsilyl radical, for example, has been found<sup>31</sup> to be thermally more stable than its hydrocarbon analog the t-butyl radical, since decomposition was not observed up to 400°C. Similarly, dimethylsilyl<sup>31</sup> and disilyl<sup>32</sup> radicals are stable up to 200 and 220°C, respectively.

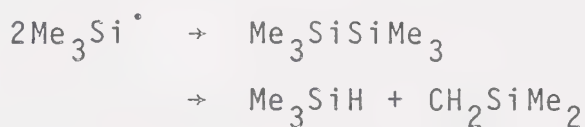
Relatively few elementary reactions of silyl radicals have been investigated kinetically, particularly in the gas phase, since not many "clean" radical sources are known.



Gammie et al.<sup>33</sup> used the photolysis of bis-trimethylsilyl mercury,



as a source of trimethylsilyl radicals. The disproportionation-combination rate constant ratio,



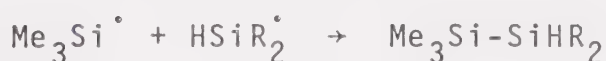
$k_d/k_c \sim 0.046$  is much smaller than that for t-butyl radicals,  $3.6^{34}$ , due to the instability of the silicon-carbon  $p_\pi$ - $p_\pi$  bond. Gammie et al.<sup>33</sup> also photolyzed the mercurial in the presence of silanes having readily abstractable hydrogen, and measured rate constants for H abstraction by trimethylsilyl radicals:



It was also possible to estimate the rate constant ratio of the cross-disproportionation



and combination reactions





between trimethylsilyl radicals and other silyl radicals, and the values of  $k_d/k_c$  are summarized in Table I-2.

The mercury ( $^3P_1$ ) photosensitized decomposition of silicon hydrides<sup>32,35</sup> and alkyl silanes<sup>31,36</sup> is another relatively clean source of silyl radicals in the gas phase, and has been used to measure the rate of recombination of trimethylsilyl radicals<sup>36</sup> and  $k_d/k_c$  ratios for different silyl radicals. The results are also given in Table I-2. The pressure dependence of the  $k_d/k_c$  ratio for disilyl radicals<sup>32</sup> reflects the instability of the chemically activated tetrasilane molecule. The chemically activated product disilane formed by recombination of monosilyl radicals is unstable up to 1000 torr<sup>32,35</sup>:



This is in marked contrast to the recombination of methyl radicals where the product, ethane, is stabilized above a few torr total pressure.

Photolytic decomposition of di-t-butylperoxide in the presence of silicon hydrides has been used for some kinetic studies of silyl radicals in the liquid phase. Silyl radicals are produced by H-abstraction by t-butoxy radicals, e.g.

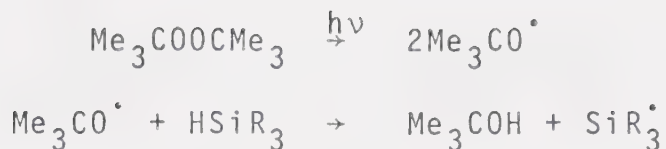




TABLE I-2  
 Values of  $k_d/k_c$  for Various Silyl and  
 Methylated Silyl Radicals

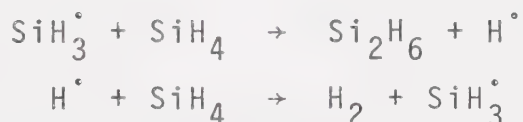
Radicals	$k_d/k_c$ (25°C)	Reference
$\text{Me}_3\text{Si} + \text{Me}_3\text{Si}$	$0.046 \pm 0.011$	33
$\text{Me}_3\text{Si} + \text{Me}_3\text{Si}$	0.03	31
$\text{Me}_3\text{Si} + \text{Me}_2\text{SiH}$	0.28	33
$\text{Me}_3\text{Si} + \text{MeSiH}_2$	0.50	33
$\text{Me}_2\text{SiH} + \text{Me}_2\text{SiH}$	0.14	31
$\text{MeSiH}_2 + \text{MeSiH}_2$	0.11	31
$\text{MeSiD}_2 + \text{MeSiD}_2$	0.04	31
$\text{Si}_2\text{H}_5 + \text{Si}_2\text{H}_5$	0.12 (400 torr)	32
$\text{SiH}_3 + \text{SiH}_3$	$\infty$ (up to 1000 torr)	32,35





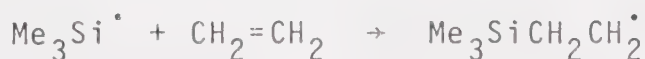
and their concentration can be monitored by electron spin resonance spectroscopy.

Thus Gaspar, Haizlip and Choo<sup>37</sup> used combined flash photolysis and electron spin resonance spectroscopic methods to study the reactions of  $\text{SiH}_3^\bullet$  and  $\text{Me}_3\text{Si}^\bullet$  radicals with the parent silanes between  $-150^\circ$  to  $-120^\circ\text{C}$  and  $-82^\circ$  to  $20^\circ\text{C}$ , respectively. Bimolecular self-reaction has been established as the dominant path for disappearance of the radicals, and no evidence was found for the propagation of the chain by reactions



which were postulated in the pyrolysis of  $\text{SiH}_4$ <sup>38,39</sup>.

The same technique has also been used to study the rate of addition of  $\text{SiH}_3^\bullet$  and  $\text{Me}_3\text{Si}^\bullet$  radicals to ethylene<sup>40</sup> which was concluded to be a very efficient scavenger of silyl radicals. The rate constant for the addition reaction





is  $k(\text{M}^{-1}\text{s}^{-1}) = 10^{7.0} \exp(-2,500/RT)$ ; the fact that the activation energy is considerably lower than  $E_a$  for methyl, ethyl and n-propyl radical addition to ethylene, 6.8<sup>41</sup>, 5.5<sup>42</sup> and 7.4 kcal/mol<sup>41</sup>, respectively, was explained in terms of stabilization of the carbon-centered free radical by a  $\beta$ -silicon substituent. Monosilyl radicals,  $\text{SiH}_3^\bullet$ , react with ethylene even faster than  $\text{Me}_3\text{Si}^\bullet$ <sup>40</sup>.

Similarly, Pollock et al.<sup>32</sup> found that the rate of addition of disilyl radicals,  $\text{Si}_2\text{H}_5^\bullet$ , to ethylene is about three orders of magnitude faster than the corresponding rate for  $\text{C}_2\text{H}_5^\bullet$  radicals; this was attributed to the greater physical size of the silicon 3p orbitals, greater polarizability and availability of the 3d orbitals on silicon, and the tetrahedral configuration of the silyl radical.

Both ethylene and nitric oxide have been found to be very efficient scavengers of silyl radicals and this fact has been used to help elucidate the decomposition mechanisms of a variety of silicon compounds<sup>31,32,43-50</sup>.

Since  $D(\text{Si-H})$  is lower than  $D(\text{C-H})$ , the rate of hydrogen abstraction from saturated compounds by silyl radicals is expected to be slower than that by the corresponding alkyl radicals, which abstract H atoms from Si-H bonds very efficiently. A large body of information has become available on the hydrogen abstraction reactions



by alkyl radicals from a variety of silanes<sup>51,52</sup>. The A factors are similar to those for abstraction from alkanes but the activation energies are lower, in agreement with the trend in the bond dissociation energies. The Arrhenius parameters for H abstraction by methyl radicals from Si-H bonds of monosilane<sup>60</sup> and methylsilanes<sup>61</sup> are listed in Table I-3, where it is seen that the activation energies for abstraction from all the methylsilanes are practically the same. This is also consistent with recent bond strength measurements (Table I-1). Silicon forms stronger bonds to halogens than does carbon, and abstraction of halogen atoms by silyl radicals from alkyl halides is an exothermic process.

The chemistry of silyl radicals and some Arrhenius parameters associated with these reactions have been recently reviewed<sup>30,51-53</sup>.

#### 4. Silylenes

Silylenes, the divalent radical silicon analogs of carbenes, play a very important role in silicon chemistry.

In contrast to carbene,  $\text{:CH}_2$ , in which the triplet ground state is nearly linear<sup>54</sup> (HCH angle  $\sim 140^\circ$ ); the  $\text{:SiH}_2$  ground state appears to be a bent singlet<sup>54,55</sup>





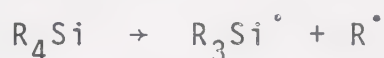
TABLE I-3  
Arrhenius Parameters for Hydrogen Abstraction by  
Methyl Radicals from Silanes

Reactant	$\log A, (M^{-1}s^{-1})$	$E_a, \text{ kcal/mol}$	Reference
$\text{SiH}_4$	$9.26 \pm 0.17$	$7.47 \pm 0.29$	60
$\text{CH}_3\text{SiH}_3$	$9.28 \pm 0.24$	$8.13 \pm 0.39$	61
$(\text{CH}_3)_2\text{SiH}_2$	$9.04 \pm 0.18$	$8.30 \pm 0.31$	61
$(\text{CH}_3)_3\text{SiH}$	$8.69 \pm 0.27$	$8.31 \pm 0.47$	61



(HSiH angle  $\sim 92^\circ$ ) and therefore little diradical character is expected.

Silylenes are formed in the decomposition of many silicon compounds brought about by the action of heat, radiation, electron impact, silent electric discharge, or by chemical activation; in most decompositions, however, silylene formation by the so-called "molecular" process is accompanied by single bond homolyses which lead to the formation of silyl radicals:



Although the formation of silylene requires the splitting of two bonds, this is partly compensated for by the formation of a new bond and thus the endothermicity of the molecular process might actually be lower than that for single bond fission. A fine balance has been found to exist between these two modes of decomposition<sup>56</sup> and this aspect will be considered later in more detail. It has been shown that pyrolysis of some disilanes, e.g.<sup>57-59</sup>





may be used as a clean and convenient source of silylenes.

Silylenes may either polymerize, react with the silane precursors or with a "trapping" reagent. Polymerization, insertion into single bonds, and addition to multiple bonds are three types of reactions which characterize most of the known chemistry of silylenes<sup>59</sup>, of which several review articles are available<sup>51,52,54,59,62</sup>.

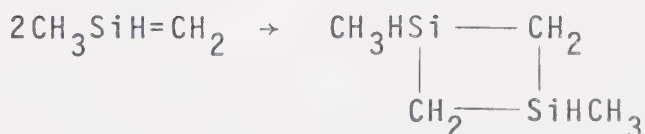
Very recently, evidence has been obtained<sup>63</sup> for dimerization of dimethylsilylene to tetramethyldisilane,



and a novel rearrangement to 1-methylsilaethylene



followed by dimerization to 1,3-dimethyl-1,3-disilacyclobutane

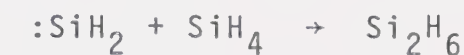


has been suggested<sup>63</sup>.

Silylenes are generally less reactive than carbenes<sup>64</sup>; they insert rapidly into Si-H, Si-O and Si-halogen bonds, but not into Si-C, C-H or C-C bonds; insertion into the Si-Si bond has also been suggested<sup>65</sup>.



The absolute rates and Arrhenius parameters for insertion into silane and disilane,



have been measured:  $k_{\text{SiH}_4} = 10^{9.7} \exp(-1300 \pm 1100)/RT$  and  $k_{\text{Si}_2\text{H}_6} = 10^{9.9} \exp(-400 \pm 1200)/RT (\text{M}^{-1} \text{s}^{-1})$ , respectively<sup>66</sup>. The high preexponential factors and low activation energies indicate that insertion of  $:\text{SiH}_2$  into the Si-H bond is an extremely rapid process.

Relative rates of insertion of  $:\text{SiH}_2$  into the Si-H bond of silicon hydrides and methylsilanes have been measured by two groups who offered two alternative explanations for the observed trends. Ring et al.<sup>65,67</sup> found the following order of reactivity (per Si-H bond),



and rationalized the results in terms of the electrophilic nature of  $:\text{SiH}_2$  and the hydridic character of Si-H bonds, i.e. the greater the negative charge on the hydrogen, the faster the rate of insertion. Cox and Purnell<sup>68</sup> however found a different order of reactivity,

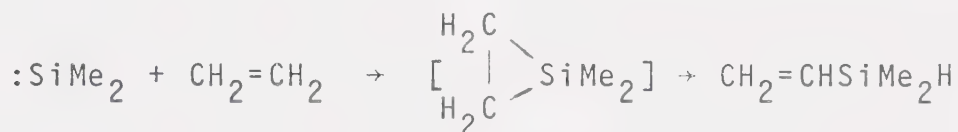






and concluded that the differences in the rates reflect differences in the Si-H bond dissociation energies. In view of the most recent values of  $D(\text{Si-H})^{13}$ , however, the explanation offered by Ring et al. appears to be more plausible.

Silylenes also react with a variety of unsaturated organic compounds. Addition across the double bond has been shown<sup>59,64,69,70</sup> to proceed via unstable silacyclopropane derivatives, e.g.



Silylene reacts very rapidly with 1,3-butadiene, and Jenkins et al.<sup>71</sup> found that addition of  $:\text{SiH}_2$  to 1,3-butadiene can compete favorably with insertion into  $\text{Si}_2\text{H}_6$ ; the reactivity of silylenes toward ethylene, however, is relatively low. For example, Atwell and Weyenberg<sup>59</sup> reported the following order of relative reactivities towards  $:\text{SiMe}_2$  :

saturated hydrocarbons < benzene < ethylene <<  
dimethoxytetramethyldisilane < dienes and alkynes.

Since ethylene is an effective scavenger of silyl radicals on the one hand but is unreactive towards silylenes on the other, this can be used to advantage in



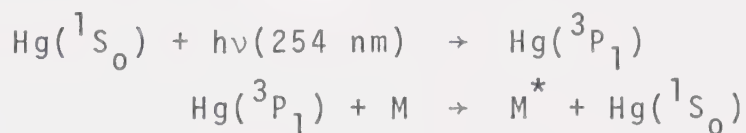
elucidation of the types of bond cleavages occurring in the decomposition of many silicon compounds.

## 5. Homogeneous Decomposition of Some Silicon Compounds

Significant advances have recently been made with regard to the kinetic and mechanistic aspects of the homogeneous gas phase decompositions of some silicon-containing compounds, particularly silicon hydrides and methylsilanes. The results, which will now be reviewed, can be classified according to the methods used, namely, mercury photosensitization, direct photolysis, chemical activation and pyrolysis.

### (i) Mercury ( $^3P_1$ ) Photosensitized Decomposition

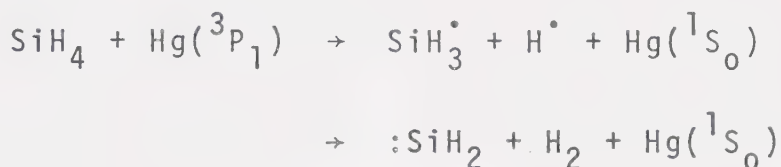
Since most silicon hydrides and methylsilanes absorb only in the vacuum UV region, mercury photosensitization can be used to advantage:



The energy transferred to the substrate M is  $\sim 112$  kcal/mol, a quantity more than sufficient to induce rupture of Si-C, Si-H or Si-Si bonds.



The occurrence of radical and molecular primary steps in the  $\text{Hg}(^3\text{P}_1)$  photosensitized decomposition of monosilane has been proposed<sup>72,44,31</sup>



but the experiments conducted in the presence of nitric oxide<sup>48</sup> suggested that formation of silylene is not important.

Similarly, Nay et al.<sup>31</sup> showed that the only major process of importance in the  $\text{Hg}(^3\text{P}_1)$  photosensitized decomposition of methylsilanes is Si-H bond cleavage. A minor contribution from a molecular process leading to  $\text{H}_2$  and silylenes was postulated in the cases of  $\text{MeSiH}_3$  and  $\text{Me}_2\text{SiH}_2$  in order to account for a significant mass imbalance between the major products.

## (ii) Vacuum UV Photolysis

The gas phase photolysis of monomethylsilane has been investigated<sup>45,46</sup> using the xenon and krypton resonance lines at 147.0 and 123.6 nm respectively (the absorption of methylsilane is continuous in this region<sup>73</sup>). The primary quantum yields are summarized in Table I-4,



TABLE I-4  
 Primary Quantum Yields in the 147.0 <sup>a</sup> and  
 123.6 nm <sup>b</sup> Photolysis of Monomethylsilane <sup>c</sup>

	$\phi$	
	147.0 nm	123.6 nm
$\text{CH}_3\text{SiD}_3 + h\nu \xrightarrow{1} \text{CH}_3\text{SiD} + \text{D}_2$	0.32	0.16
$\xrightarrow{2} \text{CH}_3\text{SiD} + 2\text{D}$	0.05	0.09
$\xrightarrow{3} \text{CH}_2\text{SiD}_2 + \text{HD}$	0.23	<0.37 (0.14)
$\xrightarrow{4} \text{CHSiD}_3 + \text{H}_2$	0.07	0.11
$\xrightarrow{5} \text{CH}_3\text{D} + \text{SiD}_2$	0.09	0.08
$\xrightarrow{6} \text{CH}_3 + \text{D} + \text{SiD}_2$	0.26	0.25
$\xrightarrow{7} \text{CH}_3 + \text{D} + \text{D}_2 + \text{Si}$	0.00	0.17
$\xrightarrow{8} \text{CH}_3 + \text{SiD}_3$	$\sim 0.01$	0.00
	<u>1.03</u>	<u>1.23 (1.00)</u>

<sup>a</sup> Photonic energy 195 kcal/mol.

<sup>b</sup> Photonic energy 231 kcal/mol.

<sup>c</sup> References 45 and 46.





where it is seen that the primary quantum yield for the elimination of molecular hydrogen and formation of methylsilylene, step (1), becomes more important as the photonic energy is decreased. This seems to indicate that molecular elimination is the lowest energy path for decomposition of methylsilane and might assume more significance as the energy content is decreased.

The gas phase photolysis of dimethylsilane at 147.0 nm has been investigated by Alexander<sup>47</sup> and the primary mechanism is shown in Table I-5. In view of the large amount of energy absorbed by the molecule, it is not surprising to find a very complex fragmentation pattern; molecular elimination of hydrogen from the silicon atom and formation of dimethylsilylene, step (6), is apparently unimportant.

### (iii) Chemical Activation

A chemically activated molecule is formed either by radical recombination, insertion or addition of divalent species. The energy content of a newly formed vibrationally excited molecule can be calculated from thermochemical data.

The kinetics of decomposition of chemically activated dimethylsilane have been studied by Hase,



TABLE I-5  
 Primary Mechanism for the 147.0 nm<sup>a</sup> Photolysis of  
 Dimethylsilane-d<sub>2</sub><sup>b</sup>

	$\phi$
$(\text{CH}_3)_2\text{SiD}_2 + h\nu \xrightarrow{1} \text{CH}_3\text{SiD} + \text{CH}_3\text{D}$	0.15
$\xrightarrow{2} \text{CH}_3\text{SiD} + \text{CH}_3 + \text{D}$	0.20
$\xrightarrow{3} \text{SiD}_2 + 2\text{CH}_3$	0.08
$\xrightarrow{4} \text{CH}_2\text{SiD}_2 + \text{CH}_4$	0.05
$\xrightarrow{5} \text{CH}_3\text{SiD}_2\text{H} + \text{CH}_2$	0.04
$\xrightarrow{6} (\text{CH}_3)_2\text{Si} + \text{D}_2$	0.07
$\xrightarrow{7} \text{CHSiD}_2 + \text{CH}_3 + \text{H}_2$	0.04
$\xrightarrow{8} \text{CHCH}_3\text{Si} + \text{D}_2 + \text{H}_2$	0.07
$\xrightarrow{9} \text{CH}_2\text{CH}_3\text{Si} + \text{HD} + \text{D}$	0.09
$\xrightarrow{10} \text{CHCH}_3\text{SiD} + \text{HD} + \text{H}$	0.05
$\xrightarrow{11} \text{CH}_2\text{CH}_3\text{SiD}_2 + \text{H}$	0.05
$\xrightarrow{12} \text{CH}_2\text{CH}_3\text{SiD} + \text{HD}$	0.12
	<u>1.01</u>

<sup>a</sup> Photonic energy 195 kcal/mol.

<sup>b</sup> From reference 47.



Mazac and Simons<sup>74</sup>. Vibrationally excited dimethylsilane, having an average energy content of  $\sim 130$  kcal/mol, was produced by insertion of singlet methylene into the Si-H bond of methylsilane. The decomposition paths and the rate constants are shown in Table I-6. Comparison of Tables I-5 and I-6 substantiates the previous suggestion that molecular elimination of hydrogen from simple silicon hydrides becomes more important as the energy available is lowered. This process might therefore be expected to be of major significance in thermal decompositions.

On the other hand, Cowfer et al.<sup>75</sup> studied the reactions of hydrogen atoms with  $\text{SiH}_4$ ,  $\text{CH}_3\text{SiH}_3$ ,  $(\text{CH}_3)_2\text{SiH}_2$  and  $(\text{CH}_3)_3\text{SiH}$ , where chemically activated molecules are formed by radical combination reactions such as



(the minimum excitation energy is approximately  $E^* \approx D(\text{Si-H}) \approx 90$  kcal/mol), and concluded that decomposition via molecular elimination channels is negligible since they require rigid transition states: this would markedly decrease the sum of states available to the transition state complex and therefore substantially lower the rate of molecular elimination compared to single bond cleavage. The authors also pointed out that



TABLE I-6  
Reaction Paths and Rate Constants for the  
Decomposition of Chemically Activated <sup>a</sup>  
Dimethylsilane <sup>b</sup>

Reaction	$10^9 k, s^{-1}$
$(CH_3)_2SiH_2^* \rightarrow$ products	4.0
1 $CH_3 + CH_3SiH_2$	$\sim 0.90$
2 $CH_4 + CH_3SiH$	0.85
3 $(CH_3)_2Si: + H_2$	1.90
4 $(CH_3)_2SiH + H$	$\sim 0.30$

<sup>a</sup> Average excitation energy  $129 \pm 4$  kcal/mol.

<sup>b</sup> From reference 74.





since the bond dissociation energy  $D(\text{Si-CH}_3)$  is lower than  $D(\text{Si-H})$ , the main mode of decomposition of methylsilanes should be via Si-C bond cleavage.

## 6. Pyrolysis

In thermal activation the heat absorbed by the molecule is converted into vibrational energy which is assumed to be equipartitioned among the various internal degrees of freedom. Because of this energy equipartitioning the weakest bond in the molecule is the one which is eventually homolyzed. Although there are exceptions, most molecules decompose from the highest vibrational level of the ground, singlet state, and hence much of the kinetic and thermochemical data available today have been derived from pyrolysis experiments.

Quite frequently, however, the system may be complicated by the occurrence of heterogeneous processes, radical chain reactions and secondary thermal decomposition of the products. In many cases these difficulties can be overcome by studying the effects of surface, addition of radical scavengers, and by keeping the reaction conversion very low. Flow systems have been used to advantage in cases of high product instability.

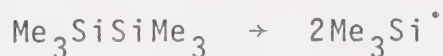


Pyrolyses of simple alkanes proceed by the well-known Rice-Herzfeld mechanism<sup>76</sup> in which the initial slow dissociation of the parent molecule into radicals via homogeneous C-C bond cleavage is followed by fast radical chain reactions. Except for the case of methane, primary molecular elimination of hydrogen does not appear to be significant. In contrast, silicon-containing analogs apparently decompose by parallel and independent radical and molecular processes; the reactions are often partly heterogeneous and radical chain mechanisms are allegedly involved.

#### (i) Disilanes

The pyrolysis of disilanes has attracted a great deal of attention in recent years and the mechanisms of the decompositions of  $\text{Si}_2\text{H}_6$  and of all the methylated disilanes are now well understood.

With the exception of hexamethyldisilane<sup>16,17</sup> where dissociation of the Si-Si bond and formation of  $\text{Me}_3\text{Si}^\bullet$  radicals



occurs simultaneously with  $\text{Me}_2\text{Si}:$  elimination,





all the other methylidisilanes<sup>27,58,77</sup> were found to decompose exclusively by unimolecular, homogeneous gas phase elimination of silylenes. The pyrolyses of  $\text{Si}_2\text{H}_6$ <sup>57,79,80</sup> and  $\text{Si}_3\text{H}_8$ <sup>65,77,79</sup> also proceed via elimination of silylene.

Some Arrhenius parameters for the elimination of silylenes from disilanes are shown in Table I-7. It is significant that all the activation energies, except that for  $\text{Me}_6\text{Si}_2$ , reaction (3), lie within a narrow range,  $48.0 \pm 2.0$  kcal/mol; these values correspond approximately to the reaction enthalpies since the activation energies for the reverse reactions, insertion of silylenes into Si-H bonds, are very small and close to zero<sup>66</sup>. All the reactions (except (3)) involve a 1,2-hydrogen shift and since the bond dissociation energies  $D(\text{Si-H})$  in the silane products, i.e.  $\text{SiH}_4$ ,  $\text{MeSiH}_3$ ,  $\text{Me}_2\text{SiH}_2$  and  $\text{Me}_3\text{SiH}$ , are independent of the number of methyl groups attached to the silicon atom, (cf. Table I-1) it might therefore appear that  $D(\text{Si-Si})$  and  $D(\text{Si-H})$  in disilanes are also unaffected by increased methylation on the silicon atoms<sup>13</sup>. The relatively high activation energy for reaction (3), and the fact that to date there is no evidence of silylene insertion into Si-C bonds suggest that the activation



TABLE I-7  
Arrhenius Parameters for the Elimination of Silylenes from Disilanes

Reaction	$\log A(s^{-1})$	$E_a, kcal/mol$
$Me_3SiSiMe_2H \rightarrow Me_2Si: + Me_3SiH$ (1)	$12.93 \pm 0.31$	$47.4 \pm 0.9$ <sup>a</sup>
$HMe_2SiSiMeH_2 \rightarrow Me_2Si: + MeSiH_3$ (2)	$12.56 \pm 1.80$	$46.0 \pm 5.3$ <sup>a</sup>
$Me_3SiSiMe_3 \rightarrow Me_2Si: + Me_4Si$ (3)	$13.70 \pm 0.70$	$67.4 \pm 0.8$ <sup>b</sup>
$HMe_2SiSiMeH_2 \rightarrow MeSiH: + Me_2SiH_2$ (4)	$13.66 \pm 0.55$	$46.2 \pm 1.4$ <sup>a</sup>
$MeH_2SiSiH_3 \rightarrow MeSiH: + SiH_4$ (5)	$14.14 \pm 0.14$	$49.9 \pm 0.4$ <sup>c</sup>
$MeH_2SiSiH_3 \rightarrow :SiH_2 + MeSiH_3$ (6)	$15.28 \pm 0.15$	$50.7 \pm 0.4$ <sup>c</sup>
$H_3SiSiH_3 \rightarrow :SiH_2 + SiH_4$ (7)	$14.52 \pm 0.36$	$49.2 \pm 1.1$ <sup>d</sup>

<sup>a</sup> Reference 27; <sup>b</sup> Reference 17; <sup>c</sup> Reference 77; <sup>d</sup> Reference 57.





energy for the reverse reaction (-3) must be high. This is in agreement with Davidson's earlier qualitative prediction<sup>56</sup> that silylene elimination is only important if the precursor silane molecule contains Si-H bonds into which insertion is possible.

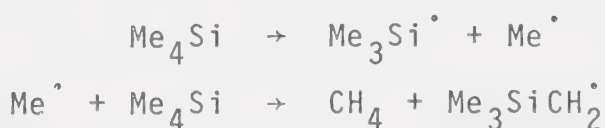
## (ii) Monosilane and Methylsilanes

In comparison with disilanes, the pyrolyses of monosilane and methylsilanes appear to proceed by more complex reaction mechanisms which have not yet been fully clarified.

### (a) Tetramethylsilane

The pyrolysis of tetramethylsilane has been extensively used for the preparation of carbosilanes<sup>81</sup>, compounds with alternate silicon and carbon atoms in the molecular skeleton. The kinetics of the pyrolysis of  $\text{Me}_4\text{Si}$  have been investigated in a flow system<sup>82</sup>.

Methane was one of the major reaction products, presumably formed by  $\text{Me}_3\text{Si-Me}$  bond cleavage,

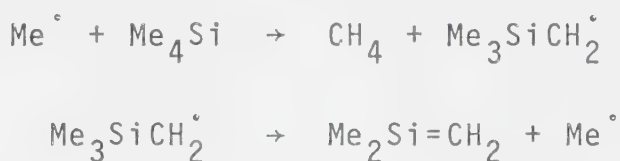




and the following first order rate constant was reported:

$$\log k(s^{-1}) = (14.3 \pm 0.23) - (67600 \pm 800)/(2.3RT)$$

The activation energy however is less than  $D(\text{Me}_3\text{Si-Me}) \sim 85 \text{ kcal/mol}^{13,23}$ , and this seems to indicate the presence of free radical chain reactions in the system, such as<sup>51</sup>



Some heterogeneous reactions must also participate in the decomposition of tetramethylsilane, since the rate of decomposition and the relative product yields were both affected by the nature of the reaction vessel surface<sup>82</sup>. Moreover, the low thermal stabilities of some of the products and radical intermediates preclude the assignment of a complete mechanism.

#### (b) Trimethylsilane

Complications of a similar nature have also been encountered in the pyrolysis of trimethylsilane. This reaction was originally proposed<sup>83</sup> to be a radical non-chain process, in which hydrogen and methane are formed by Si-H and Si-C cleavage respectively. The following Arrhenius parameters were determined:



$$\log k_{H_2} (s^{-1}) = (15.6 \pm 0.7) - (80,300 \pm 500)/(2.3RT)$$

$$\log k_{CH_4} (s^{-1}) = (15.9 \pm 0.7) - (76,500 \pm 500)/(2.3RT)$$

However  $D(\text{Me}_3\text{Si-H}) \approx 89 \text{ kcal/mol}^{13,15,16}$  and  $D(\text{Me-SiMe}_2\text{H}) \approx 85 \text{ kcal/mol}^{13}$  which suggest that the actual mechanism is not quite so simple as previously proposed<sup>83</sup>; moreover, recent experiments<sup>51,84</sup> strongly indicate the presence of radical chain reactions.

### (c) Dimethylsilane and Monomethylsilane

The pyrolysis of dimethylsilane has not been reported in the literature and only qualitative results on the pyrolysis of monomethylsilane have been described<sup>39,56,85</sup>.

The pyrolysis of monomethylsilane was claimed<sup>86</sup> to be "a remarkably clean" reaction, since the major products consisted only of hydrogen and 1,2-dimethyldisilane; dimethylsilane and a solid polymer were minor products<sup>85</sup>. Ring et al.<sup>39</sup> suggested that both methylsilyl and methylsilylene radicals are formed in primary reactions,



and Davidson<sup>56</sup> claimed that Si-C cleavage





takes place as well.

#### (d) Monosilane

The nature of the primary steps in the pyrolysis of monosilane is probably one of the most controversial issues in the chemistry of silicon compounds and in spite of numerous studies carried out over the last 40 years there is still no agreement on the mechanism of this reaction. Because the experimental results on this reaction were of prime importance in the elucidation of our own work, the pyrolysis of  $\text{SiH}_4$  will be discussed in more detail.

The first extensive analytical and kinetic investigation of the pyrolysis of  $\text{SiH}_4$  was carried out by Purnell and Walsh<sup>38</sup>. At low conversions the two major products were  $\text{H}_2$  and  $\text{Si}_2\text{H}_6$  in a ratio of  $\sim 1.26$ ; the minor products were  $\text{Si}_3\text{H}_8$  and a polymeric solid. The orders of formation of  $\text{H}_2$  and  $\text{Si}_2\text{H}_6$  were  $\sim 1.5$  with respect to the substrate, and the rate of formation of the major products could be described by the relation

$$R(\text{H}_2) = \frac{1}{1.26} R(\text{Si}_2\text{H}_6) = 10^{15.2} \exp\left(-\frac{55,900}{RT}\right) [\text{SiH}_4]^{3/2} \text{ M}^{-1} \text{ s}^{-1}$$

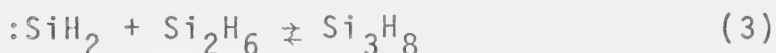




Purnell and Walsh also observed that the reaction rates were fast and erratic in a fresh, nitric acid-washed vessel, but were lower and more reproducible once the surface became coated by silicon; in such silicon-coated vessels, the reaction rates were independent of the surface to volume ratio which suggests, but however does not prove, the absence of heterogeneous reactions. The addition of inert gases caused an acceleration of the reaction rates but the reaction orders were unaffected.

Purnell and Walsh suggested two mechanisms which would be consistent with their results: mechanism A, molecular hydrogen elimination followed by insertion of silylene into the substrate:

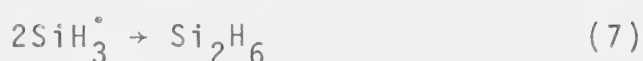
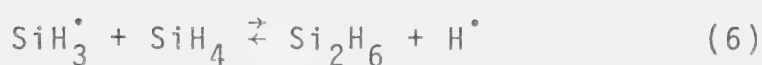
Mechanism A:



and mechanism B, homolytic silicon-hydrogen bond rupture followed by a free radical chain propagated by H atoms and  $\text{SiH}_3^\bullet$  radicals:

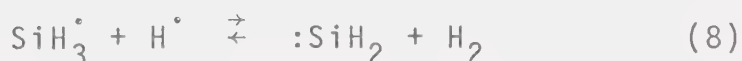


## Mechanism B:



Thermochemical considerations led Purnell and Walsh to favour mechanism A. Moreover, the decomposition was carried out at relatively low pressures (35 - 230 torr) where the unimolecular first order rate constant for a light molecule such as  $\text{SiH}_4$  may well be pressure-dependent: this would explain the experimental reaction order of 1.5 and the accelerating effect of inert gases on the rate of decomposition.

Further support in favour of mechanism A came from the work of John and Purnell<sup>87</sup> who obtained the data required to calculate the equilibrium constant between the products of the two possible modes of decomposition of  $\text{SiH}_4$ ,



At 600°K,  $K_8 = 10^{15.9}$  and thus  $\text{SiH}_4$  should preferentially decompose via silylene elimination. John and Purnell<sup>87</sup> also calculated the analogous equilibrium constant for the case of  $\text{Si}_2\text{H}_6$ ,





Similarly, at 600°K,  $K_9 = 10^{11.3}$ , again predicting that silylene formation predominates as was observed experimentally<sup>57</sup>.

Other experimental data<sup>66</sup> on the insertion reactions of  $\text{:SiH}_2$  into  $\text{H}_2$ , reaction (-1), support the occurrence of Mechanism A.

Mechanism B, however, is favoured by Ring and coworkers<sup>39,88</sup> who considered the kinetics of the radical mechanism and showed that the experimental activation energy is consistent with mechanism B; however, the experimentally observed A factor,  $10^{15.2}\text{s}^{-1}$ , cannot be reconciled with mechanism B unless the rate of  $\text{SiH}_3^\bullet + \text{SiH}_3^\bullet$  recombination reaction is unusually slow, having an A factor of approximately  $10^6 \text{ M}^{-1}\text{s}^{-1}$ . Recent measurements of the rates of self-reactions of silyl radicals<sup>33,36,37,89,90</sup> indicate, however, that the A factor for the combination of silyl radicals is approximately  $10^{10} \text{ M}^{-1}\text{s}^{-1}$ .

The types of products formed in pyrolysis experiments conducted in the presence of other reagents provides more direct and compelling evidence for the occurrence of radical mechanism B. Thus HD and  $\text{D}_2$  were formed in the pyrolysis of  $\text{SiD}_4$  in the presence of  $\text{H}_2$ <sup>39</sup>, and the products formed in the presence of acetylene<sup>88</sup> are



consistent with  $^{\circ}\text{SiH}_3$  rather than  $:\text{SiH}_2$  precursors.

Similarly, in the co-pyrolysis of  $\text{SiH}_4$  and  $\text{SiD}_4$ <sup>39</sup>, HD was formed in quantities comparable with those of  $\text{H}_2$  and  $\text{D}_2$ .

It has also been shown<sup>88</sup> that orbital symmetry correlations apparently favour single bond dissociation over molecular cleavage.

It appears therefore that the thermal decomposition of  $\text{SiH}_4$  can proceed by two initial steps, in parallel and in competition, one yielding  $:\text{SiH}_2 + \text{H}_2$  and the other,  $^{\circ}\text{SiH}_3 + \text{H}$ . At this point, it should be recalled that Purnell and Walsh<sup>38</sup> noted that heterogeneous processes might participate in the decomposition and if this is so, one would expect the radical processes to be the most affected. This aspect of the mechanism has been completely neglected in recent discussions and in the kinetic schemes of Ring et al.<sup>39,88</sup>.

## B. Unimolecular Reactions

The understanding of most thermal decompositions is closely tied to the theory of unimolecular reactions, which will now be briefly outlined.

A gas phase unimolecular reaction is the simplest kind of elementary reaction since it involves the isomerization or decomposition of a single isolated





reactant molecule:

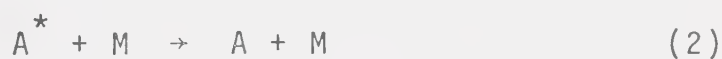


and

$$R_{uni} = k_{uni}[A]$$

However, detailed studies of several unimolecular reactions have shown that the first order rate coefficient  $k_{uni}$  is constant only at high pressures and declines at low pressures.

The original theory of unimolecular reactions, developed by Lindemann<sup>91</sup>, was based on the following concepts. A fraction of the reactant molecules becomes energized in bimolecular collisions and eventually the energy content becomes greater than the critical quantity  $E_0$  required for decomposition. The energized molecules can either be de-energized by further collisions or undergo unimolecular reaction. The mechanism is expressed by the following reactions:



where  $A^*$  is a substrate molecule sufficiently energized that it can react, and M is any bath molecule. By



applying the steady state approximation to the concentration of  $A^*$ , the rate expression for the Lindemann scheme is

$$R_{\text{uni}} = k_3[A^*] = \frac{k_1 k_3 [M]}{k_2 [M] + k_3} [A] \quad (4)$$

Equation (4) qualitatively predicts the decline or "fall-off" in the first order rate constant at lower pressures; however, quantitative agreement between the experimental and calculated "fall-off" curves has been generally rather poor.

In the simple Lindemann theory all the rate constants were taken to be energy independent. Hinshelwood<sup>92</sup> proposed that  $k_1$  is energy dependent and included contributions from the vibrational degrees of freedom in statistical calculations on the probability that the energy content of A is greater than  $E_0$ . Shortly after Hinshelwood's proposal, Rice and Ramsperger<sup>93</sup> and, independently, Kassel<sup>94</sup>, suggested that the original Lindemann mechanism of collisional energization and de-energization is probably correct but that the rate of conversion of an energized molecule to the product, reaction (3), is a function of its energy content. The main achievement of the RRK theory was the derivation of an expression for the energy dependence of  $k_3$ .

Kassel<sup>94</sup> treated the reactant molecule as a system of loosely coupled oscillators having identical



frequencies, allowing a free flow of energy between the normal modes. Assuming that the rate constant  $k_3(E)$  is related to the probability that the critical energy  $E_0$  is concentrated in a certain part of the molecule (in one oscillator), he derived the relationship<sup>94</sup>

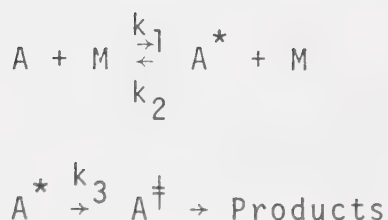
$$k_3(E) = \nu \left( \frac{E - E_0}{E} \right)^{s-1} \quad (5)$$

where  $E_0$  is the critical energy,  $E$  is the total energy of the molecule,  $s$  is the number of oscillators, and  $\nu$  is identified with the experimental high pressure A-factor<sup>97</sup>.

Reasonable agreement has been found between experimental and theoretical fall-off curves with the proper choice of the parameters; however, the fact that  $s$ , the number of oscillators, cannot be predicted by theory, makes this method somewhat empirical. It has been found, however, for a large number of reactions, that the required value of  $s$  is about half the total number of oscillators in the molecule.

Marcus<sup>95</sup> further refined the RRK treatment and the resulting RRKM method is the most widely used and successful model to date. The evaluation of the rate constants is based on the methods of quantum statistical mechanics and transition state theory is incorporated into the calculation. The following reaction scheme is used:





where  $A^*$  is an energized molecule of energy content  $E^* > E_0$ , but the energy distribution is unfavourable for reaction.  $A^\ddagger$  is the transition state complex, which corresponds to the top of an energy barrier between the reactant and products.

In the evaluation of the energy dependence of the rate constant  $k_3$ , the vibrational energy of the molecule is assumed to undergo rapid statistical redistribution. The contributions from external and internal rotations are less significant.

The energy dependence of the rate constant  $k_3$  is given by the following expression,

$$k_3(E^*) = \lambda \frac{Q^\ddagger}{Q^*} \frac{\Sigma P(E^\ddagger)}{h N(E^*)} \quad (6)$$

where  $\lambda$  is the degeneracy of the reaction path (i.e. the number of ways a certain reaction can occur),  $Q^*$  is the rotational partition function,  $\Sigma P(E^\ddagger)$  is the total number of vibrational-rotational quantum states of  $A^\ddagger$  with energy  $E^\ddagger = E^* - E_0$ , and  $N(E^*)$  is the density of quantum states of the substrate at an energy  $E^*$ . The RRKM expression for the





overall first order rate constant is

$$k_{\text{uni}} = \frac{\lambda Q^\ddagger}{h Q^* Q_A} \int_{E_0}^{\infty} \frac{\Sigma P(E^\ddagger) \exp(-E^*/kT) dE^*}{1 + k_3(E^*)/k_2[M]} \quad (7)$$

The de-energization rate constant  $k_2$  is usually considered to be independent of energy content and can be approximated by the collision number.

The RRKM model can in principle be applied to any unimolecular reaction taking place in a ground state molecule and its widespread use in pyrolytic, photolytic and chemically activated systems has been very successful for the elucidation of many elementary reactions. Moreover, the experimental fall-off regions of  $k_{\text{uni}}$  can be correctly predicted on the basis of this model.

### C. The Present Investigation

Although the rate constant parameters for a variety of elementary reactions of organosilicon radicals are rapidly becoming available, the range of studies is still severely limited by the unavailability of suitable sources of silyl radicals.

Thermal decomposition of silicon compounds is one potential source of silicon radicals but surprisingly very few substrates have been investigated. Kinetic data



on the relative importance of molecular and radical processes are very sparse indeed and therefore the occurrence or non-occurrence of these processes cannot be elucidated on structural or thermochemical grounds. Thus some disilanes were found to pyrolyze via molecular elimination of silylenes and others predominantly via silyl radicals; the simplest member of the series, monosilane, appears to feature both radical and molecular modes of decomposition.

We therefore decided to initiate a systematic study of the pyrolyses of a number of silicon compounds. Monomethylsilane was chosen for the first investigation since it is a rather simple molecule and the kinetics of decomposition were expected to be relatively straightforward.

We were also cognizant of the possibility that monomethylsilane, like monosilane, may decompose via competing radical and molecular processes, and therefore decided to examine the reaction in the presence of a radical scavenger. Since ethylene scavenges silyl radicals very efficiently but is relatively unreactive towards silylenes, its effect can be used to advantage in the elucidation of the radical and molecular processes occurring. In spite of the high thermal stability of ethylene, its potential as a radical scavenger in the



thermal decomposition of silicon compounds had not yet been explored.

At the time this work was initiated preliminary results of the pyrolysis of monomethylsilane were published by Ring et al.<sup>39,85</sup>. Their results are qualitatively in agreement with ours, but do not allow mechanistic or kinetic interpretation.

We also decided to investigate the pyrolysis of dimethylsilane in order to assess the possible effects of increasing methyl substitution on the silicon atom on the nature and rates of the elementary processes.



## CHAPTER II

### EXPERIMENTAL

#### A. Vacuum Systems

Two vacuum systems were utilized, the main one for pyrolysis and separation of products, and the auxiliary one for purification and photolyses of the substrates.

(1) The main apparatus was a conventional high vacuum static system (Figure II-1), constructed of Pyrex glass and evacuated to  $10^{-6}$  torr by means of a two-stage mercury diffusion pump, backed by a Welch Duo-Seal Model 1405 oil rotary pump. Delmar mercury float valves, Hoke teflon-seated valves (numbers TY440 and 425106Y-316-SS) or glass stopcocks lubricated with high vacuum Apiezon N and L grease were used throughout. The valve leading to the reactor was a stainless steel high temperature Hoke valve (number 421 306Y-316-SS). In addition to a vacuum line for gas handling, the apparatus incorporated a pyrolytic furnace assembly and a gas chromatographic unit. Pressures were measured with a mercury manometer or a McLeod gauge. Gas transfers and distillations were monitored on a Pirani Vacuum Gauge (Consolidated Vacuum Corporation type GP-140) using Pirani tubes (type GP-001) as the sensing heads. A low pressure line was used to operate the mercury float









valves and Toepler pumps. The inner surface of the gas handling system was treated with trimethylchlorosilane before use, and every time after being exposed to air, in order to deactivate free -OH groups on various surfaces in the system which could cause decomposition of silanes<sup>38</sup>.

(2) The auxiliary system (Figure II-2) was a conventional high vacuum assembly pumped by a two-stage mercury diffusion pump backed by a Cenco Hyvac 7 oil pump. The apparatus was kept grease-free by using Delmar mercury float valves, Hoke 425106Y-316-SS valves, or teflon stop-cocks (Ace Glass Inc. number 8194) equipped with Viton-A "O" rings. The vacuum system consisted of a distillation train, storage bulbs and a special line fitted with a Porapak Q column. The column could be purged by a stream of helium, evacuated and used for purification of substrate, as described in Section II-D-3. The auxiliary system was also used for mercury-photosensitized decomposition of substrates in order to prepare authentic samples of disilanes, as described in Section II-E. A cylindrical quartz cell, 10 cm in length and 5 cm in diameter containing a small drop of mercury was attached to the vacuum system via a Hoke valve. A low pressure mercury resonance lamp (Hanovia #687A45) was used as the source of radiation.

Before use, the vacuum system was treated with gaseous trimethylchlorosilane.



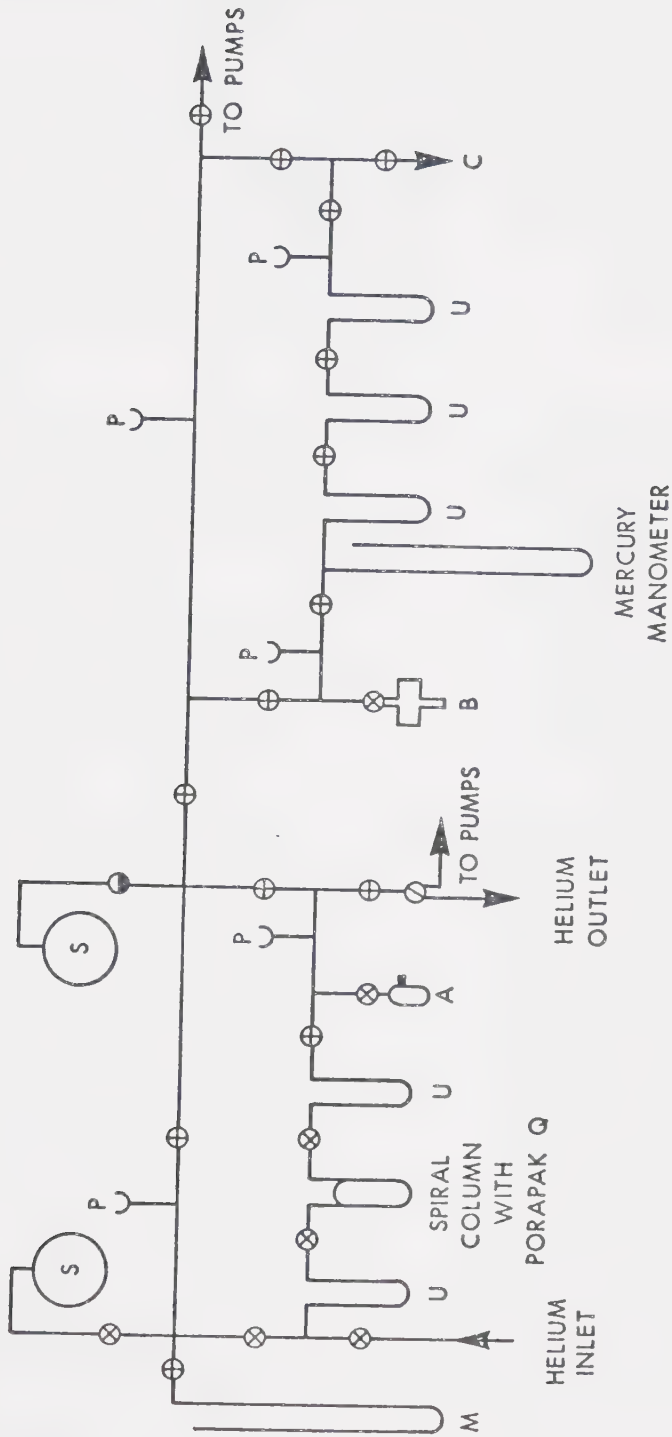


Figure II-2. Auxiliary Vacuum System for Photolysis and Purification of Methylsilane and Dimethylsilane.  
 A, sampling ampoule with silicone seal. B, photolysis cell.  
 C, to atmosphere. M, mercury manometer. P, pirani tube.  
 S, storage bulbs. U, u-traps. ⊗ -Hoke valve, ⊕ -Teflon valve with "O" rings, ⊙ -three-way glass stopcock, ⊙ -mercury float valve.



## B. Pyrolytic Furnace Assembly

The pyrolytic assembly consisted of a quartz vessel surrounded by an aluminium block furnace as depicted in Figure II-3<sup>96</sup>. The reactor was connected to the vacuum line with a high temperature Hoke valve which in turn was fastened to the furnace block in order to minimize dead space.

The cylindrically-shaped furnace consisted of two halves connected by hinges allowing easy removal from the reaction vessel. The aluminium block was surrounded by a layer of glass wool and transite and, in order to minimize temperature fluctuation and heat loss, the entire unit was wrapped in aluminium foil and placed into a box made of asbestos board. The furnace was heated by means of eight 300-watt pencil heaters arranged in parallel to ensure uniform heating. The pencil heaters were powered and regulated by an API 2-Mode proportional electronic controller. The junction of an iron-constantan thermocouple from the controller was located in a small gap between the reaction vessel and the aluminium block in the middle of the furnace. The temperature of the furnace was maintained to within  $\pm 0.2^{\circ}\text{C}$  and the gradient over the length of the reaction vessel was less than  $\pm 0.3^{\circ}\text{C}$ .

Two iron-constantan thermocouples were used to monitor the temperature in the reaction vessel. One was





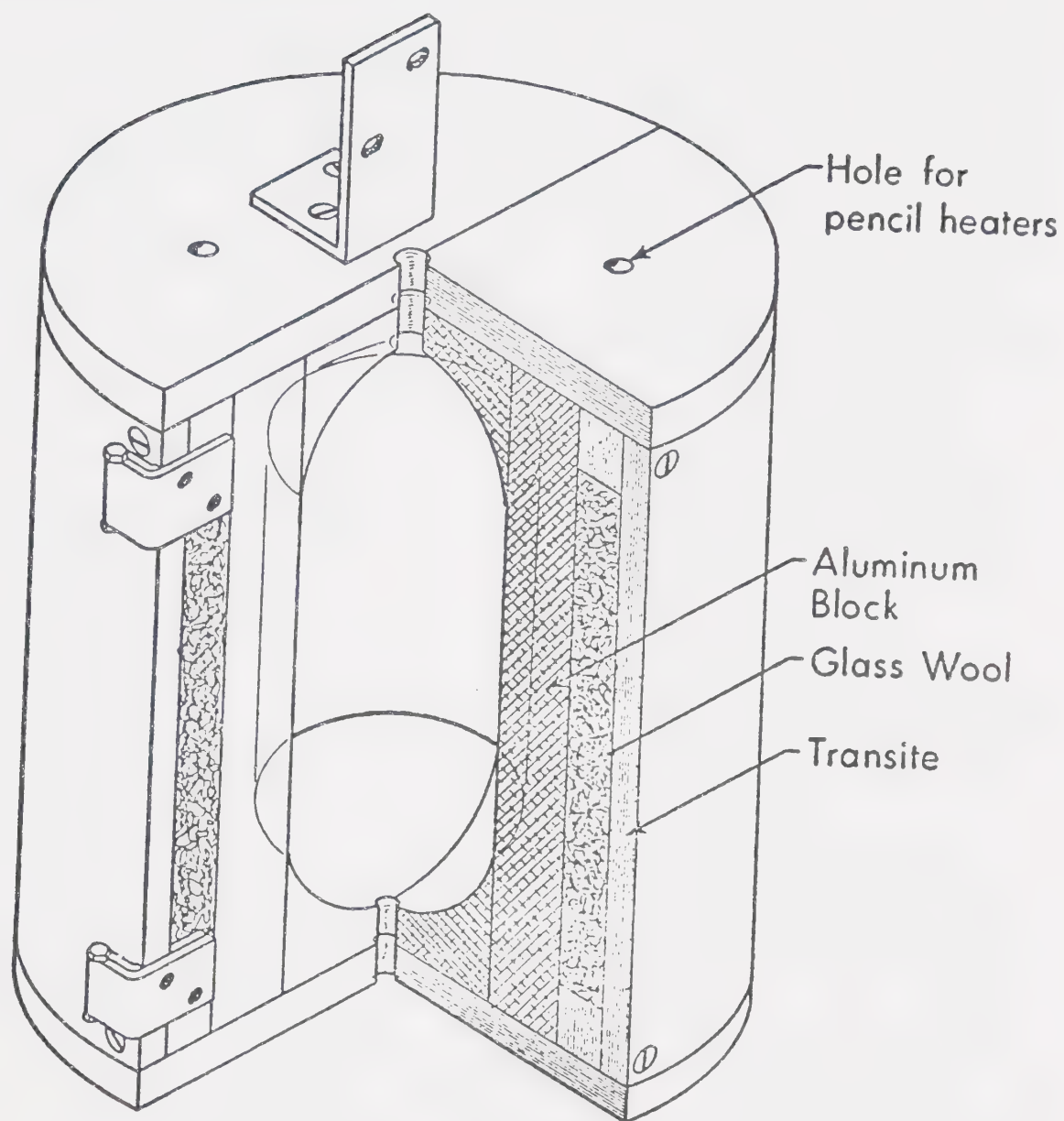


Figure II-3. Sectional View of the Pyrolytic Furnace.



positioned on the outside wall of the vessel and the other in the center of the cell by means of a special thermocouple well. The electromotive force was measured by a Wheelco Instruments potentiometer (Model 310-P), with the reference junctions of the thermocouples at 0°C. A small temperature drop in the cell ( $\sim 1.0 - 1.5^\circ\text{C}$ ) was observed immediately after a fresh reaction mixture was admitted. The temperature rose to the original preset value within 20-40 sec and thereafter remained constant (to within  $\pm 0.2^\circ\text{C}$ ). In short experiments, the reaction temperature was corrected for the initial drop.

Before use, the reaction vessel was treated with a 2:9 mixture of concentrated hydrofluoric and nitric acids, then rinsed with distilled water, acetone and methanol and dried in a vacuum oven at  $190^\circ\text{C}$ . After the vessel was attached to the vacuum system and evacuated, it was treated with gaseous trimethylchlorosilane and then thoroughly evacuated to  $10^{-6}$  torr.

Most of the experiments were carried out in a quartz cell of volume 206.6 cc with a surface/volume ratio of about  $1.0\text{ cm}^{-1}$ . The inner surface of the cell was coated by a polymer from previous experiments. For investigation of surface effects, a packed cell of volume 153.5 cc with surface/volume ratio of about  $21\text{ cm}^{-1}$  was prepared by filling a quartz vessel with quartz tubings the ends of which were fire polished.



## C. Analytical Methods

### 1. Gas Chromatography

The main analytical method employed was gas chromatography with detection by flame ionization or thermal conductivity.

(i) The thermal conductivity gas chromatograph was a component type and was coupled directly to the high vacuum system. The Gow-Mac TR-II-B detector was equipped with W2 filaments and operated at 63°C. The filament current was kept constant at 250 ma by means of a Gow-Mac 9999C power supply, and the results were read out on a Sargent recorder model RS. The carrier gas was helium; it was dried by passage through a column of molecular sieve at -196°C and its flow was regulated by a Hewlett-Packard flow controller (No. 5080-6710).

The thermal conductivity g.c. was used mainly for analyses of the product gases noncondensable at solid nitrogen temperature (-210°C), namely hydrogen and methane. Hydrogen was determined by difference. The thermal conductivity g.c. was also used for separation and identification of condensable products. After passage through the column and detector, the separated components in the effluent could be condensed in a trapping train, from which they could be transferred directly to the high vacuum system and used for mass spectral analysis or preparation of calibration mixtures.

The columns used and the operating conditions are summarized in Table II-1.



TABLE II-1  
Thermal Conductivity G.C. Operating Conditions

Column	Dimensions	Flow Rate <sup>a</sup> cc min <sup>-1</sup>	Temperature °C	Compounds Analysed
Molecular Sieve 13x, 30-60 mesh	6 ft x 6 mm i.d. glass	35	25	H <sub>2</sub> , CH <sub>4</sub>
10% Silicone gum Rubber SE-30 on Chromosorb W (AW-DMCS), 60-80 mesh	20 ft x 6 mm i.d. glass	40	50	MeSiH <sub>3</sub> Me <sub>2</sub> SiH <sub>2</sub> Me <sub>3</sub> SiH (Me <sub>2</sub> SiH) <sub>2</sub>
Porapak Q 50-80 mesh	5 ft x 6 mm i.d. glass	45	50-160	C <sub>2</sub> H <sub>4</sub> , C <sub>2</sub> H <sub>6</sub> MeSiH <sub>3</sub> C <sub>3</sub> H <sub>6</sub> , C <sub>3</sub> H <sub>8</sub> Me <sub>2</sub> SiH <sub>2</sub> Me <sub>3</sub> SiH MeEtSiH <sub>2</sub> (MeSiH <sub>2</sub> ) <sub>2</sub>

<sup>a</sup> Using helium.





(ii) The flame ionization chromatograph was a Hewlett-Packard model 5750 and was used for analysis of the reaction products condensable at liquid nitrogen temperature ( $-196^{\circ}\text{C}$ ). It was operated in a dual column-dual detector arrangement with temperature programming, as follows: 6 min post-injection interval at  $60^{\circ}\text{C}$ , temperature rise  $20^{\circ}\text{C}/\text{min}$  ( $60 \rightarrow 165^{\circ}\text{C}$ ), 20 - 40 min upper limit interval at  $165^{\circ}\text{C}$ . The dual flame detectors were operated at  $230^{\circ}\text{C}$  with hydrogen and oxygen flow rates of 20 cc/min and 200 cc/min, respectively. Helium was the carrier gas; its flow rate was 25 cc/min and it was dried as described previously. Two identical  $6' \times 1/4''$  stainless steel columns packed with Porapak Q (50-80 mesh) were used in a dual operation, one for product separation and the other as reference, in order to reduce a baseline drift during temperature programming due to column bleeding. The drift was further reduced by using teflon-coated minimum bleed septums (Unimetrics, catalog No. 2016) in the injection port. The sample was injected with a gas syringe and the results were displayed on a Minneapolis-Honeywell chart recorder model 15307856-01-05-0-000-790-07 009.

Linearity of the detector response for the substrate was determined, and the relative response factors for the products (with respect to the substrate) were obtained by calibration using authentic samples. In g.c. analyses of the



reaction mixtures, the substrate could be used as internal standard, since its concentration was practically unchanged (within experimental error ) at conversions below 1%. When silicon compounds were burned in the flame of the detector during analysis, a white powder of  $\text{SiO}_2$  was formed which deposited on both the jet and collector of the detector. The powder was periodically wiped off and the jet was cleaned by means of a fine wire. It was confirmed, by frequently repeated calibrations, that neither the white deposit nor the cleaning operations affected the relative response factors of the detector.

The compounds which were analyzed by means of the flame ionization g.c. are listed below in the order of their retention times: ethylene, ethane, monomethylsilane, propylene, propane, dimethylsilane, trimethylsilane, methylethylsilane, dimethylethylsilane, 1,2-dimethyldisilane, 1,1,2,2-tetramethyldisilane. Product identifications were accomplished by comparison of their g.c. retention times and mass spectra with those of authentic samples. Since authentic samples of methylethylsilane and dimethylethylsilane were not available, the identification of these compounds was based on analysis of their mass spectra, listed in Appendices I and II.



## 2. Mass Spectral Analysis

Mass spectra were obtained on Associated Electronics Industries instruments, models MS 2 and MS 12. On both of these instruments, it was possible to carry out gas chromatographic analysis with simultaneous mass spectrometry of each peak as it eluted from the column.

Hydrogen isotope ratios were determined on Associated Electronics Industries Models MS 10 and MS 2 mass spectrometers.

## D. Experimental Procedure

### 1. Pyrolysis

Before the experiment, the reaction vessel was thoroughly evacuated to  $10^{-6}$  torr and its temperature was preset to the desired value. Pure substrate from the storage tank was condensed in bulb A (see Figure II-1) by liquid nitrogen. Bulb A was then warmed to room temperature and the pressure of the substrate was measured with a mercury manometer. The volume of bulb A and that of the adjacent manifold leading to the manometer were calibrated. The manometer pressure was read by means of a cathetometer with a precision better than  $\pm 0.05$  torr and the substrate was admitted to the reaction vessel by a momentary opening of the valve attached to the reactor. While the reaction was in progress, the remaining substrate in the manifold was transferred to bulb A. The actual pressure in the reaction vessel



was calculated from the difference. Since the conversions were generally low, 0.1 - 0.5% ( $\sim 1\%$  maximum), any pressure changes in the reaction vessel were negligible and there was no special need for any pressure monitoring device in the reaction vessel. On the contrary, it could be a source of an additional error by increasing dead space of the reactor.

In the experiments with mixtures of gases, the reactant pressures were individually measured and then the components condensed together in bulb A. With the valve to the manifold closed, the bulb was suddenly submerged into a hot water bath and allowed to stand for several hours to assure good mixing.

## 2. Product Analysis

After pyrolysis, the reaction mixture was passed through two traps at  $-196^{\circ}\text{C}$  and  $-210^{\circ}\text{C}$  respectively.

(i) The gases noncondensable at  $-210^{\circ}\text{C}$  were pumped off with a one-stage mercury diffusion pump and a Toepler pump and measured in a gas burette. The pumps were operated continuously for about 30 minutes after the end of each experiment and during this period readings of the gas burette were taken in 6 minute intervals, in order to get some information about gas evolution from the polymer in the reaction vessel. From the gas burette, the noncondensable gases were transferred quantitatively by means of a second





Toepler pump into the evacuated sample loop of the thermal conductivity g.c. and introduced to the column for analysis.

(ii) The reaction products condensable at  $-210^{\circ}\text{C}$  were usually present only in minute quantities ( $< 0.02 \mu\text{ moles}$ ), very often too small to be measured in a gas burette.

Measurable quantities of this fraction were obtained in the pyrolysis of monomethylsilane at high conversions ( $> 1\%$ ) and mass spectrometric analysis indicated the presence of monosilane.

(iii) The entire condensable ( $-196^{\circ}\text{C}$ ) reaction mixture, consisting of substrate and products, was first measured in a gas burette and then quantitatively transferred into a Pyrex ampoule fitted with a mercury covered Burrel Silicone rubber seal. The mixture was allowed to warm up and the internal pressure was raised to 760 torr by introducing helium with a gas syringe. The ampoule contents were mixed by pumping with the gas syringe and a suitably sized sample ( $5 - 100 \mu\text{l}$ ) was then withdrawn for injection into the flame ionization g.c. described in Section II-C-1. The injection was usually repeated several times for the same mixture to insure higher precision. Knowing the total amount of sample and relative response factors of the detector for the major components, the composition of the mixture could be determined from the relative peak areas measured with a planimeter.



### 3. Substrate Purification

Special methods of purifying monomethylsilane and dimethylsilane were developed. The auxiliary vacuum system shown in Figure II-2 was used for this procedure.

#### (i) Monomethylsilane

A major impurity in monomethylsilane (MMS) was dimethylsilane (DMS) which, although present in quantities less than 1%, was nevertheless one of the reaction products in the pyrolysis of MMS and therefore it was necessary to remove it from the substrate completely. A simple low temperature distillation did not give satisfactory results since the vapor pressures of MMS and DMS are quite similar. An excellent separation, however, was obtained by distilling the mixture through a Porapak Q column and collecting only the first fraction.

The purity of MMS from this fraction was checked by flame ionization g.c., which was capable of detecting impurity levels less than 0.001%, and no traces of DMS were found. A high efficiency of purification was the main advantage of the method since in a single operation, lasting less than 10 minutes, it was possible to obtain pure substrate in quantities sufficient for 10-30 experimental runs (about 20 moles).

The column was a Pyrex spiral trap (6 ft long, 9 mm i.d.) packed with Porapak Q (80-100 mesh). Before use,



it was first purged by a stream of dried helium at 190°C for several hours, allowed to cool to room temperature, and then thoroughly evacuated to less than  $10^{-5}$  torr, usually overnight.

Methylsilane (previously distilled at -139°C and degassed at -160°C) was transferred into a U-trap adjacent to the column and its pressure maintained at about 600 torr by means of a low temperature bath of dimethylmalonate slush. The Porapak column was operated at 0°C. The impure MMS was admitted into the column and the fraction which passed through within 8 minutes was collected in the second U-trap at -196°C. After a purity check, this fraction was transferred into a storage bulb. The remaining impure MMS was then removed from the distillation line and helium was passed through the heated column in order to prepare it for the next purification cycle.

Monomethylsilane- $d_3$  was also purified in the same manner.

#### (ii) Dimethylsilane

The major impurities in dimethylsilane (DMS) were monomethylsilane (MMS), trimethylsilane (TMS), and traces of propane. Since MMS and TMS were both reaction products of the pyrolysis of DMS, they must be removed from the substrate. Removal of MMS and propane was accomplished by a repeated degassing of DMS at -130°C (n-pentane slush). In order to remove TMS, DMS was first distilled at -115°C



(ethanol slush) and then passed through the Porapak Q column, as in the case of MMS. The column was operated at 25°C, the pressure of impure DMS was maintained at about 150 torr by means of a chloroform slush (-64°C), and the fraction of pure DMS eluted in 6 minutes was retained.

#### E. Materials

The materials used, their source and their purification are listed in Table II-2.

Authentic samples of 1,2-dimethyldisilane and 1,1,2,2-tetramethyldisilane were prepared by the mercury photosensitized decomposition of monomethylsilane (MMS) and dimethylsilane (DMS), respectively, as described by Nay et al.<sup>31</sup>. The photolysis cell in the auxiliary vacuum system (Section II-A) was filled with about 400 torr of substrate silane and irradiated at room temperature for 2 hrs; the disilane product was separated from the substrate by a low temperature distillation at -130°C and -115°C for MMS and DMS, respectively, and purified by preparative g.c. by means of the thermal conductivity gas chromatograph. The columns and conditions used are listed in Table II-1.





TABLE II-2

## Materials Used

Material	Supplier	Purification
Helium	Canadian Liq. Air; Linde	Passed through column of molecular sieve at -196°C.
Hydrogen (for g.c.)	Canadian Liq. Air; Linde	None
Oxygen (for g.c.)	Canadian Liq. Air; Linde	None
Methane	Matheson	None
Ethylene	Philipps Petroleum <sup>a</sup>	Degassed at -186°C. Distilled at -160°C.
Monosilane	Merck, Sharp and Dohme	Degassed at -196°C. Distilled at -160°C.
Monomethylsilane	Merck, Sharp and Dohme	As described in Section II-D-3.
Monomethylsilane-d <sub>3</sub>	Merck, Sharp and Dohme	As described in Section II-D-3.
Dimethylsilane	Peninsular	As described in Section II-D-3.



TABLE II-2 (cont'd)  
Materials Used

Material	Supplier	Purification
Trimethylsilane	Chemical Procurement	Degassed at -112°C. Distilled at -98°C.
1,2-Dimethyldisilane	Laboratory preparation as described in Section II-E.	Preparative g.c.; conditions as in Table II-1.
1,1,2,2-Tetramethyldisilane	Laboratory preparation as described in Section II-E.	Preparative g.c.; conditions as in Table II-1.
Trimethylchlorosilane	PCR Incorporated	Fractional Distillation at 760 torr; a fraction boiling at 56-58°C was collected.

<sup>a</sup> Research Grade, purity 99.99%.



## CHAPTER III

### PYROLYSIS OF MONOMETHYLSILANE

#### A. Results

The pyrolysis of monomethylsilane was studied in a static system over the range of conditions 340 - 440°C and 40 - 400 torr initial substrate pressure. The investigation was focussed on the initial stages of the reaction (conversions below 1%) where secondary decompositions are minimal. The effects of time, reaction vessel surface, and addition of a free radical scavenger were investigated in order to determine the nature of the processes responsible for the observed products.

##### 1. The Reaction Products and Their Distribution

The following products were observed in the early stages of pyrolysis of monomethylsilane (MMS): hydrogen, 1,2-dimethyldisilane (DMDS), dimethylsilane (DMS), monosilane, methane, and a dark brown polymer deposited on the inner surface of the reaction vessel.

Hydrogen and DMDS were the major reaction products and DMS was a minor product; monosilane and methane were formed occasionally in trace amounts and often could not be detected at all (the detection limits



for  $\text{SiH}_4$  and  $\text{CH}_4$  were approximately 0.015 and 0.005  $\mu$  moles, respectively).

Polymer was another minor reaction product, and since it could not be directly measured and analyzed, its formation created certain complications. Some of the problems associated with polymer formation are reported later; it should be pointed out here, however, that reproducible reaction rates were obtained only in a vessel which was well coated by a polymer from previous runs.

#### (i) Gaseous Products

The only significant reaction products formed in the initial stages of MMS decomposition ( $< 1\%$  conversion) were hydrogen, DMDS and minor amounts of DMS. The ratio  $\text{H}_2/\text{DMDS}$  was approximately  $1.15 \pm 0.10$ , and both products showed a linear dependence on time. The amount of DMS formed was about 5% of that of the major products.

At conversions above 1%, the product distribution was altered considerably. The rates of formation of  $\text{H}_2$  and DMS were enhanced whereas that of DMDS declined; also, some monosilane could be detected among the reaction products.

Product yields as a function of time at  $422^\circ\text{C}$  and  $\sim 127$  torr are listed in Table III-1, and illustrated in Figure III-1. The experiments were performed in a





TABLE III-1

Variation of the Product Yields with Time in the  
Pyrolysis of  $\text{MeSiH}_3$  at  $422^\circ\text{C}$  <sup>a</sup>

Time, min	Yields, $\mu$ moles				Conversion <sup>b</sup> %
	$\text{H}_2$	DMDS	DMS	$\text{SiH}_4$	
3.0	2.18	1.83	0.09	c	0.37
4.0	2.99	d	d	c	0.49
6.0	4.37	3.76	0.20	c	0.69
12.0	9.30	7.57	0.84	0.27	1.51
12.0	8.06	7.29	0.56	0.02	1.32
18.0	13.87	10.51	1.51	0.13	1.77
24.0	19.54	11.55	2.91	0.10	3.32

<sup>a</sup> Pressure 124 - 130 torr; cell volume 206.6 cc;  
 $S/V = 1.0 \text{ cm}^{-1}$ .

<sup>b</sup> Based on the yield of  $\text{H}_2$ .

<sup>c</sup> Too small to measure ( $< 0.02 \mu$  mole).

<sup>d</sup> Not measured.



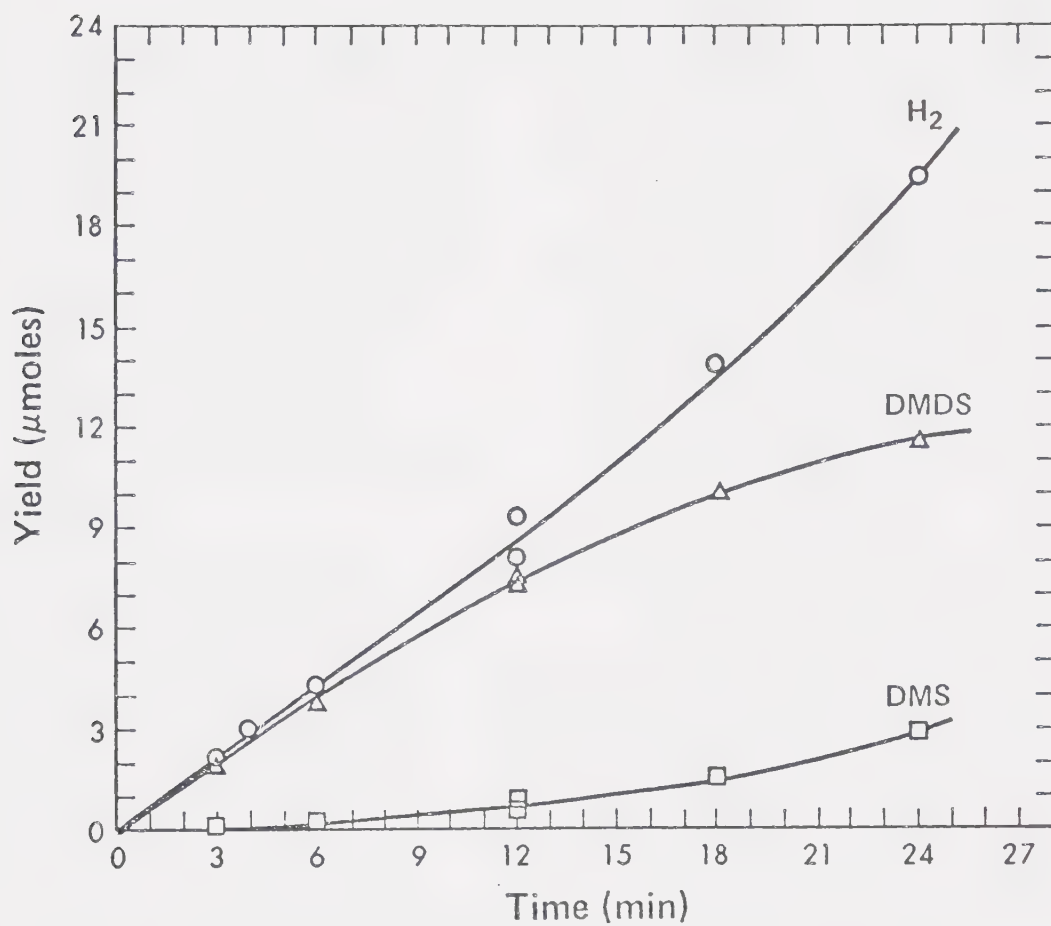


Figure III-1. Product Yields as a Function of Time in the Pyrolysis of MeSiH<sub>3</sub> at 422°C.



reaction vessel of volume 206.6 cc (surface/volume ratio  $1.0 \text{ cm}^{-1}$ ) which was already coated by a polymer.

Upon carrying out the pyrolysis to conversions of 10 - 20% or higher, the reaction system became quite complex and a large variety of new products were formed, not all of which were identified; however, DMS was one of the dominant condensable products and it was present in quantities higher than those of DMDS, indicative of the high thermal stability of DMS. An example of the product yields at conversion of 20.5% is given in Table III-2.

The investigation was therefore limited only to the initial stages of pyrolysis of MMS, i.e. to such conversion where secondary decomposition of the primary products was negligible. Most experiments were carried out to 0.1 - 0.5% conversions, and occasionally as high as 1% in order to obtain sufficient amounts of reaction products for analyses.

#### (ii) Polymer

Preliminary experiments in a new reaction vessel revealed that the reaction rates were both high and erratic and that only after carrying out several runs to high conversions, after which the inner surface of the vessel became coated by a polymer, did the rates become lower and quite reproducible.



TABLE III-2

Product Yields in the Pyrolysis of  $\text{MeSiH}_3$  at High Conversion

Temp. °C	Time, min	P(MMS), <sup>a</sup> torr	MMS consumed, μ moles	Yield <sup>c</sup> , μ moles			Conversion <sup>b</sup> %
				H <sub>2</sub>	DMDS	$\frac{\text{DMS}}{\text{SiH}_4}$ CH <sub>4</sub>	
360	4750.0	88.0	93.9	94.4	5.74	17.1 2.02 1.57	20.5

<sup>a</sup> Initial pressure in a vessel of volume 206.6 cc;  $S/V = 1.0 \text{ cm}^{-1}$ .<sup>b</sup> Based on the yield of H<sub>2</sub>.<sup>c</sup> Some other minor products were formed but were not analyzed.





The chemical composition of the polymer was not analyzed. Although a mass balance between gaseous products and monomethylsilane reacted was attempted, no definite conclusions could be reached since most experiments were carried out at very low conversions where the yield of polymer is extremely small and well within experimental error of the amount of MMS reacted.

The polymer was found to be thermally unstable, since a slow evolution of gases from the coated vessel could be observed upon heating, nevertheless it could not be completely removed from the cell even by a prolonged heating in a vacuum. The rate of degassing, however, was extremely slow when the experiments were carried out to conversions below 1%, and the amount of products which could be collected from the decomposing polymer was not sufficient for analysis.

At high conversions however a large quantity of the polymer accumulated in the reaction vessel and it was possible to follow the polymer decomposition for a long period of time (about 8 hrs) and to monitor its rate. In a typical experiment, listed in Table III-2, 8 torr MMS was pyrolyzed for about 79 hrs at 360°C ( $\sim$  20.5% conversion). The reaction vessel was opened to the main vacuum line for 30 min and then the rate of evolution of the light gases was measured.



The light gases evolved from the polymer consisted mainly of hydrogen and methane; some condensable products were also formed in trace quantities, and the presence of lower hydrocarbons ( $C_2$ ,  $C_3$ ) and all methylated monosilanes was confirmed.

The data obtained for the light gases are shown in Table III-3 and plotted in Figure III-2, from which it is seen that the rate of degassing was very steady even after several hours and therefore could be treated quantitatively.

Since hydrogen was also one of the major reaction products of the pyrolysis of MMS, it was necessary to determine the relative importance of hydrogen formation from the thermolysis of the polymer.

After prolonged heating and evacuation of the reaction vessel, the rate of gas evolution declined and then finally became unmeasurably slow or ceased completely. (The time needed to reach this stage could vary from several hours to a few days, depending on the temperature used and the amount of polymer deposited previously.) When such a vessel was used for pyrolysis of MMS at conversions below 1%, no significant degassing from the vessel was observed, indicating that the polymer was only a very minor product and its decomposition was not important compared to the pyrolysis of MMS.



TABLE III-3  
The Yield of Gases <sup>a</sup> from Polymer  
Decomposition at 360°C as a Function  
of Time

Time, min	Yield, μ mole	Time, min	Yield, μ mole
16.0	0.04	225.0	0.67
26.0	0.08	254.0	0.74
36.0	0.11	265.0	0.79
46.0	0.13	290.0	0.85
56.0	0.16	300.0	0.89
66.0	0.19	325.0	0.95
76.0	0.21	335.0	0.99
86.0	0.24	350.0	1.03
96.0	0.27	361.0	1.06
104.0	0.28	371.0	1.08
121.0	0.34	400.0	1.17
131.0	0.38	411.0	1.21
160.0	0.46	420.0	1.24
170.0	0.49	430.0	1.26
180.0	0.53	440.0	1.29
191.0	0.55	450.0	1.31
200.0	0.59	463.0	1.34
213.1	0.63	470.0	1.36 <sup>b</sup>

<sup>a</sup>  $\text{H}_2 + \text{CH}_4$  .

<sup>b</sup> Contains ~ 0.06 μ mole  $\text{CH}_4$  and ~ 1.30 μ mole  $\text{H}_2$  .



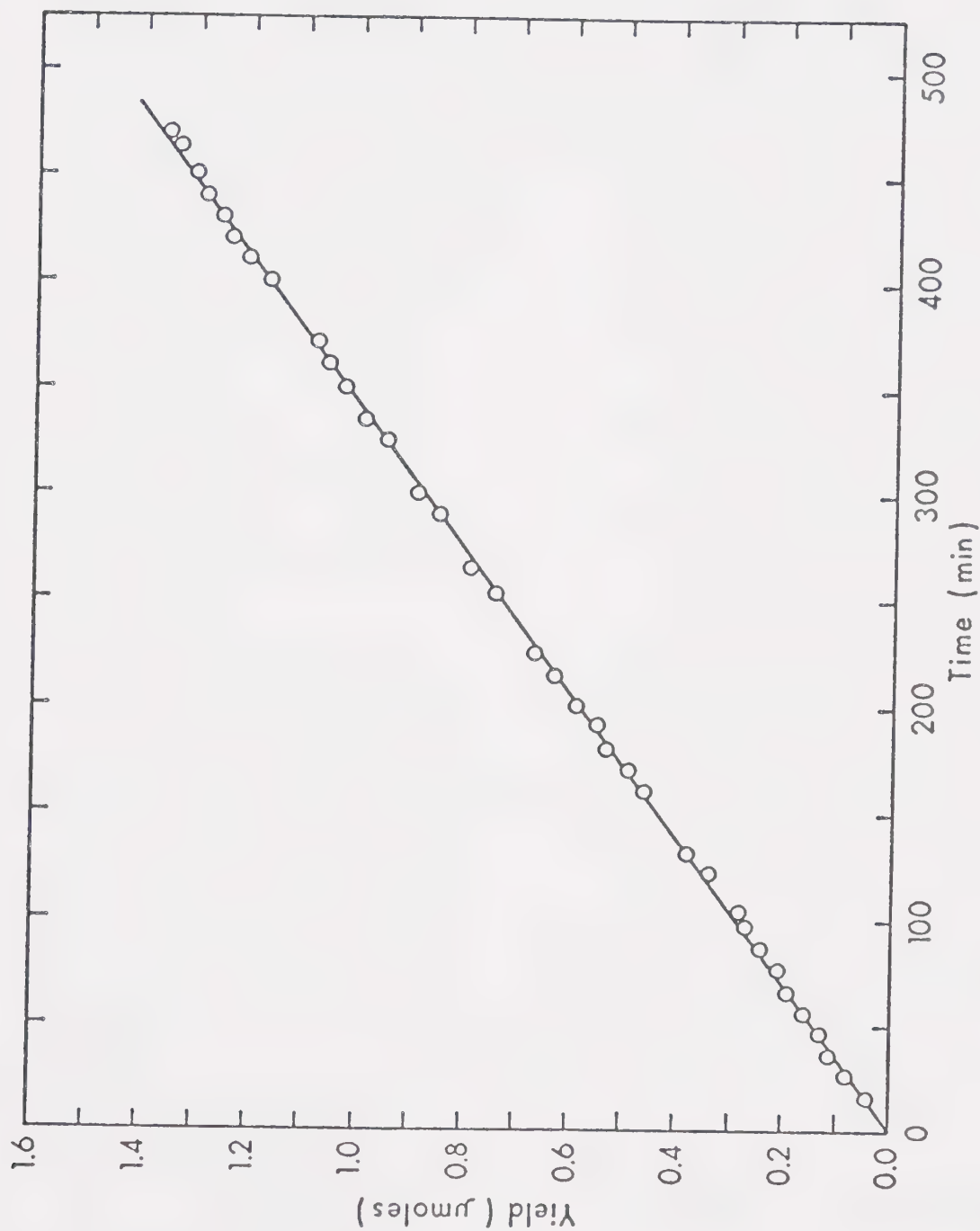


Figure III-2.  $\text{H}_2 + \text{CH}_4$  Yields from Polymer Decomposition at  $360^\circ\text{C}$  as a Function of Time.





To summarize, reproducible rates could be obtained in a seasoned reaction vessel provided the conversions were kept below 1%. In those cases where extensive decomposition of MMS had occurred, or when a large number of experiments had been performed in short consecutive intervals and the polymer deposit was relatively heavy, a simple correction could be made to the observed  $H_2$  yields assuming that the rates of decomposition of the polymer and of the substrate are independent. The procedure is illustrated in Appendix III. Alternatively, the reaction vessel could be heated and evacuated until no gas evolution could be detected.

## 2. Reaction Order of Hydrogen Formation

In order to obtain some insight into the kinetic features of the decomposition of monomethylsilane, experiments were carried out to determine the initial order of formation of hydrogen. The polymer coated vessel was heated at the reaction temperature and evacuated before each run for at least several hours, usually overnight, in order to minimize any possible contribution from decomposition of the polymer.

The reaction order of hydrogen formation can be calculated using the relationship

$$R(H_2) = k_{H_2} [MMS]^n$$



where  $R(H_2)$ ,  $k_{H_2}$ ,  $[MMS]$ , and  $n$  are the initial rate of hydrogen formation, specific rate constant, initial substrate concentration, and order, respectively. The slope of the logarithmic plot of rate vs substrate pressure yields the order of reaction.

The reaction orders were determined over the temperature range 341 - 441°C and the results of the rate data, given in Tables III-4 to III-7 are presented in the form of log - log plots in Figures III-3 and III-4.

The orders, determined by least mean square analyses, are summarized in Table III-8 and are seen to increase from unity, at 441°C, to 1.63 at 341°C.

### 3. Surface Effects and Influence of the Polymer on Surface Activity

The kinetics of gas phase thermal reactions are often complicated by contributions from heterogeneous reactions. Surface reactions are generally very complex phenomena, influenced by surface activity and difficult to control and reproduce, and their occurrence should be minimized in the studies of homogeneous reactions. Surface reactions are particularly prevalent in new, unused reaction vessels, and the walls of the vessel often require a special treatment in order to suppress surface effects; the most usual way is to pyrolyze the substrate repeatedly until the experimental results become



TABLE III-4

Variation of the Hydrogen Yield with  
Monomethylsilane Pressure at Different Temperatures <sup>a</sup>

P(MMS), torr	Time, min	H <sub>2</sub> Yield, μ mole	Conversion, %
<u>441°C</u>			
215.7	0.90	3.03	0.302
171.5	1.01	2.47	0.311
153.7	1.00	2.62	0.367
118.0	1.00	1.57	0.287
104.1	1.00	1.59	0.329
80.8	1.01	1.05	0.280
70.3	1.05	1.18	0.359
57.6	1.50	1.11	0.416
48.2	1.20	0.80	0.357
39.5	2.00	1.02	0.557
32.3	2.00	0.87	0.579
<u>429°C</u>			
203.5	1.50	2.97	0.310
138.2	1.50	1.76	0.270
94.0	2.00	1.38	0.311
63.7	3.00	1.41	0.469
42.8	4.00	1.24	0.614

<sup>a</sup> Cell volume 206.6 cc.



TABLE III-5

Variation of the Hydrogen Yield with  
Monomethylsilane Pressure at 421°C <sup>a</sup>

P(MMS), torr	Time, min	H <sub>2</sub> Yield, μ mole	Conversion, %
214.3	2.50	2.34	0.229
177.0	2.50	1.87	0.221
147.1	2.50	1.53	0.218
125.7	3.20	1.66	0.277
120.2	3.00	1.48	0.258
100.3	3.05	1.21	0.253
81.4	4.50	1.44	0.371
69.2	4.50	1.18	0.358
55.7	6.00	1.26	0.474
47.1	6.50	1.13	0.504
31.6	9.00	1.05	0.697

<sup>a</sup> Cell volume 206.6 cc.





TABLE III-6

Variation of the Hydrogen Yield with  
Monomethylsilane Pressure at 400°C <sup>a</sup>

P(MMS), torr	Time, min	H <sub>2</sub> Yield, μ mole	Conversion, %
212.3	6.00	1.84	0.176
209.0	6.00	1.50	0.146
202.9	10.00	2.75	0.276
148.5	10.00	1.85	0.253
144.4	10.00	1.73	0.244
135.8	7.10	1.19	0.178
138.6	11.00	1.81	0.266
93.9	10.00	1.09	0.236
91.8	10.00	0.99	0.219
73.7	15.00	1.22	0.337
62.9	15.30	1.03	0.333
61.9	13.00	0.84	0.276
48.5	15.00	0.80	0.335
42.3	20.00	0.87	0.418
33.7	24.00	0.80	0.483

<sup>a</sup> Cell volume 206.6 cc.



TABLE III-7

Variation of the Hydrogen Yield with  
Monomethylsilane Pressure at Different Temperatures <sup>a</sup>

P(MMS), torr	Time, min	H <sub>2</sub> Yield, μ mole	Conversion, %
<u>381°C</u>			
212.8	16.50	1.58	0.147
210.2	11.00	1.09	0.102
145.2	21.50	1.15	0.156
141.5	26.00	1.34	0.187
96.5	30.00	0.94	0.192
65.2	31.00	0.60	0.182
42.9	47.00	0.57	0.263
28.4	90.00	0.73	0.508
<u>361°C</u>			
92.6	148.0	1.26	0.260
62.1	210.0	1.03	0.318
40.5	280.0	0.85	0.402
<u>341°C</u>			
195.8	275.0	2.32	0.220
128.2	325.5	1.34	0.194
84.5	553.0	1.19	0.261

<sup>a</sup> Cell volume 206.6 cc.



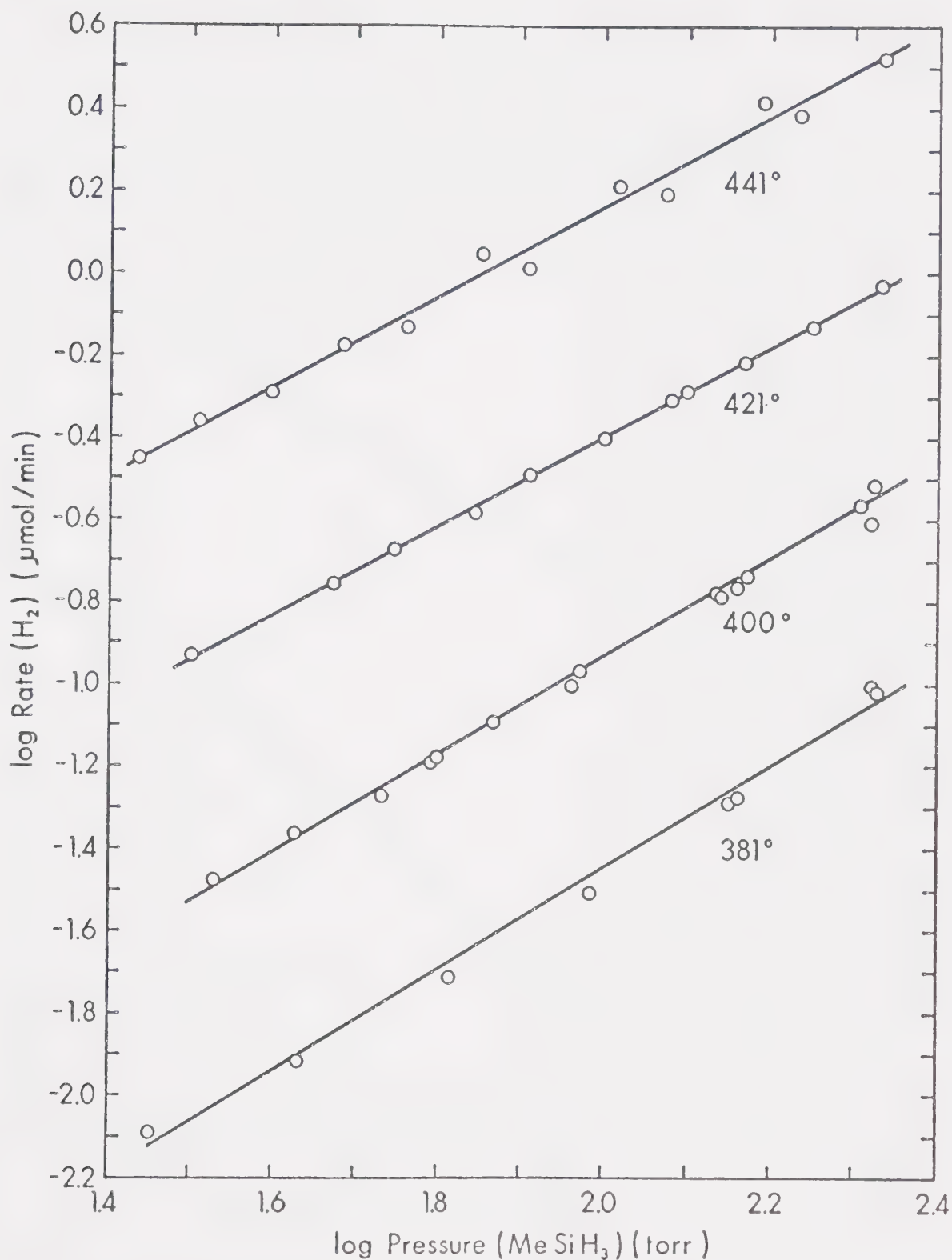


Figure III-3. Order Plots for  $\text{H}_2$  Formation in the Pyrolysis of  $\text{MeSiH}_3$  at 381, 400, 421 and 441°C.



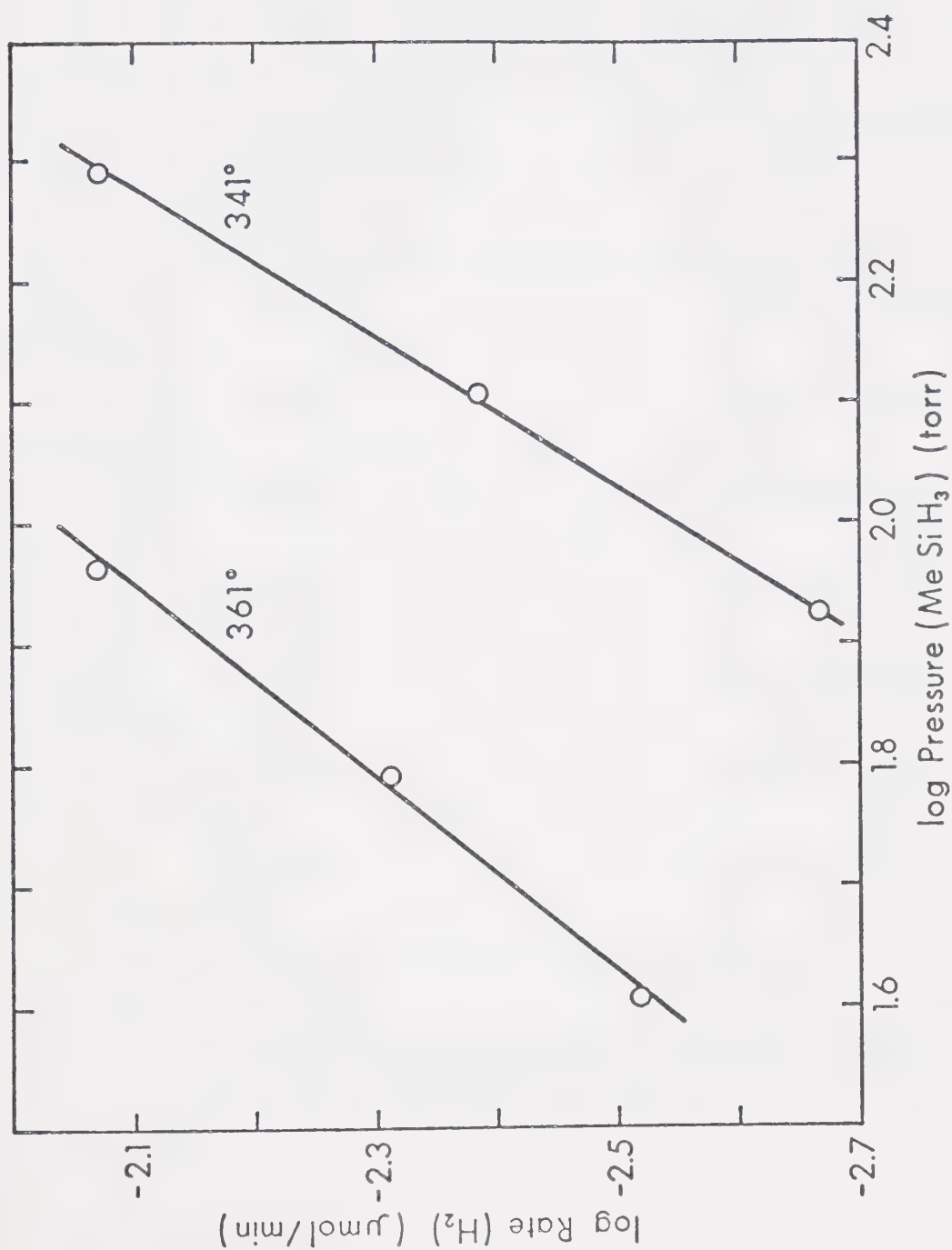


Figure III-4. Order Plots for  $\text{H}_2$  Formation in the Pyrolysis of  $\text{MeSiH}_3$  at  $341^\circ\text{C}$  and  $361^\circ\text{C}$ .





TABLE III-8  
Reaction Order of Hydrogen Formation  
in the Pyrolysis of Monomethylsilane  
at Different Temperatures <sup>a</sup>

Temperature °C	Order
441	1.09 $\pm$ 0.04
429	1.19 $\pm$ 0.03
421	1.09 $\pm$ 0.01
400	1.17 $\pm$ 0.02
381	1.27 $\pm$ 0.04
361	1.24 $\pm$ 0.08
341	1.63 $\pm$ 0.04

<sup>a</sup> In unpacked reaction vessel of volume  
206.6 cc, S/V = 1.0 cm<sup>-1</sup>.



reproducible. However, even when the reaction vessel has been "seasoned" in this way and reproducibility attained, some of the reaction can still be occurring on the walls.

The influence of surfaces on the rate of the reaction is normally investigated in two ways: first, by varying the surface area to volume ratio ( $S/V$ ) and secondly, by changing the nature of the surface. Both effects were investigated.

#### (i) Effect of Variation of the Surface/Volume Ratio

In order to examine the effect of the variation of the surface/volume ratio on the reaction rates, the pyrolysis of monomethylsilane was carried out at  $415^{\circ}\text{C}$  at various reaction times and initial pressures of the substrate in packed and unpacked reaction vessels having  $S/V$  ratios of  $21\text{ cm}^{-1}$  and  $1.0\text{ cm}^{-1}$ , respectively.

The surface of both vessels was coated by a polymer from previous runs and the vessels were heated at  $415^{\circ}\text{C}$  and evacuated in between experiments, usually overnight. (The vessels were initially "seasoned" by repeated pyrolysis of about 70 torr MMS at  $415^{\circ}\text{C}$  for 10.0 min, until the experimental results become reproducible; about 5 to 10 runs were required to attain reproducibility. The required conversions of the seasoning experiments increased with increasing surface area of the



vessel.) The degassing from the reaction vessels, caused by decomposition of the polymer, was monitored before and after each run, and in those cases where evolution of gases were observed, a correction for the  $H_2$  yield was applied, cf. Appendix III.

Firstly, time studies were carried out in the packed vessel at  $415^\circ C$  and at initial substrate pressures of about 51, 102 and 204 torr, to investigate the nature of secondary processes at high conversions. The results, Tables III-9 and III-10, were found to be similar to those obtained in an unpacked vessel at  $422^\circ C$  and 127 torr (as shown in Table III-1 and Figure III-1), confirming the linear dependence of  $H_2$  and DMDS formation on time in both vessels, at conversions below 1%. DMS was again a minor product.

The product yields as a function of MMS pressure at  $415^\circ C$  in the packed and unpacked vessels are listed in Tables III-11 and III-12, respectively. The rates of formation of hydrogen, DMDS and DMS at  $415^\circ C$  and at various MMS pressures in two different vessels are compared in Figures III-5, III-6 and III-7, respectively, using logarithmic order plots.

The results indicated that the pyrolysis of MMS might be partly heterogeneous, since the rates of formation of all the products in the packed vessel appeared



TABLE III-9  
The Products of  $\text{MeSiH}_3$  Pyrolysis as a Function  
of Reaction Time at  $416^\circ\text{C}$  <sup>a</sup>

Time, min	Yields, $\mu$ moles				Conversion, <sup>b</sup> %
	$\text{H}_2$	DMDS	DMS	$\text{SiH}_4$	
5.00	2.07	1.92	0.23	0.12	0.56
6.00	1.76	1.58	0.11	0.08	0.48
8.00	2.91	2.48	0.28	c	0.80
10.00	3.72	3.60	0.49	c	1.03
10.00	3.35	2.93	0.32	0.10	0.92
15.00	d	3.94	0.78	c	-
15.00	5.21	d	d	c	1.43
15.00	5.30	4.04	0.53	0.22	1.43
23.20	9.67	5.83	1.29	0.15	2.62

<sup>a</sup> Pressure of MMS 101 - 104 torr; cell volume 153.5 cc;  
 $S/V = 21 \text{ cm}^{-1}$ .

<sup>b</sup> Based on the yield of  $\text{H}_2$ .

<sup>c</sup> Too small to measure in gas burette ( $< 0.02 \mu$  mole).

<sup>d</sup> Not measured.





TABLE III-10  
The Products of  $\text{MeSiH}_3$  Pyrolysis as a Function  
of Reaction Time at  $415^\circ\text{C}$  <sup>a</sup>

Time, min	Yields, $\mu$ mole				Conversion, <sup>b</sup> %
	H <sub>2</sub>	DMDS	DMS	SiH <sub>4</sub>	
<hr/>					
	<u>202 - 205 torr</u>				
2.50	1.76	1.74	0.08	c	0.24
3.00	2.50	2.11	0.14	0.05	0.34
4.00	2.91	3.13	0.17	0.02	0.40
5.00	4.25	3.50	0.28	0.02	0.59
6.00	4.42	4.32	0.28	0.06	0.61
7.50	6.33	4.91	0.44	0.03	0.88
8.00	6.16	5.50	0.40	0.01	0.85
10.00	10.10	7.56	0.98	0.08	1.41
	<u>50.0 - 51.8 torr</u>				
2.50	0.35	0.29	0.01	c	0.19
8.00	1.08	0.97	0.05	c	0.60
10.00	1.41	1.15	0.10	c	0.78
12.50	1.68	1.26	0.11	c	0.91
15.00	2.12	1.67	0.185	c	1.19

<sup>a</sup> Cell volume 153.5 cc;  $S/V = 21 \text{ cm}^{-1}$ .

<sup>b</sup> Based on the yield of  $\text{H}_2$ .

<sup>c</sup> Too small to measure in gas burette; less than 0.02  $\mu$  moles.



TABLE III-11

Product Yields as a Function of Pressure of  
 $\text{MeSiH}_3$  at  $415^\circ\text{C}$  in a Packed Vessel <sup>a</sup>

P( $\text{MeSiH}_3$ ), torr	Time, min	Yields, $\mu$ moles		
		$\text{H}_2$	DMDS	DMS
514.3	2.50	5.05	4.68	0.123
363.5	2.00	3.64	3.65	0.155
361.4	2.50	3.71	3.17	0.139
362.8	2.50	3.30	3.18	0.100
268.3	2.00	2.33	2.17	0.100
269.4	2.50	1.86	1.84	0.036
205.4	4.00	2.91	3.13	0.165
203.7	6.00	4.42	4.32	0.28
203.3	2.50	1.76	1.74	0.081
206.4	2.50	1.26	1.20	0.018
154.1	2.50	1.17	1.16	0.054
113.5	3.00	1.03	0.94	0.055
102.0	6.00	1.76	1.58	0.110
76.0	2.50	0.51	0.40	0.020
51.7	2.50	0.35	0.29	0.011
50.4	8.00	1.08	1.01	0.050

<sup>a</sup> Volume 153.5 cc,  $S/V = 21 \text{ cm}^{-1}$ .



TABLE III-12

Product Yields as a Function of Pressure of  
 $\text{MeSiH}_3$  at  $415^\circ\text{C}$  in the Unpacked Vessel <sup>a</sup>

P( $\text{MeSiH}_3$ ), torr	Time, min	Yields, $\mu$ moles		
		$\text{H}_2$	DMDS	DMS
468.1	2.50	7.43	4.80	0.44
460.8	10.00	20.87	18.13	0.65
400.7	2.00	3.63	3.20	0.10
404.8	2.00	3.46	2.76	0.074
407.8	2.00	3.03	2.76	0.060
241.5	2.50	1.98	1.85	0.052
224.9	2.50	4.15	3.43	0.30
201.5	2.50	1.63	b	b
154.8	2.50	1.31	0.95	0.023
138.5	2.50	1.15	0.78	0.022
144.2	12.00	4.93	4.23	0.090
109.1	2.50	0.80	0.66	0.010
62.4	2.50	0.40	0.46	0.033
49.3	2.50	0.32	0.42	0.004
48.9	3.00	b	0.38	0.004
45.4	3.00	0.36	0.31	0.004

<sup>a</sup> Volume 206.6 cc,  $\text{S/V} = 1.0 \text{ cm}^{-1}$ .

<sup>b</sup> Not measured.



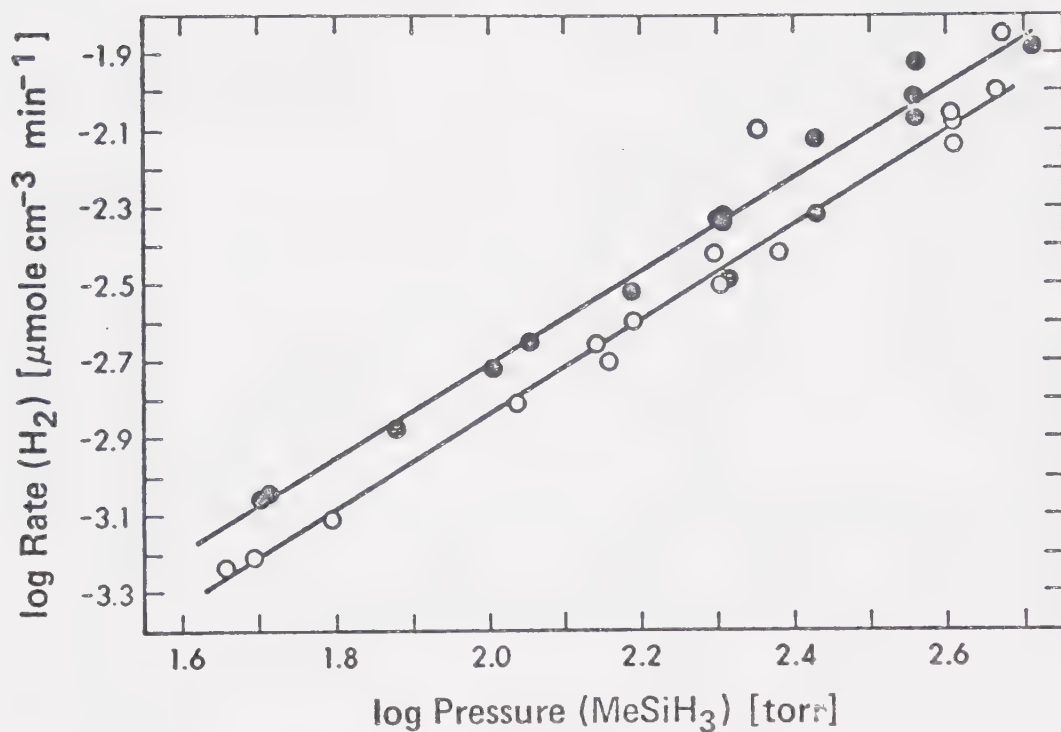


Figure III-5. Rate of H<sub>2</sub> Formation as Function of MeSiH<sub>3</sub> Pressure at 415°C in Reaction Vessels of Different S/V Ratios;  
 O , 1.0 cm<sup>-1</sup>; ● , 21 cm<sup>-1</sup>.





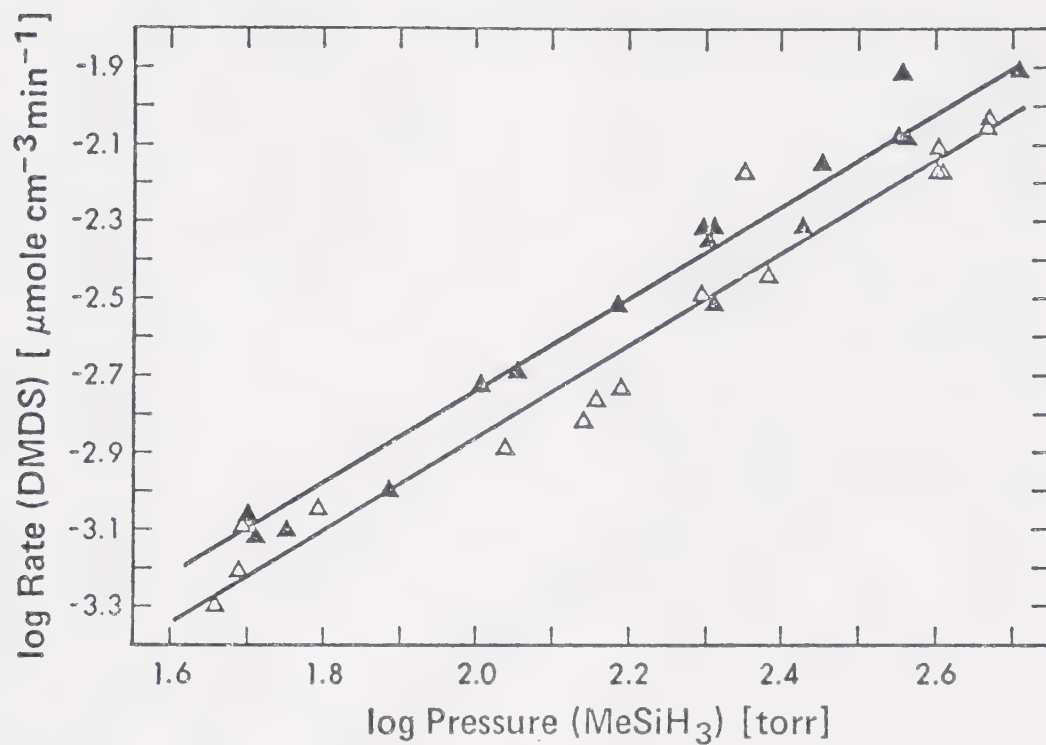


Figure III-6. Rate of DMDS Formation as Function of MeSiH<sub>3</sub> Pressure at 415°C in Reaction Vessels of Different S/V Ratios; Δ , 1.0 cm<sup>-1</sup>; ▲ , 21 cm<sup>-1</sup>.



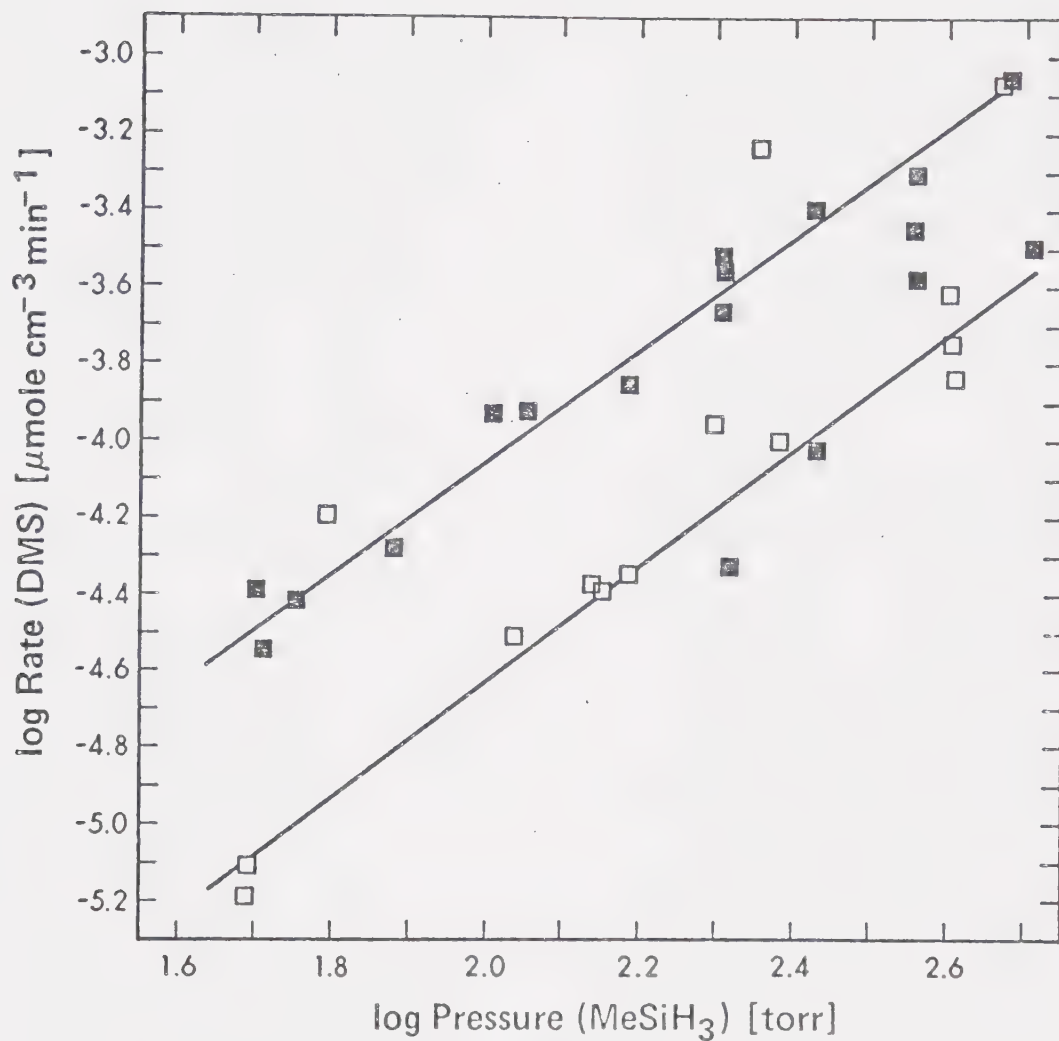


Figure III-7. Rate of DMS Formation as Function of MeSiH<sub>3</sub> Pressure at 415°C in Reaction Vessels of Different S/V Ratios;  
 □ , 1.0 cm<sup>-1</sup>; ■ , 21 cm<sup>-1</sup>.



to be generally faster than those in the unpacked vessel; the minor product, DMS, was affected the most by a change in the S/V ratio.

The results, however, are not very conclusive in view of the large scatter of the data: Figures III-5 to III-7 show that some results in the packed vessel were low and essentially not different from those in the unpacked vessel, while on the other hand, some experiments in the unpacked vessel were unusually fast.

Even though the observed scatter was partly due to experimental errors, it was nevertheless possible to establish a certain correlation between the large deviation from the "expected" rates and the mode of treatment of the reaction vessel before the experiment: when the polymer was freshly deposited on the surface of the vessel, the reaction rates tended to decrease and the effect of S/V ratio on the reaction rate became less apparent; prolonged heating and evacuation of the reaction vessels, on the other hand, caused an increase in the reaction rates. The effect of the nature of the surface on the reaction rates is examined in the next section in more detail.

#### (ii) Effect of the Nature of the Surface

The insensitivity of a reaction rate on the surface/volume ratio does not necessarily imply a



complete absence of surface reactions, since a heterogeneous reaction could escape detection if a radical-chain mechanism which is both surface-initiated and surface-terminated were involved<sup>97</sup>. A change in the nature of the surface, however, could indicate the presence of such radical-chain processes since as a rule the nature of the walls affects the rates of wall-initiation and wall-termination of the chain differently<sup>98</sup>.

A very limited choice of reaction vessel surfaces was available for this investigation, mainly because polymer deposition on the surface of the vessel occurred with every run, and after several experiments, regardless of the initial treatment, the surfaces eventually became identical.

The effects of changing the nature of the surface were studied in two ways: (a) starting with a new cell, the effect of gradually increasing polymer deposition on the reaction rate was investigated and (b) the thermal stability of the polymer was examined since it was not known to what extent polymer decomposition affected the nature of the surface.

(a) The investigation of the effect of increased polymer deposit was carried out in a packed quartz vessel (volume 153.5 cc,  $S/V = 21 \text{ cm}^{-1}$ ), which was first washed and treated as described in Section II-B, and then a





silicon mirror was deposited by repeatedly pyrolyzing monosilane to completion (hydrogen and a silicon mirror were the only products observed when  $\sim 100$  torr  $\text{SiH}_4$  was pyrolyzed at  $490^\circ\text{C}$  for about 48 hrs). The vessel was then thoroughly evacuated to  $10^{-6}$  torr and no degassing could be observed. The silicon mirror surface was chosen since it was assumed to be inert, both in the pyrolysis of monosilane<sup>38</sup> and disilane<sup>57</sup>.

In order to determine how the thermal decomposition of MMS was affected by increasing polymer deposition in the cell, a repetitive series of experiments was carried out under identical reaction conditions in the silicon-coated reaction vessel.

The results, listed in Table III-13, are illustrated in Figure III-8, where the product yields are plotted vs the serial number of the run (i.e. the aggregate reaction time in the vessel) to show how the rates of formation of all the products are suppressed as the extent of polymer deposition increases. For comparison, product yields obtained in a "seasoned" packed vessel under the same conditions, are included.

From Table III-13 and Figure III-8 it can be seen that the yields of hydrogen, DMS and monosilane were affected the most by polymer deposition, and that of DMDS, the least.



TABLE III-13

Effect of Polymer Deposition on the Product Yields in  
Successive Pyrolyses of  $\text{MeSiH}_3$  at  $415^\circ\text{C}$  <sup>a</sup>

Experiment Number	$\text{P}(\text{MeSiH}_3)$ , torr	Yields, $\mu$ moles			
		$\text{H}_2$	DMDS	DMS	$\text{SiH}_4$
1	68.3	9.90	3.69	3.30	1.66
2	67.4	5.82	3.70	2.06	0.85
4 <sup>b</sup>	73.3	3.94	2.80	0.81	c
5	66.4	c	2.62	0.50	c
6	65.6	2.61	2.31	0.36	0.20
7	69.0	2.82	2.47	0.43	0.15
d	68.0	1.86	1.76	0.08	<.02

<sup>a</sup> Time, 10.00 min; cell volume 153.5 cc;  $\text{S/V} = 21 \text{ cm}^{-1}$ ; silicon-mirror surface.

<sup>b</sup> The reaction mixture from experiment number 3 was accidentally lost.

<sup>c</sup> Not determined.

<sup>d</sup> "Seasoned" vessel.



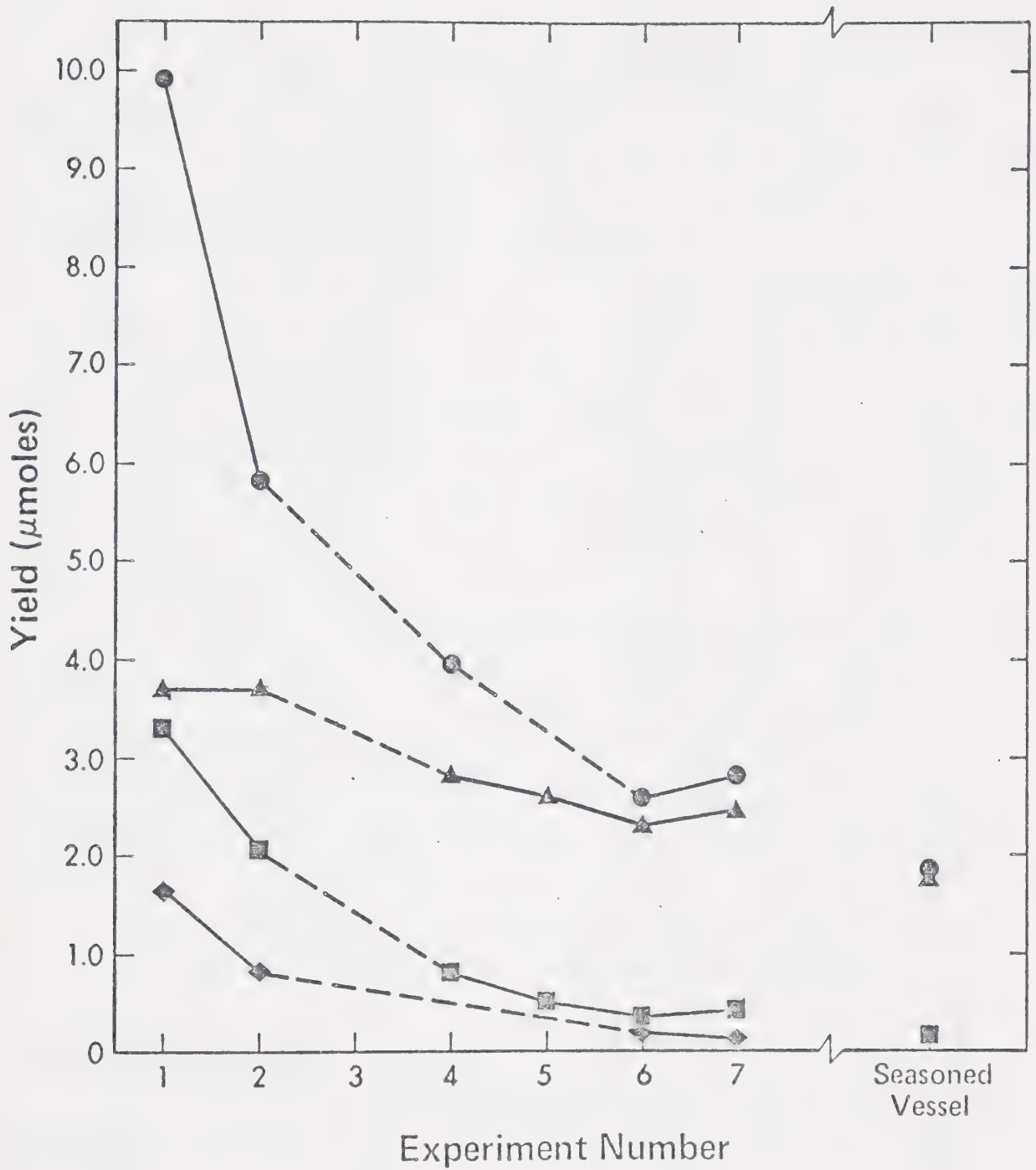


Figure III-8. Effect of Increased Polymer Deposition on the Product Yields in Successive Pyrolyses of  $\text{MeSiH}_3$  at  $415^\circ\text{C}$ .

●,  $\text{H}_2$ ; ▲, DMDS; ■, DMS; ◆,  $\text{SiH}_4$ ;  
 —, consecutive experiments;  
 ---, non-consecutive experiments.



It appears that some heterogeneous processes, and probably radical-chain reactions, are involved in the pyrolysis of MMS and that the polymer is able to deactivate the surface to a high extent.

(b) With regard to the thermal stability of the polymer, it should be recalled at this point that it decomposed slowly when heated in vacuum, liberating light gases. This may indicate that the character of the polymer and consequently that of the surface may have been changed by prolonged heating.

Indeed, it was observed that the rate of MMS pyrolysis obtained in a "seasoned" vessel which had been continuously heated at the reaction temperature and evacuated for a period of several days (or even at shorter periods if the temperature was raised) was always faster than that in subsequent runs.

Typical results are illustrated in Table III-14.

#### 4. Effect of Added Ethylene

In order to determine the molecular or free radical nature of the primary steps in the reaction, the pyrolysis of monomethylsilane was carried out in the presence of ethylene.

Ethylene is a molecule well known for its behaviour as a radical scavenger, and is thermally stable





TABLE III-14

Effect of Polymer Treatment in a "Seasoned" Vessel<sup>a</sup> on the  
Rate of Pyrolysis of Monomethylsilane at 415°C

P(MMS), torr	Time, min	Yield, $\mu$ mole			Rate, $\mu$ mole/min			Vessel Treatment
		H <sub>2</sub>	DMDS	DMS	H <sub>2</sub>	DMDS	DMS	
400.9	2.00	11.10	6.09	0.40	5.55	3.05	0.20	b
409.8	2.51	8.00	6.14	0.37	3.19	2.45	0.15	c
405.0	2.50	7.29	6.08	0.31	2.92	2.43	0.12	c
400.7	2.00	3.63	3.13	0.10	1.82	1.60	0.050	d
407.8	2.00	3.03	2.76	0.057	1.52	1.38	0.029	d
404.8	2.00	3.46	2.76	0.074	1.73	1.38	0.037	d

<sup>a</sup> Cell volume 206.6 cc; S/V =  $1.0 \text{ cm}^{-1}$ ; cell seasoned as described in Section III-A-3i.

<sup>b</sup> Heated at 415°C and evacuated for 1 month.

<sup>c</sup> Heated at 500°C and evacuated for 24 hrs.

<sup>d</sup> Freshly coated by polymer before experiment: ~ 55 torr MMS pyrolyzed at 415°C for 30 min, the mixture discarded, and the vessel evacuated for 30 min at 415°C.



at the temperatures used for the pyrolysis of MMS. Thus no hydrogen was detected when 466.5 torr of ethylene was heated at 415°C for 10 min, and only a negligible trace of methane ( $\sim 0.03 \mu$  mole) was formed. Small quantities of propylene and butene were detected but these did not interfere analytically with the products from the pyrolysis of MMS.

Before each run, the reaction vessel was heated at 500°C and evacuated for  $\sim 16$  hrs; the effect of added ethylene on the rate of pyrolysis of MMS was investigated at 415 and 360°C, at constant MMS pressures of about 405 and 278 torr, respectively. The variation of the rates of formation of hydrogen and DMDS with pressure of added ethylene is shown in Table III-15, and the data at 415°C are illustrated in Figure III-9.

The results show that addition of ethylene to the system has a profound effect on the product yields: the rates of formation of  $H_2$  and DMDS decrease very rapidly initially and then level off to constant values (above ca 5% added ethylene); DMS is completely suppressed. Some additional reaction products were formed, the most prominent of which was identified as methylethylsilane by its mass spectrum given in Appendix I.



TABLE III-15

Effect of Added Ethylene on the Product Yields  
in the Pyrolysis of  $\text{MeSiH}_3$  <sup>a</sup>

Pressure, torr		$\text{C}_2\text{H}_4$ molar %	Yields, $\mu$ mole		
MMS	$\text{C}_2\text{H}_4$		$\text{H}_2$	DMDS	DMS
<u>415°C<sup>b</sup></u>					
409.8	-	-	8.00	6.14	0.37
405.0	-	-	7.29	6.08	0.31
407.4	2.12	0.52	4.31	4.16	c
412.5	3.89	0.93	3.57	2.33	c
409.0	4.09	0.99	4.58	d	d
410.0	7.96	1.90	3.82	2.05	c
410.4	21.40	4.96	2.85	1.93	c
404.6	40.36	9.07	2.53	1.84	c
399.0	100.3	20.1	2.38	1.89	c
407.0	102.1	20.0	2.45	1.91	c
400.9	54.1	16.3	2.63 <sup>(e)</sup>	1.96 <sup>(e)</sup>	c
<u>360°C<sup>f</sup></u>					
274.6	68.9	20.0	1.36	1.01	c
278.2	46.2	14.2	1.34	1.09	c
280.7	30.9	9.9	1.36	1.08	c

<sup>a</sup> Cell volume 206.6 cc, ( $\text{S/V} = 1.0 \text{ cm}^{-1}$ ) was evacuated at 500°C for ~ 16 hrs before each run, except e.

<sup>b</sup> Time, 2.50 min.

<sup>c</sup> No DMS formed.

<sup>d</sup> Not measured.

<sup>e</sup> Cell freshly coated by polymer before experiment.

<sup>f</sup> Time, 100.0 min.



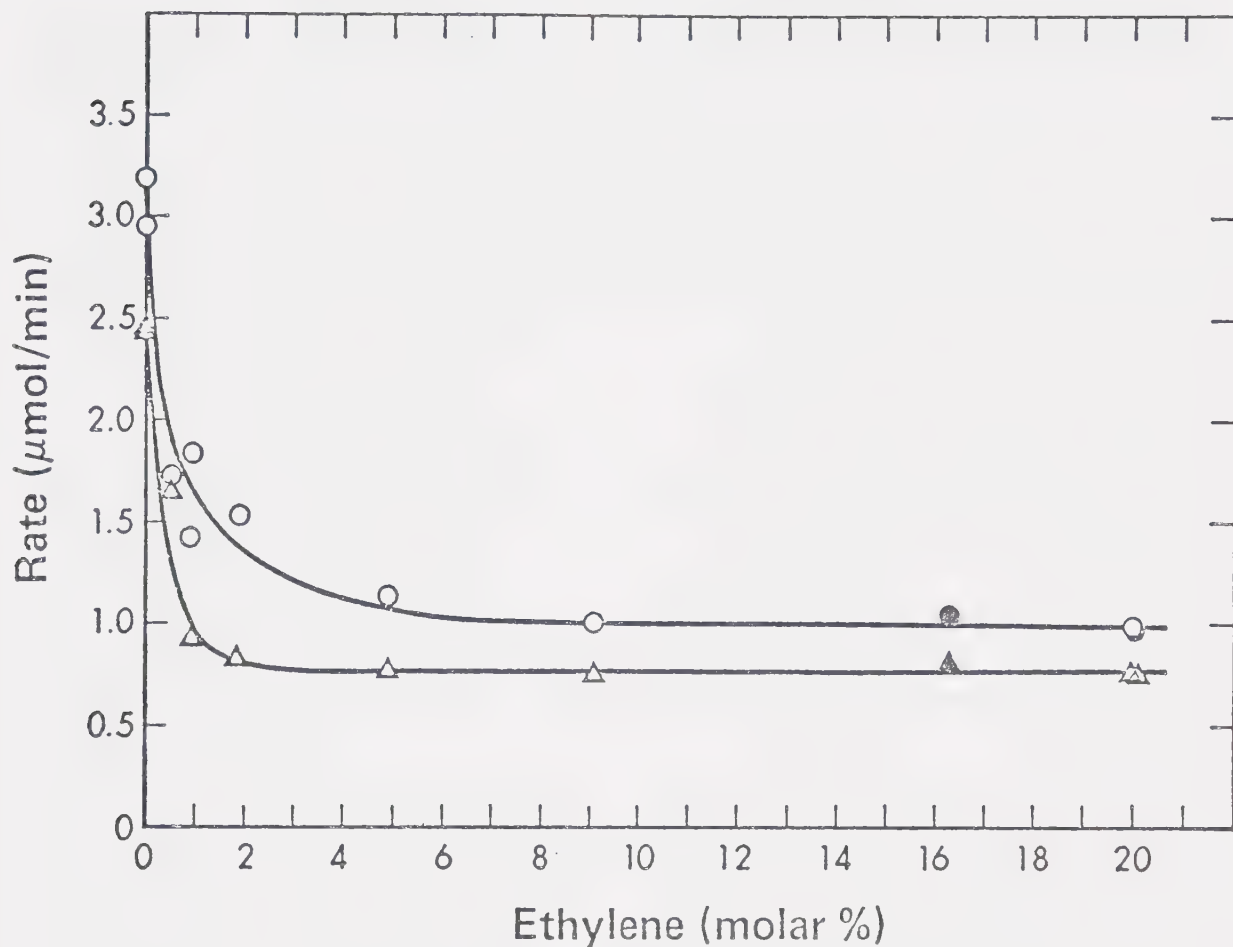


Figure III-9. Effect of Added Ethylene on the Rates of Product Formation in the Pyrolysis of  $\sim 405$  torr  $\text{MeSiH}_3$  at  $415^\circ\text{C}$ .

○  $\text{-H}_2$ , Δ  $\text{-DMDS}$  from a reactor heated and evacuated at  $500^\circ\text{C}$  for  $\sim 16$  hours;  
 ●  $\text{-H}_2$ , ▲  $\text{-DMDS}$  from a reactor freshly coated by polymer.





Figure III-9 also shows that the rates of formation of  $H_2$  and DMDS in the level-off region were not dependent on the nature of the surface of the reaction vessel. It is seen that in the presence of a high concentration of  $C_2H_4$ , the rates in a vessel freshly coated with polymer were the same as those obtained in the vessel evacuated for  $\sim 16$  hrs at  $500^\circ C$ .

It was concluded that the limiting hydrogen and DMDS yields formed at higher pressures of ethylene were of molecular origin, and that about 10% ethylene in the mixture was sufficient to eliminate contributions from radical reactions within the temperature range examined in this study.

Since the molecular reaction rates were not affected by the nature of the surface of the reaction vessel, it can be further concluded that the molecular process is not heterogeneous.

##### 5. Arrhenius Parameters for the Molecular Process

The pyrolysis of MMS was carried out in the presence of about 10% ethylene in the range  $340$  to  $440^\circ C$  and  $40$  to  $400$  torr MMS. Conversions were kept below 1% and the vessel was evacuated overnight before each experiment.

The results are presented in Table III-16.



TABLE III-16

The Monomethylsilane-Ethylene System: The Yields of  $H_2$  and DMDS as Function of  $MeSiH_3$  Pressure and Time at Different Temperatures, and the Calculated First Order Rate Constants for  $H_2$  and DMDS Formation <sup>a</sup>

Temperature, °C	$P(CH_3SiH_3)$ , torr	Time, min	$\frac{C_2H_4}{MeSiH_3}$	$H_2$ , moles	DMDS, moles	$k_{H_2}^1$ , $\frac{1}{s}$	$k_{DMDS}^1$ , $\frac{1}{s}$
440	278.3	2.50	0.111	8.17	6.24 <sup>a</sup>	$4.22 \times 10^{-5}$	$3.22 \times 10^{-5}$
441	133.4	2.50	0.107	3.95	3.03	$4.26 \times 10^{-5}$	$3.26 \times 10^{-5}$
440	43.0	2.50	0.107	1.22	0.96 <sup>e</sup>	$4.08 \times 10^{-5}$	$3.21 \times 10^{-5}$
421	282.3	3.00	0.107	2.87	2.25	$1.18 \times 10^{-5}$	$9.28 \times 10^{-6}$
420	62.7	6.50	0.107	1.33	1.10	$1.14 \times 10^{-5}$	$9.42 \times 10^{-6}$
415	404.6	2.50	0.100	2.53	1.84	$8.66 \times 10^{-6}$	$6.40 \times 10^{-6}$
415	277.9	2.50	0.195	1.75	1.31	$8.73 \times 10^{-6}$	$6.53 \times 10^{-6}$
415	194.9	2.50	0.195	1.21	0.91	$8.62 \times 10^{-6}$	$5.77 \times 10^{-6}$
415	58.4	10.00	5.554	1.46	<sup>b</sup>	$8.67 \times 10^{-6}$	-
401	406.3	4.00	0.107	1.50	1.14	$3.13 \times 10^{-6}$	$2.38 \times 10^{-6}$
399	192.7	8.00	0.111	1.30	1.18	$2.85 \times 10^{-6}$	$2.49 \times 10^{-6}$
400	90.9	16.00	0.107	1.23	1.07	$2.87 \times 10^{-6}$	$2.49 \times 10^{-6}$
380	189.3	30.00	0.107	1.17	1.00	$6.77 \times 10^{-7}$	$5.79 \times 10^{-7}$
380	57.3	125.00	0.111	1.57	1.21 <sup>c</sup>	$7.21 \times 10^{-7}$	$5.56 \times 10^{-7}$



TABLE III-16 (cont'd)

The Monomethylsilane-Ethylene System: The Yields of  $H_2$  and DMDS as Function of  $MeSiH_3$  Pressure and Time at Different Temperatures, and the Calculated First Order Rate Constants for  $H_2$  and DMDS Formation <sup>a</sup>

Temperature °C	$P(CH_3SiH_3)$ , torr	Time, min	$\frac{C_2H_4}{MeSiH_3}$	$H_2$ , moles	DMDS, moles	$k_{H_2}^1$ , $s^{-1}$	$k_{DMDS}^1$ , $s^{-1}$
360	278.2	100.0	0.166	1.34	1.09	$1.54 \times 10^{-7}$	$1.25 \times 10^{-7}$
360	280.7	100.0	0.110	1.36	1.08	$1.54 \times 10^{-7}$	$1.23 \times 10^{-7}$
360	84.6	340.0	0.111	1.35	1.05	$1.49 \times 10^{-7}$	$1.16 \times 10^{-7}$
361	38.1	792.0	0.111	1.48	1.13 <sup>c</sup>	$1.57 \times 10^{-7}$	$1.19 \times 10^{-7}$
340	398.4	370.0	0.111	1.55	1.00	$3.25 \times 10^{-8}$	$2.09 \times 10^{-8}$
340	127.6	910.0	0.111	0.92	0.85	$2.44 \times 10^{-8}$	$2.26 \times 10^{-8}$

<sup>a</sup> Cell volume 206.6 cc

<sup>b</sup> Not analyzed.

<sup>c</sup> Traces of DMS present.



(i) Order of Formation of Hydrogen and DMDS

From the data in Table III-16, the logarithms of the rates of  $H_2$  and DMDS formation were plotted against the logarithms of initial MMS pressure, and the corresponding order plots at different temperatures are shown in Figure III-10.

The reaction orders, derived from the slopes of the order plots by least mean squares analyses, are listed in Table III-17. The formation of both products was found to be first order with respect to monomethylsilane at all temperatures; the sole exception was hydrogen at  $340^\circ\text{C}$ , and the observed deviation from unity was probably an experimental error since the value is based on two points only.

(ii) Rate Constants and Arrhenius Parameters for Hydrogen and DMDS Formation

In the presence of 10% ethylene, the formation of  $H_2$  and DMDS was first order with respect to MMS, thus

$$\text{Rate}(H_2) = \frac{\Delta[H_2]}{\Delta t} = k'_{H_2} [MMS] , \quad \text{and}$$

$$\text{Rate}(\text{DMDS}) = \frac{\Delta[\text{DMDS}]}{\Delta t} = k'_{\text{DMDS}} [MMS] ,$$

where  $\Delta[H_2]$ ,  $\Delta[\text{DMDS}]$  are the product yields in concentration units,  $\Delta t$  is the reaction time,  $k'_{H_2}$  and  $k'_{\text{DMDS}}$  are the individual first-order rate constants at a certain





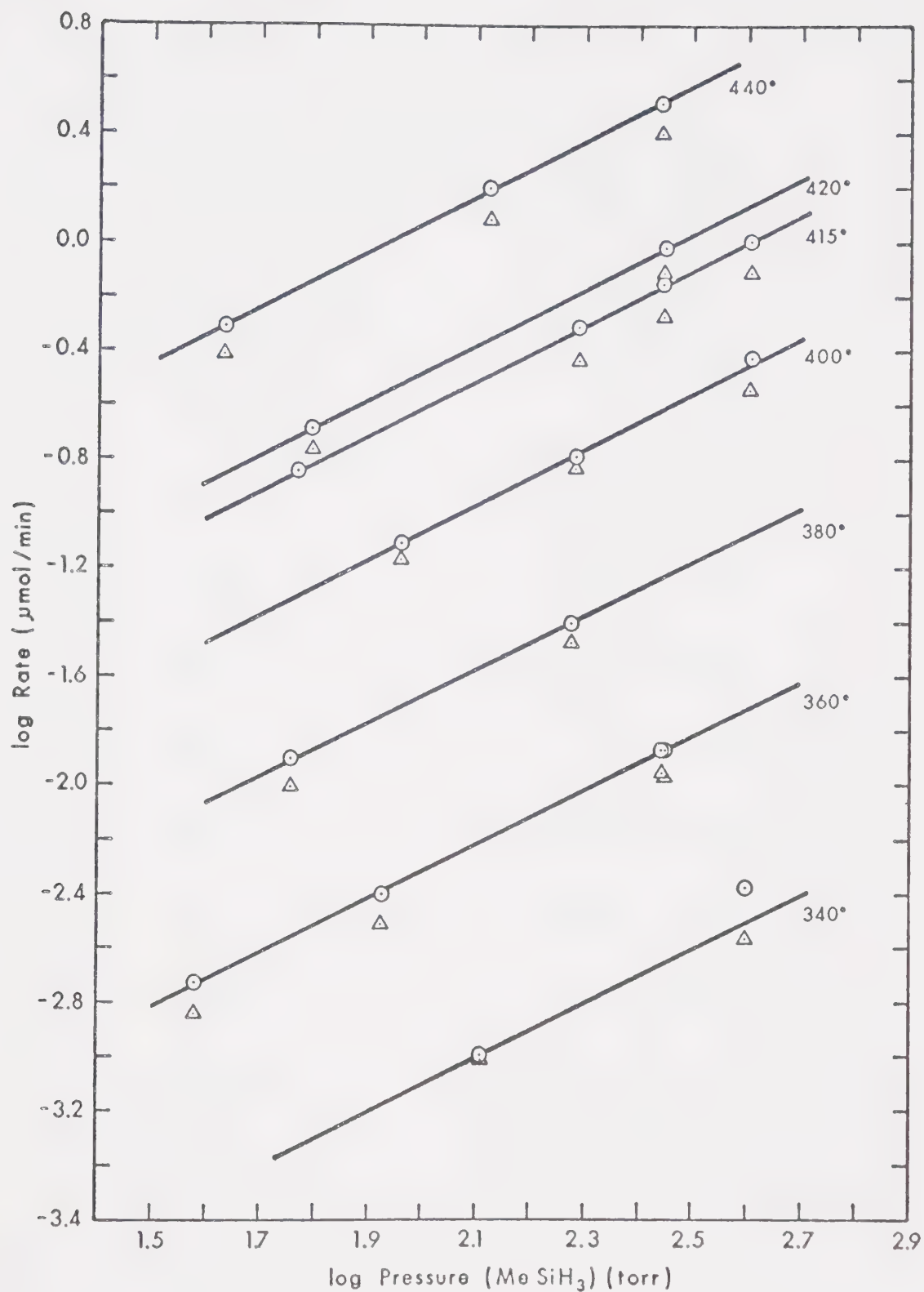


Figure III-10. Order Plots for  $\text{H}_2$  and DMDS at Different Temperatures in the Presence of  $\sim 10\%$  Ethylene;  $\odot$  -  $\text{H}_2$ ,  $\triangle$  - DMDS.



TABLE III-17

Monomethylsilane-Ethylene System: Orders  
of Formation of Hydrogen and DMDS

Temperature	Order	
	H <sub>2</sub>	DMDS
440	1.02	1.004
420	1.03	0.96
415	1.00	1.03
400	1.01	0.97
380	0.95	1.03
360	0.99	1.02
340	1.25	0.92



reaction temperature (with the prime indicating the presence of ethylene), and  $[MMS]$  is the substrate concentration.

Since the conversions were well below 1%, it is reasonable to assume that the concentration of the substrate was unchanged, i.e.

$$[MMS] \approx [MMS]_{\text{initial}} \quad .$$

The calculated rate constants  $k'_{H_2}$ ,  $k'_{DMDS}$  are listed in Table III-16.

The activation energies and pre-exponential factors associated with  $H_2$  and DMDS formation were calculated from the slopes and intercepts of the Arrhenius plots, using the logarithmic form of the Arrhenius equation,

$$\log k = \log A - \frac{E_a}{2.3 RT}$$

where  $k$  is the rate constant,  $A$  is the pre-exponential factor,  $E_a$ , the activation energy,  $T$ , absolute temperature, and  $R$  the gas constant (1.987 cal/deg mole).

The Arrhenius plots for  $H_2$  and DMDS formation in the presence of ethylene are shown in Figure III-11 and the corresponding Arrhenius parameters obtained by least mean squares analyses are presented in Table III-18.



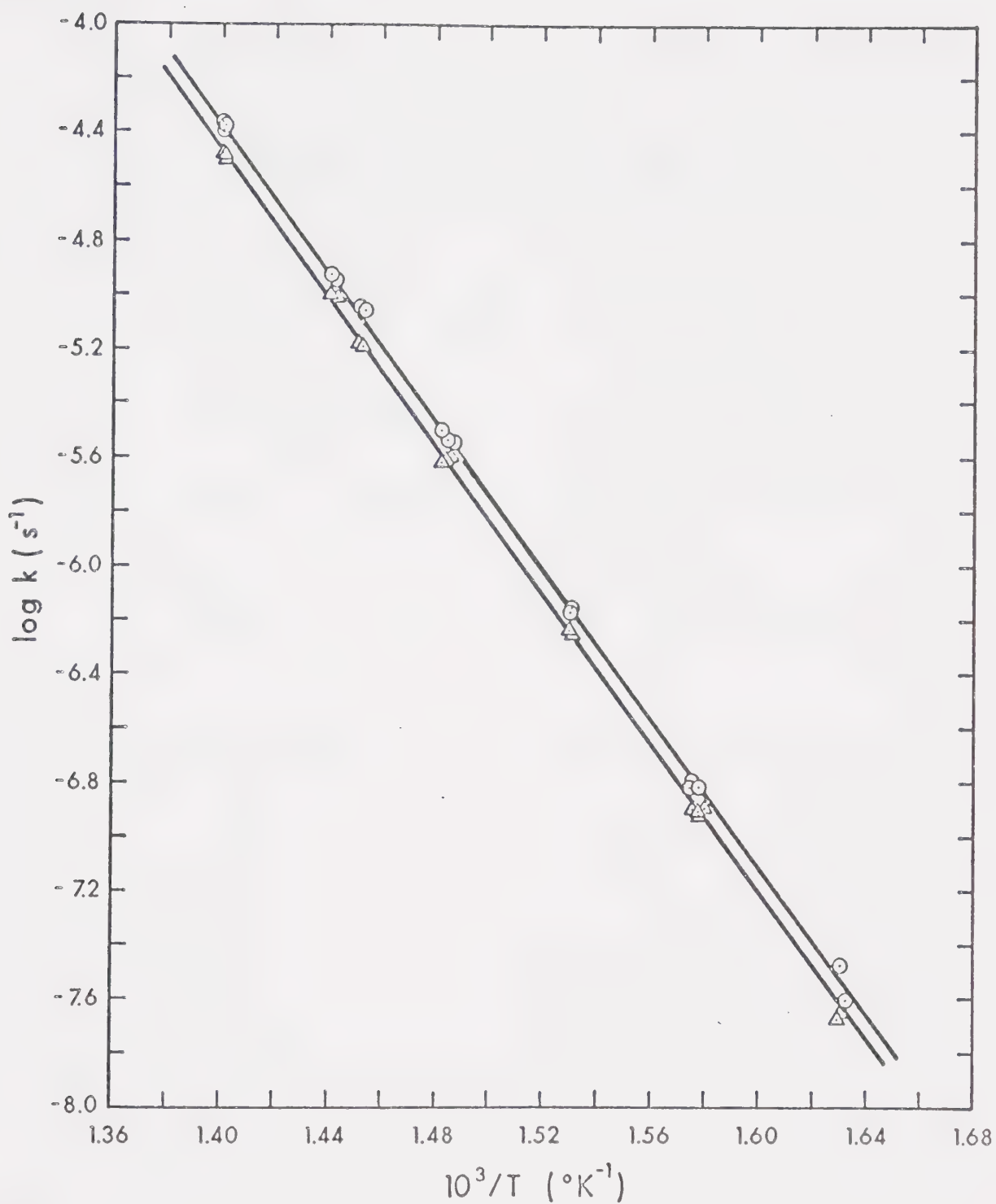


Figure III-11. Arrhenius Plots for  $H_2$  and DMDS Formation from the Pyrolysis of  $MeSiH_3$  in the Presence of  $\sim 10\%$  Ethylene;  $\odot$  -  $H_2$ ,  $\triangle$  - DMDS.





TABLE III-18

Arrhenius Parameters for  $H_2$  and DMDS  
Formation in the Monomethylsilane-Ethylene System

Product	$\log A$ ( $s^{-1}$ )	$E_a$ , kcal/mole
$H_2$	$15.02 \pm 0.10$	$63.27 \pm 0.31$
DMDS	$14.87 \pm 0.12$	$63.15 \pm 0.35$



## 6. Isotopic Labelling Experiments

In order to establish whether the Si-H or C-H bonds were involved in the production of hydrogen, isotopically labeled monomethylsilane- $d_3$  ( $CH_3SiD_3$ ) was pyrolyzed both in the presence and absence of 10% ethylene, and the isotopic composition of hydrogen was analyzed. The results are presented in Table III-19.

It was found that about 97% of the hydrogen fraction was  $D_2$ . Since the isotopic purity of monomethylsilane- $d_3$  used was reported<sup>31,46,61</sup> to be about  $97.0 \pm 0.5\%$ , the results indicated that hydrogen was formed solely by splitting of Si-H bonds.

## B. Discussion

In the initial stages of the pyrolysis of monomethylsilane (MMS), hydrogen and 1,2-dimethyldisilane (DMDS) were formed as major products and dimethylsilane (DMS) as a minor product. When a free radical scavenger, ethylene, was added to the reaction system, the formation of  $H_2$  and DMDS was partially suppressed and that of DMS was totally suppressed.

The results suggest that at least two different processes leading to  $H_2$  and DMDS formation must participate in the pyrolysis of MMS. One, a radical process, is suppressed by the addition of ethylene, and the other, a



TABLE III-19  
Isotopic Distribution of Hydrogen from the  
Pyrolysis of Monomethylsilane-d<sub>3</sub>

Temperature, °C	P(CH <sub>3</sub> SiD <sub>3</sub> ), <sup>a</sup> torr	Time, min	H <sub>2</sub> , μ moles	H <sub>2</sub>	
				HD	D <sub>2</sub>
				molar %	
401 <sup>b</sup>	370.1	12.75	2.44	0.58	94.74
403 <sup>b</sup>	284.5	20.00	2.52	0.45	95.04
415 <sup>b</sup>	193.1	18.00	4.70	0.43	95.17
401 <sup>c</sup>	364.2	12.00	4.94	0.7	97.2
401 <sup>c</sup>	251.7	12.00	3.27	1.82	96.23

<sup>a</sup> Cell volume 206.6 cc.

<sup>b</sup> 9.90% Ethylene in the mixture.

<sup>c</sup> Without ethylene.



molecular process, leads to the formation of nonscavengable  $H_2$  and DMDS.

In spite of the apparent simplicity of the overall reaction, the kinetics of the pyrolysis were found to be complex. The main complications arose from the occurrence of heterogeneous reactions, as indicated by the dependence of the reaction rates on the mode of treatment of the reaction vessel. Although a great deal of effort was expended in order to eliminate surface reactions, only partial success was achieved and therefore this aspect of the pyrolysis will only be briefly discussed. In the presence of ethylene however, the rates were not surface dependent, and the resulting kinetic data on the molecular process can be treated quantitatively.

#### 1. The Primary Reaction Steps

The hydrogen fraction from the pyrolysis of monomethylsilane- $d_3$  ( $CH_3SiD_3$ ) consisted almost entirely of  $D_2$ , Table III-19. Thus C-H bond cleavage is not important and can be neglected as a primary reaction step.

Cleavage of the Si-C bond can also be eliminated as a primary step in the pyrolysis of MMS, since no significant yields of methane were observed. The rate of H-abstraction by  $CH_3$  radicals from Si-H bonds is





known to be extremely rapid<sup>61</sup>. (The formation of small amounts of methane, which were occasionally detected, can be explained by slow thermal decomposition of the polymer.)

The present experimental data do not agree with the results of Davidson et al.<sup>56</sup>, who claimed analytical and kinetic evidence for the occurrence of Si-C cleavage,



The results of this study conclusively show that in the primary steps of the pyrolysis of MMS, only the silicon-hydrogen bonds are broken. MMS may decompose either by elimination of molecular  $\text{H}_2$  yielding methylsilylene, reaction (1), or by dissociation of a single silicon-hydrogen bond forming an H atom and a methylsilyl radical, reaction (2).



The results indicate that both primary steps (1) and (2) occur and that these steps can be distinguished by adding ethylene to the system.

A possible reaction mechanism for the pyrolysis of MMS will now be proposed in order to elucidate the effect of added ethylene.



## 2. Possible Reaction Mechanism

From the experimental results and the literature data available on the reactivity of silyl radicals and silylenes, the reaction scheme shown in Table III-20 is proposed for the pyrolysis of MMS.

The proposed mechanism is consistent with the formation of the major reaction products,  $H_2$  and DMDS, under the various conditions employed. It does not, however, provide a satisfactory explanation for the formation of the minor product, DMS, since the species X in reaction (9) is unspecified; reaction (9) will be discussed later in more detail (See Section III.B.4.iv.).

Reactions (1), (3) and (4) correspond to the molecular process and are assumed to be unaffected by the addition of ethylene.

It is suggested that the radical process is represented by reactions (2), (5)-(9) in the absence of ethylene, and by reactions (2), (10)-(12) in the presence of high concentrations of ethylene.

In neat MMS pyrolysis, a free radical chain is operative and contributes to the yields of  $H_2$  and DMDS formed by the molecular process. According to the scheme, this radical chain is initiated in primary step (2), propagated by reactions (5) and (6), and terminated by methylsilyl radicals either by self-combination,



TABLE III-20  
Reaction Scheme for the Pyrolysis of MeSiH<sub>3</sub>

Reaction Step	log A <sup>a</sup>	E <sub>a</sub> , kcal/mol
Molecular process:		
MeSiH <sub>3</sub> → MeSiH: + H <sub>2</sub>	(1)	63.20+0.33 <sup>b</sup> ~ 1;50 <sup>c</sup>
MeSiH: + MeSiH <sub>3</sub> ⇌ (MeSiH <sub>2</sub> ) <sub>2</sub>	(3;-3)	
MeSiH: → polymer	(4)	
Radical process:		
Initiation		
MeSiH <sub>3</sub> $\xrightarrow{\text{wall}}$ MeSiH <sub>2</sub> <sup>•</sup> + H	(2)	28-57 <sup>b</sup>
(a) No Ethylene:		
Propagation		
H <sup>•</sup> + MeSiH <sub>3</sub> → H <sub>2</sub> + MeSiH <sub>2</sub> <sup>•</sup>	(5)	~3 <sup>c</sup>
MeSiH <sub>2</sub> <sup>•</sup> + MeSiH <sub>3</sub> → (MeSiH <sub>2</sub> ) <sub>2</sub> <sup>•</sup> + H <sup>•</sup>	(6)	~10 <sup>c</sup> ≤10 <sup>c</sup>
Termination		
2 MeSiH <sub>2</sub> <sup>•</sup> → (MeSiH <sub>2</sub> ) <sub>2</sub>	(7)	~10 <sup>c</sup>
MeSiH <sub>2</sub> <sup>•</sup> $\xrightarrow{\text{wall}}$ products	(8)	
MeSiH <sub>2</sub> <sup>•</sup> + X → Me <sub>2</sub> SiH <sub>2</sub>	(9)	~1 <sup>c</sup>



TABLE III-20 (cont'd)  
Reaction Scheme for the Pyrolysis of MeSiH<sub>3</sub>

Reaction Step	log A <sup>a</sup>	E <sub>a</sub> , kcal/mol
(b) Ethylene added:		
$\text{H}^\bullet + \text{C}_2\text{H}_4 \rightarrow \text{C}_2\text{H}_5^\bullet$	(10)	
$\text{MeSiH}_2^\bullet + \text{C}_2\text{H}_4 \rightarrow \text{MeSiH}_2\text{CH}_2\text{CH}_2^\bullet$	(11)	
$\text{C}_2\text{H}_5^\bullet$ and $\text{MeSiH}_2\text{CH}_2\text{CH}_2^\bullet \rightarrow$ stable products	(12)	
	10.0 <sup>c</sup>	1.8 <sup>c</sup>
	>7.0 <sup>c</sup>	<2.5 <sup>c</sup>

<sup>a</sup> A-factors for unimolecular and bimolecular reactions are in units of s<sup>-1</sup> and M<sup>-1</sup>s<sup>-1</sup>, respectively.

<sup>b</sup> Measured in this work.

<sup>c</sup> Estimated from literature data; see text.





reaction (7), or by diffusion to the walls, reaction (8).

In the presence of ethylene, hydrogen atoms and methylsilyl radicals from the primary step (2) are scavenged in reactions (10) and (11), where ethyl and  $\beta$ -methylethylsilyl radicals, respectively, are formed. Although these radicals may undergo further addition, abstraction, recombination or disproportionation reactions to form stable products, reaction (12), it is assumed that no significant amounts of  $H_2$  or DMDS will be formed in these processes.

Thus, if steps (5)-(9) could be effectively eliminated by high concentrations of ethylene, the radical process will no longer contribute to the yields of  $H_2$  and DMDS, and these products will then be formed solely by the molecular process.

The effect of ethylene on the pyrolysis of MMS will now be discussed in detail.

### 3. Effect of Added Ethylene on the Molecular and Radical Processes

According to the reaction scheme in Table III-20, the yields  $H_2$  and DMDS in the presence of ethylene will correspond to the molecular process, if the following conditions are fulfilled:



- (a) the molecular process, i.e. reactions (1), (3) and (4), is unaffected by the addition of ethylene; and
- (b) reactions (5)-(9) are suppressed by ethylene, and the subsequent reactions of ethyl and  $\beta$ -methylethylsilyl radicals, (12), do not form any additional  $H_2$  or DMDS.

Each of these possibilities will now be discussed.

(i) Molecular Process, Reactions (1), (3) and (4)

(a) Reaction (1)

The primary reaction step (1),



represents a unimolecular decomposition of the thermally activated substrate molecule, the rate constant of which is pressure dependent in the fall-off region (see Section I.B).

The experimentally measured first order rate constants for  $H_2$  and DMDS formation in the presence of ethylene, listed in Table III-16, were determined in a broad pressure range of approximately 40 - 400 torr. They were, within experimental error, independent of total pressure and therefore represent the limiting high pressure values.

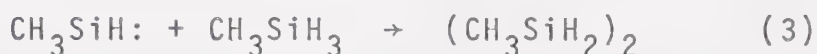


Moreover, an RRKM calculation of the fall-off curve for the rate constant of reaction (1) confirmed that the present investigation was carried out in the high pressure region<sup>99</sup>.

Thus it can be concluded that at pressures above 40 torr, the rate of reaction (1) is unaffected by the addition of ethylene.

(b) Reaction (3)

Reaction (3),



represents insertion of methylsilylene into the Si-H bond of the substrate. In order that spin be conserved in the primary reaction step (1),  $\text{MeSiH:}$  must be produced in the singlet state which is very likely the ground electronic state by analogy with  $:\text{SiH}_2$ <sup>55</sup>.

Although the rate of reaction (3) has not been reported, one can deduce from the following considerations that it must be very fast. The Arrhenius parameters for insertion of  $:\text{SiH}_2$  into  $\text{SiH}_4$ ,



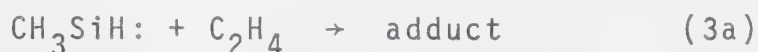
are  $E_a = 1.3 \pm 1.1$  kcal/mol and  $\log A(\text{M}^{-1}\text{s}^{-1}) = 9.7 \pm 0.4$ <sup>66</sup>, and the preexponential factor for insertion of methylsilylene into monosila





was calculated to be  $\log A(\text{M}^{-1}\text{s}^{-1}) = 10.1$ <sup>77</sup>. The latter reaction is also very rapid and its activation energy is likely to be very small. The rate of insertion of MeSiH: into MeSiH<sub>3</sub>, reaction (3), should therefore be fast and feature a similar A-factor and low  $E_a$ <sup>68</sup>.

In the presence of ethylene, addition of methylsilylene across the double bond, reaction (3a),



might be expected to occur in parallel and in competition with reaction (3)<sup>62,86</sup>; however, the limiting yields of DMDS were unaffected by increasing concentrations of C<sub>2</sub>H<sub>4</sub> (see Table III-15), indicating that methylsilylene is not very reactive toward ethylene.

Moreover, from the available information on the reactivity of various silylenes, it can be deduced that the rate of reaction (3a) should be very slow in comparison with reaction (3). For example, Attwell and Weyenberg<sup>59</sup> reported that the relative reactivity of Me<sub>2</sub>Si: towards a series of substrates follows the trend benzene < ethylene << dimethoxytetramethyldisilane < 1,3-dienes,



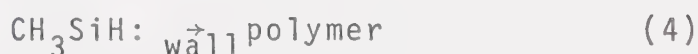


and that ethylene cannot compete with 1,3-butadiene for  $\text{Me}_2\text{Si:}$ . Jenkins, Ring et al.<sup>69</sup> have shown that for  $\text{MeSiH:}$  the rate of addition to 1,3-butadiene is comparable with the rate of insertion into Si-H bonds, and also reported that for the most reactive silylene,  $:\text{SiH}_2$ , the rate of insertion into Si-H bonds is about four times faster than the rate of addition to 1,3-butadiene.

On the basis of these results it can be deduced that addition reaction (3a) cannot compete with insertion reaction (3), and therefore reaction (3) will not be affected by the addition of ca 10% of ethylene to the reaction system.

(c) Reaction (4)

Reaction (4),



is one of several reactions which might lead to the formation of polymer. Polymer was formed mainly in the later stages of the pyrolysis of MMS; in the initial stages, however, (at conversions below 1%) it was only a very minor product.

The rate of reaction (4) will depend on the concentration of  $\text{MeSiH:}$  which can be estimated from the following considerations. DMDS is less thermally stable than the substrate, MMS, and the main mode of decomposition



of DMDS is via elimination of methylsilylene<sup>58</sup>, i.e. reaction (-3),



the Arrhenius parameters of which can be estimated from recently published data<sup>27,77</sup> to be  $\log A_{-3}(\text{s}^{-1}) = 14.0$  and  $E_{-3} = 50.0 \text{ kcal/mol}$ . Together with the previously estimated Arrhenius parameters for reaction (3),  $\log A_3(\text{M}^{-1}\text{s}^{-1}) = 10$ ,  $E_3 = 1 \text{ kcal/mol}$ <sup>66,68</sup>, the equilibrium constant  $K_{-3}$  at  $400^\circ\text{C}$  is:

$$K_{-3} = \frac{k_{-3}}{k_3} = \frac{[\text{MeSiH:}][\text{MMS}]}{[\text{DMDS}]} \approx 1.5 \times 10^{-12} \text{ M}$$

Thus at  $\sim 0.2\%$  conversion the equilibrium concentration of MeSiH: is very small, of the order of  $\sim 3 \times 10^{-15} \text{ M}$ , and since the rate of reaction (4) is expected to be diffusion controlled, small quantities of ethylene should have no effect.

Thus it can be concluded that the rates of the molecular reactions (1), (3) and (4), are unaffected by the addition of ethylene. We shall now turn our attention to the effect of ethylene on radical processes.

## (ii) Radical Reactions

### (a) Scavenging of H atoms

Hydrogen atoms, formed in the primary reaction step (2) or by reaction (6) (see Table III-20), can react



either with the substrate, reaction (5),



and propagate the chain or can be scavenged by added ethylene, reaction (10):



Several values for the room temperature rate constant  $k_5$  have been reported,  $2.1 \pm 0.5 \times 10^8 \text{ M}^{-1}\text{s}^{-1}$  <sup>100</sup>,  $6.9 \pm 1.2 \times 10^8 \text{ M}^{-1}\text{s}^{-1}$  <sup>75</sup>,  $1.8 \pm 0.5 \times 10^8 \text{ M}^{-1}\text{s}^{-1}$  <sup>75</sup> and  $3.1 \times 10^8 \text{ M}^{-1}\text{s}^{-1}$  <sup>101</sup>, where the last two refer to the analogous  $\text{D} + \text{CH}_3\text{SiH}_3$  system. Obi et al. <sup>101</sup> have also estimated the activation energy  $E_5$  to be 2.3 - 3.7 kcal/mol, assuming an A-factor in the range  $5 \times 10^9 - 5 \times 10^{10} \text{ M}^{-1}\text{s}^{-1}$  per Si-H bond.

The addition of H atoms to ethylene, (10), has been thoroughly investigated and the reported high pressure rate constants at room temperature <sup>102,103</sup> are in good agreement, yielding an average value of  $6.9 \pm 1.1 \times 10^8 \text{ M}^{-1}\text{s}^{-1}$ .  $E_{10}$  is 1.5 - 2.0 kcal/mol <sup>103,104</sup> and  $\log A_{10}(\text{M}^{-1}\text{s}^{-1}) = 10.0 \pm 0.1$  <sup>105</sup>.

Thus the room temperature rate constant ratio  $k_{10}/k_5$  is about 2, in good agreement with the experimentally determined value of  $k_{10}/k_5 = 1.72$  <sup>101</sup> where  $k_{10}$  refers to the  $\text{D}^\bullet + \text{C}_2\text{D}_4$  reaction. Since  $E_{10} = 1.75 \text{ kcal/mol}$ ,



$A_{10} = 10^{10.0} \text{ M}^{-1}\text{s}^{-1}$  and  $E_5 \sim 3.0 \text{ kcal/mol}$ , then  
 $A_5 = 10^{10.6} \text{ M}^{-1}\text{s}^{-1}$ , and at  $400^\circ\text{C}$   $k_{10}/k_5 \approx 0.64$ .

Thus, within the temperature range used in this work, the rate constants for reactions (5) and (10) are not very different, and ethylene therefore cannot compete very efficiently with MMS for H atoms.

This relative inefficiency of ethylene in scavenging H atoms is further increased in the present study by the relatively low concentrations of  $\text{C}_2\text{H}_4$  used (see Table III-16). Thus, at  $400^\circ\text{C}$  and for a mixture containing  $\sim 10\%$  ethylene, the relative rates  $R_{10}/R_5$  will be approximately

$$\frac{R_{10}}{R_5} = \frac{k_{10}[\text{C}_2\text{H}_4]}{k_5[\text{MMS}]} = 0.64 \frac{[10\%]}{[90\%]} = 0.07$$

i.e. only  $\sim 7\%$  of H atoms present in the system will be scavenged by ethylene and the remaining 93% will react with the substrate by (5) yielding  $\text{H}_2$ .

This simple calculation however is not compatible with experimental observations. Figure III-9 shows that in the presence of  $\sim 1\%$  ethylene the rate of  $\text{H}_2$  formation has already dropped to about 50% of its original value, and at 6% added  $\text{C}_2\text{H}_4$  it was almost 70% lower; further increases in the ethylene concentration did not have any apparent effect.





Since this high efficiency of ethylene cannot be explained simply in terms of scavenging of H atoms, it must be related to a suppression of the rate of H atom formation in the chain propagation step (6):



If the chain length is large, then the majority of H atoms formed in the system will come from the chain propagation step (6) and the chain propagation reactions (5) and (6) will be the major source of  $\text{H}_2$  formed in the radical process; the other contribution from the chain initiation step (2) will be only minor. In other words, since the chain length,  $\lambda$ , is defined as

$$\lambda = \frac{\text{Rate(Propagation)}}{\text{Rate(Initiation)}}$$

the individual contributions from the initiation and propagation steps  $\text{H}_{2,\text{Rad}}^{\text{Init}}$  and  $\text{H}_{2,\text{Rad}}^{\text{Prop}}$  respectively can be expressed as:

$$\frac{\text{H}_{2,\text{Rad}}^{\text{Init}}}{\text{H}_{2,\text{Rad}}^{\text{Prop}}} = \frac{1}{\lambda}$$

Thus, if  $\lambda$  is very large the relative contribution from the initiation step will be very small. That this is indeed the case is evident from the large decrease in  $\text{H}_2$  yields in the presence of small concentrations of ethylene; direct evidence for the presence of a long chain will be presented later (Section III.B.3.vii).

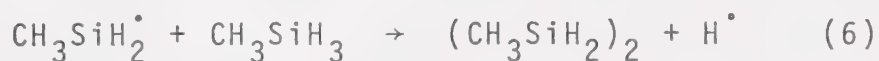


In the next section it will be shown that ethylene is a highly efficient scavenger of methylsilyl radicals, and that even small concentrations of  $C_2H_4$ , e.g. 5 - 10%, can effectively suppress reaction (6) and thus eliminate the contribution  $H_2^{Prop.}_{Rad}$ .

Furthermore, it will be shown (Section III.B.4.v) that the rate of the chain initiation reaction (2) is very small in comparison with that of the molecular reaction (1), and therefore the  $H_2$  yields measured in the presence of ethylene can be assumed to be formed by the molecular process only, i.e. by reaction (1).

#### (b) Scavenging of Methylsilyl Radicals

Methylsilyl radicals formed in the primary reaction step (2) or by reaction (5), can either react with the substrate, reaction (6), or be scavenged by added ethylene, reaction (11):



Neither reaction has been investigated kinetically.

From the most recent data on bond dissociation energies in silicon compounds<sup>13,15,17</sup> however, one may estimate  $D(MeSiH_2-H) \sim 90$  and  $D(MeSiH_2-SiH_2Me) \sim 80$  kcal/mol, and thus reaction (6) will be approximately 10 kcal/mol endothermic.  $E_6$  will probably be higher

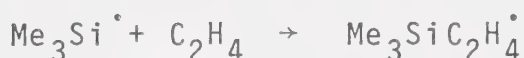


than 10 kcal/mole, since

$$E_6 = \Delta H_6 + E_{-6} \approx 10 + E_{-6}$$

where  $\Delta H_6$  is the enthalpy change of the reaction, and  $E_{-6}$  is the activation energy of the reverse reaction. A value of  $E_6 = 13 - 15$  kcal/mol is quite plausible since in the analogous  $\text{SiH}_3^\bullet + \text{SiH}_4$  system, the activation energies for the forward and reverse reactions have been estimated to be  $\sim 15$ <sup>39</sup> and  $\sim 3$  kcal/mol<sup>32</sup>, respectively. The maximum value of the A factor for the  $\text{SiH}_3^\bullet + \text{SiH}_4$  reaction has been estimated to be  $\sim 10^{10} \text{ M}^{-1} \text{ s}^{-1}$ <sup>39</sup>.

The rate of addition of methylsilyl radicals to ethylene, reaction (11), can also be estimated. Choo and Gaspar<sup>40</sup> found that the rate of addition of trimethylsilyl radicals to ethylene,



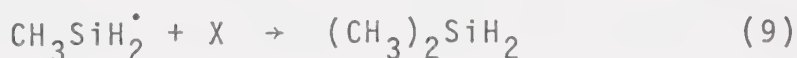
is much faster than that of simple alkyl radical addition to ethylene. They measured the activation energy and A factor,  $2.5 \pm 0.2$  kcal/mole and  $10^{7.0 \pm 0.2} \text{ M}^{-1} \text{ s}^{-1}$ , respectively, and reported that the rate of addition of  $\text{SiH}_3^\bullet$  to ethylene was even more rapid than that of the  $\text{Me}_3\text{Si}^\bullet$  radical. Similarly, Pollock et al.<sup>32</sup> found that the addition of disilyl radicals to ethylene is several orders of magnitude faster than that of corresponding



alkyl radicals. At room temperature the rate constants for addition of disilyl and trimethylsilyl radicals to ethylene are  $4 \times 10^6 \text{ M}^{-1}\text{s}^{-1}$  <sup>32</sup> and  $2 \times 10^5 \text{ M}^{-1}\text{s}^{-1}$  <sup>40</sup>, respectively.

The rate of addition of methylsilyl radicals to ethylene, (11), is probably of the same order of magnitude as that of disilyl radicals and much faster than that of  $\text{Me}_3\text{Si}$  radicals, which may be considered as a lower limit for  $k_{11}$ . Therefore, using the measured Arrhenius parameters for the  $\text{Me}_3\text{Si}^\bullet + \text{C}_2\text{H}_4$  reaction, and the estimated values for reaction (6),  $E_6 \sim 13 \text{ kcal/mol}$ ,  $A_6 \sim 10^{10} \text{ M}^{-1}\text{s}^{-1}$  (vide supra), it follows that  $R_{11}/R_6 \geq 3 \times 10^3$  at  $400^\circ\text{C}$ .

Thus, in the presence of ca 10% ethylene,  $k_{11}/k_6 \geq 3 \times 10^2$ , and therefore the chain cannot be sustained. Since the concentration of methylsilyl radicals will be greatly reduced, the other DMDS-forming reactions in the radical process, i.e. termination reactions (7) and (8), will also be suppressed. The total suppression of DMS, formed via



is direct evidence for efficient scavenging of methylsilyl radicals.





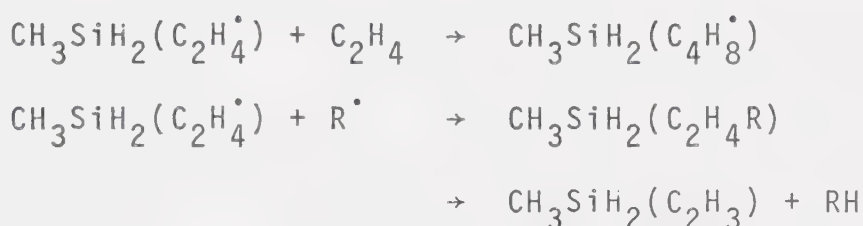
When methylsilyl radicals react with ethylene,



$\beta$ -methylethylsilyl radicals are formed. These undergo further reactions, the most important of which is abstraction of H atoms from the substrate



to form methylethylsilane. Other possible reactions are addition to ethylene, recombination and disproportionation,



These are minor processes, however, and the nature of the products could not be established. It is reasonable, however, to assume that none of these processes will lead to the formation of DMDS.

Thus it can be concluded that in the presence of ethylene, the observed DMDS yields will correspond solely to the contribution from the molecular process.

### (iii) Arrhenius Parameters for $\text{H}_2$ and DMDS Formation in the Presence of Ethylene

It has been shown that the DMDS yields formed in the pyrolysis of MMS in the presence of ethylene



arise exclusively from the molecular process, i.e. reactions (1) and (3); (1) is the rate-determining step. Since some decomposition of DMDS might have occurred even at low conversions,  $k_{\text{DMDS, Molec.}}$  (see Table III-16) should be  $\leq k_1$ .

The Arrhenius parameters for  $\text{H}_2$  formation in the presence of ethylene (Table III-18), are the same, within experimental error, as those for DMDS and would therefore appear that  $k_{\text{H}_2, \text{Molec.}} \approx k_{\text{DMDS, Molec.}} \approx k_1$ .

The errors in the rate constant parameters are commensurate with the errors in the  $\text{H}_2/\text{DMDS}$  ratios, (Table III-16); which were consistently higher than unity ( $\sim 1.27 \pm 0.10$ ) and it would appear that the hydrogen yields in the presence of  $\text{C}_2\text{H}_4$  may contain a very small contribution from the radical primary step (2). Therefore  $k_{\text{H}_2, \text{Molec.}} \geq k_1$ .

The radical contribution to the  $\text{H}_2$  yields in the presence of ethylene are very small however and we conclude that the measured Arrhenius parameters for  $\text{H}_2$  and DMDS formation in the presence of  $\text{C}_2\text{H}_4$  relate solely to the rate constant  $k_1$  of the molecular primary step (1); these results will now be used to elucidate the radical processes occurring in the absence of ethylene.



#### 4. Pyrolysis in the Absence of Ethylene: the Radical Process

In the pyrolysis of neat MMS, the molecular and radical processes both contribute to the formation of  $H_2$  and DMDS. To a good approximation these processes may be considered to be independent of each other, and thus in the absence of ethylene the yields of  $H_2$  and DMDS may be expressed as the sum of the individual contributions from the molecular and radical processes.

The radical yields of  $H_2$  and DMDS may thus be calculated from the total yields given in Tables III-4 to III-7 and Tables III-11 and III-12 by subtracting the molecular yields obtained from the Arrhenius parameters for the molecular process, listed in Table III-18.

The results for hydrogen at different temperatures are listed in Tables III-21 to III-25, and the radical yields of all products at 415°C in the unpacked and packed vessels are given in Tables III-26 and III-27, respectively.

##### (i) The Reaction Orders for the Products of the Radical Process

The reaction order for products formation by the radical process was determined from the slope of conventional  $\log(\text{rate})$  versus  $\log(\text{substrate concentration})$  plots by least-square analysis. The orders for  $H_{2,\text{Rad}}$



TABLE III-21  
Yields of Hydrogen from the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 441°C and 429°C <sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, μ moles		Rate, M s <sup>-1</sup>		
			Total	Molecular Radical	10 <sup>7</sup> H <sub>2</sub> , Total	10 <sup>8</sup> H <sub>2</sub> , Rad	
<u>441°C</u>							
171.5	3.84	60.6	2.47	2.175	0.295	1.98	2.36
118.0	2.65	60	1.57	1.420	0.150	1.27	1.21
80.8	1.81	60.6	1.05	0.994	0.056	0.84	0.45
57.6	1.29	90	1.11	1.059	0.051	0.60	0.27
39.5	0.87	120	1.02	0.969	0.051	0.41	0.21
<u>429°C</u>							
203.5	4.64	90	2.97	1.79	1.18	1.60	6.35
138.2	3.15	90	1.76	1.22	0.54	0.94	2.90
94.0	2.15	120	1.38	1.01	0.37	0.56	1.50
63.7	1.46	180	1.41	1.07	0.34	0.38	0.91
42.8	0.98	240	1.24	0.92	0.32	0.25	0.65

<sup>a</sup> Cell volume 206.6 cc.





TABLE III-22  
Yields of Hydrogen by the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 421°C<sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, $\mu$ moles		Rate, M s <sup>-1</sup>		
			Total	Molecular Radical	10 <sup>8</sup> H <sub>2</sub> , Total	10 <sup>9</sup> H <sub>2</sub> , Rad	
214.3	4.95	150	2.34	1.83	0.51	7.55	16.4
177.0	4.09	150	1.87	1.51	0.36	6.03	11.5
147.1	3.40	150	1.53	1.26	0.27	4.94	8.78
125.7	2.90	192	1.66	1.38	0.28	4.19	7.16
120.2	2.77	180	1.48	1.23	0.25	3.98	6.64
100.3	2.32	183	1.21	1.05	0.16	3.20	4.31
81.4	1.88	270	1.44	1.25	0.19	2.58	3.35
69.2	1.60	270	1.18	1.065	0.115	2.11	2.06
55.7	1.29	360	1.26	1.14	0.11	1.69	1.44
47.1	1.09	390	1.18	1.05	0.13	1.40	1.66
31.6	0.73	540	1.05	0.972	0.078	0.94	0.70

<sup>a</sup> Cell volume 206.6 cc.



TABLE III-23  
Yields of Hydrogen by the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 400°C<sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, μ moles		Rate, M s <sup>-1</sup>		
			Total	Molecular Radical	10 <sup>7</sup> H <sub>2</sub> , Total	10 <sup>8</sup> H <sub>2</sub> , Rad	
212.3	5.06	360	1.84	1.07	0.77	2.48	10.3
209.0	4.98	360	1.50	1.06	0.44	2.02	5.97
202.9	4.83	600	2.75	1.71	1.04	2.22	8.40
148.5	3.54	600	1.85	1.25	0.60	1.49	4.83
144.4	3.44	600	1.73	1.22	0.51	1.40	4.15
135.8	3.23	426	1.19	0.84	0.35	1.36	3.97
138.6	3.30	660	1.81	1.28	0.53	1.33	3.86
93.9	2.24	600	1.09	0.79	0.30	0.88	2.41
91.8	2.18	600	0.99	0.77	0.22	0.80	1.75
73.7	1.75	900	1.22	0.93	0.29	0.66	1.55
62.9	1.50	918	1.03	0.81	0.22	0.54	1.16
61.9	1.47	780	0.84	0.68	0.16	0.52	1.01
48.5	1.16	900	0.80	0.61	0.19	0.43	1.01
42.3	1.01	1200	0.87	0.71	0.16	0.35	0.63
33.7	0.80	1440	0.80	0.68	0.12	0.27	0.40

<sup>a</sup> Cell volume 206.6 cc.



TABLE III-24  
Yields of Hydrogen by the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 380°C<sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, $\mu$ moles		Rate, M s <sup>-1</sup>		
			Total	Molecular Radical	10 <sup>9</sup> H <sub>2</sub> , Total	10 <sup>9</sup> H <sub>2</sub> , Rad	
212.8	5.22	990	1.58	0.74	0.84	7.73	4.12
210.2	5.15	660	1.09	0.49	0.60	7.99	4.41
145.2	3.56	1290	1.15	0.64	0.51	4.32	1.93
141.5	3.47	1560	1.34	0.78	0.56	4.16	1.75
96.5	2.37	1800	0.94	0.61	0.33	2.53	0.88
65.2	1.60	1860	0.60	0.43	0.17	1.57	0.45
42.9	1.05	2820	0.57	0.425	0.145	0.98	0.25

<sup>a</sup> Cell volume 206.6 cc.



TABLE III-25  
Yields of Hydrogen by the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 361°C and 341°C <sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, μ moles		Rate, M s <sup>-1</sup>	
			Total	Molecular Radical	10 <sup>10</sup> H <sub>2</sub> , Total	10 <sup>10</sup> H <sub>2</sub> , Rad
<u>361°C</u>						
92.6	2.35	8880	1.26	0.66	6.87	3.29
62.1	1.57	12600	1.03	0.62	3.95	1.56
40.5	1.02	16800	0.85	0.53	2.45	0.91
<u>341°C</u>						
195.8	5.11	16500	2.32	0.52	6.81	5.29
128.2	3.35	19500	1.34	0.41	3.32	2.32
84.5	2.21	33180	1.19	0.44	1.73	1.09

<sup>a</sup> Cell volume 206.6 cc.





TABLE III-26  
Product Yields by the Molecular and Radical Processes in the Pyrolysis of Monomethylsilane at  
415°C in the Unpacked Vessel <sup>a</sup>

P(MMS), torr	MMS, 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, $\mu$ moles		DMDS Yield, $\mu$ moles		DMS Yield, $\mu$ moles	10 <sup>8</sup> H <sub>2</sub> Tot		10 <sup>8</sup> H <sub>2</sub> Rad		Rate, M s <sup>-1</sup>		10 <sup>9</sup> DMS
			Tot	Mol	Tot	Mol		10 <sup>8</sup> H <sub>2</sub> Tot	10 <sup>8</sup> H <sub>2</sub> Rad	10 <sup>8</sup> DMDS <sub>Tot</sub>	10 <sup>8</sup> DMDS <sub>Rad</sub>			
400.7	9.34	120	3.63	1.735	1.895	1.34	0.10	14.6	7.64	12.9	7.50			4.03
404.8	9.44	120	3.46	1.79	1.67	1.38	0.074	14.0	6.74	11.1	5.56			2.99
407.8	9.50	120	3.03	1.84	1.19	1.42	0.060	12.2	4.81	11.1	5.41			2.42
241.5	5.62	150	1.98	1.40	0.58	1.08	0.052	6.39	1.88	5.97	2.49			1.68
198.5	4.62	120	1.58	0.92	0.66	1.33	0.046	6.37	2.67	5.38	2.52			1.86
154.8	3.61	150	1.31	0.83	0.48	0.64	0.023	4.23	1.56	3.07	0.36			0.74
139.5	3.23	150	1.15	0.80	0.35	0.62	0.022	3.78	1.13	2.52	0.52			0.71
144.2	3.36	720	4.93	3.75	1.18	2.89	0.090	3.32	0.79	2.84	0.90			0.61
109.1	2.54	150	0.80	0.59	0.21	0.46	0.010	2.58	0.68	2.13	0.66			0.32
49.3	1.15	150	0.32	0.267	0.053	0.21	0.004	1.03	0.17	1.36	0.69			0.13
49.9	1.14	180	-	-	-	0.245	0.004	-	-	1.02	0.36			0.11
45.4	1.06	180	0.36	0.29	0.07	0.23	0.004	0.97	0.19	0.83	0.22			0.11

<sup>a</sup> Cell volume 206.6cc; S/V = 1.0 cm<sup>-1</sup>.



TABLE III-27  
Yields of Products by the Molecular and Radical Processes in the  
Pyrolysis of Monomethylsilane at 415°C in the Packed Vessel <sup>a</sup>

P(MMS), torr	MMS 10 <sup>3</sup> M	Time, s	H <sub>2</sub> Yield, $\mu$ moles		DMS Yield, $\mu$ moles		DMS Yield, $\mu$ moles	H <sub>2</sub> , Tot		10 <sup>8</sup> Rate, M s <sup>-1</sup>		DMS		
			Tot	Mol	Tot	Mol		Rad	H <sub>2</sub> , Rad	DMS, Tot				
514.3	12.0	150	5.05	2.27	2.78	1.75	4.68	2.93	0.123	21.9	12.1	20.3	12.7	0.534
363.5	8.46	120	3.64	1.27	2.37	0.98	3.65	2.67	0.153	19.8	12.9	19.8	14.5	0.231
361.4	8.41	150	3.71	1.59	2.12	1.23	3.17	1.94	0.139	16.1	9.19	13.8	8.42	0.604
269.3	6.25	120	2.33	0.93	1.40	0.72	2.17	1.45	0.100	12.7	7.58	11.8	7.86	0.543
205.4	4.78	240	2.91	1.15	1.46	1.12	3.13	2.01	0.17	7.90	3.96	8.50	5.46	0.462
203.7	4.74	360	4.42	2.16	2.26	1.66	4.32	2.66	0.28	8.00	4.10	7.82	4.81	0.507
203.3	4.73	150	1.76	0.87	0.89	0.67	1.74	1.07	0.080	7.64	3.85	7.56	4.63	0.243
154.1	3.59	150	1.17	0.66	0.51	0.51	1.16	0.65	0.054	5.08	2.21	5.04	2.81	0.235
113.5	2.64	180	1.03	0.585	0.445	0.45	0.94	0.49	0.055	3.73	1.61	3.40	1.77	0.199
102.0	2.37	360	1.76	1.12	0.64	0.87	1.58	0.71	0.11	3.19	1.15	2.86	1.29	0.199
76.0	1.77	150	0.51	0.33	0.18	0.25	0.40	0.15	0.020	2.22	0.80	1.74	0.64	0.027
56.4	1.31	150	-	-	-	0.30	0.19	0.11	0.014	-	-	1.29	0.46	0.062
51.7	1.20	150	0.35	0.23	0.12	0.29	0.18	0.11	0.011	1.52	0.53	1.26	0.50	0.048
50.4	1.17	480	1.08	0.69	0.39	0.97	0.535	0.435	0.050	1.47	0.53	1.32	0.59	0.063

a Volume 153.5 cc, S/V = 21 cm<sup>-1</sup>.

<sup>a</sup> Volume 153.5 cc, S/V = 21 cm<sup>-1</sup>.



determined at different temperatures are given in Table III-28 and for  $H_{2, \text{Rad}}$ ,  $\text{DMDS}_{\text{Rad}}$  and DMS at  $415^\circ\text{C}$  in the packed and unpacked reaction vessels in Table III-29.

It is evident that the reaction order for  $H_{2, \text{Rad}}$  is between 1.5 and 2.0 depending on the experimental conditions. Similar data for  $\text{DMDS}_{\text{Rad}}$  and DMS are available for one temperature only and exhibit considerable scatter; at  $415^\circ\text{C}$  the orders both appear to be approximately 1.5, similar to that of  $H_{2, \text{Rad}}$ .

The reaction orders found for  $H_{2, \text{Rad}}$ , 1.5-2.0, are in the expected range for a radical chain process. Considering that the order for  $H_{2, \text{Molec}}$  is 1.0 (Table III-17) and that the order of  $H_{2, \text{Total}}$  is slightly greater than unity, Table III-8, it would appear that a substantial portion of total  $H_2$  yield is formed in the radical chain.

The sequence of radical reactions which are assumed to take place in the pyrolysis of MMS,

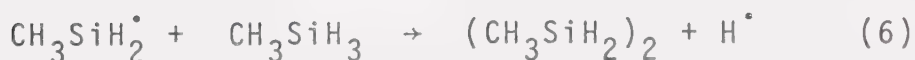




TABLE III-28  
 Reaction Orders for  $H_{2,Rad}$  in the Pyrolysis of  
 $MeSiH_3$  at Different Temperatures <sup>a</sup>

Temperature, °C	Order
441	1.74 <sub>±</sub> 0.13
429	1.47 <sub>±</sub> 0.14
421	1.65 <sub>±</sub> 0.07
400	1.59 <sub>±</sub> 0.07
381	1.65 <sub>±</sub> 0.08
361	1.55 <sub>±</sub> 0.17
341	1.88 <sub>±</sub> 0.04

<sup>a</sup> In an unpacked reaction vessel of  
 volume 206.6 cc,  $S/V = 1.0 \text{ cm}^{-1}$ .





TABLE III-29  
Reaction Orders for  $H_{2, \text{Rad}}$ ,  $\text{DMDS}_{\text{Rad}}$  and  
DMS in the Pyrolysis of  $\text{MeSiH}_3$  at  $415^\circ\text{C}$

Product	Order	
	Packed Vessel <sup>a</sup>	Unpacked Vessel <sup>b</sup>
$H_{2, \text{Rad}}$	$1.51 \pm 0.06$	$1.65 \pm 0.10$
$\text{DMDS}_{\text{Rad}}$	$1.62 \pm 0.06$	$1.32 \pm 0.22$
DMS	$1.32 \pm 0.12$	$1.59 \pm 0.09$

<sup>a</sup> Volume 153.5 cc,  $S/V = 21 \text{ cm}^{-1}$ .

<sup>b</sup> Volume 206.6 cc,  $S/V = 1.0 \text{ cm}^{-1}$ .



involves a free radical chain which is initiated unimolecularly by reaction (2) and propagated bimolecularly by reactions (5) and (6). The chain can be terminated either quadratically by reaction (7) or linearly on the walls of the reactor by reaction (8).

It can be shown that the reaction order for the products of such a chain reaction will depend mainly on the type of termination of the chain. Thus, if it is assumed that the products are formed predominantly by the chain propagation reactions (i.e. assuming a long chain length), then the usual steady-state approximations predict that the reaction order for  $H_{2,Rad}$  and  $DMDS_{Rad}$  will be  $3/2$  if the chain is terminated quadratically by (7), or 2 if the chain termination is linear, (8). The experimental reaction orders for  $H_{2,Rad}$  and  $DMDS_{Rad}$  however are between 1.5 and 2.0, and therefore it would seem that both quadratic and linear termination of the chain must participate in the reaction mechanisms.

We will return to the chain termination reactions after discussing the chain propagation steps.

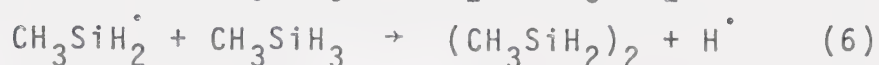
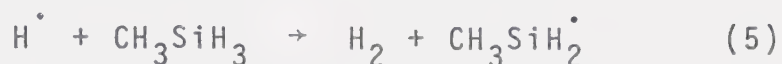
## (ii) Chain Propagation

The participation of a free radical chain mechanism in the pyrolysis of MMS has been already suggested by Ring et al.<sup>39</sup> and confirmed by the present



work (cf. Section III.B.ii.a).

Propagation of a free radical chain by reactions such as (5) and (6)



cannot be facile owing to the high activation energy of reaction (6) and can be operative only at elevated temperature. Thus, in the mercury ( $^3\text{P}_1$ ) photosensitized decomposition of  $\text{MeSiH}_3$  and  $\text{Me}_2\text{SiH}_2$ <sup>31</sup>, both H atoms and the corresponding silyl radicals were present but the product quantum yields indicated that no chains were operative at room temperature. In the case of dimethylsilane, the  $\text{H}_2$  quantum yields increased very rapidly above  $250^\circ\text{C}$ , indicating the onset of a chain reaction. Similarly, radical chain reactions are claimed to be present in the pyrolysis of  $\text{SiH}_4$  at ca  $400^\circ\text{C}$ <sup>39,88</sup>, but not at low temperatures<sup>37</sup>.

The values of the rate constants  $k_5$  and  $k_6$  have been estimated to be (Section III.B.3.ii):

$$k_5 (\text{M}^{-1}\text{s}^{-1}) \approx 10^{10.6} \exp(-3000/\text{RT})$$

$$k_6 (\text{M}^{-1}\text{s}^{-1}) \approx 10^{10} \exp(-13000/\text{RT})$$



The chain is propagated by H atoms and methylsilyl radicals the relative concentrations of which can be estimated from the rate constants  $k_5$  and  $k_6$  by

$$\frac{R_5}{R_6} = \frac{k_5 [H^\bullet] [MMS]}{k_6 [MeSiH_2^\bullet] [MMS]} = \frac{k_5}{k_6} \frac{[H^\bullet]}{[MeSiH_2^\bullet]}$$

By solving the kinetics of the radical process and applying the steady state approximations, it can be shown that if a long chain length is operative (i.e.  $H_{2,Rad}$  and  $DMDS_{Rad}$  are formed mainly by the chain propagation reactions), the rates of both propagation steps (5) and (6) are approximately the same, i.e.  $R_5/R_6 \approx 1$ . Hence,

$$\frac{[MeSiH_2^\bullet]}{[H^\bullet]} \approx \frac{k_5}{k_6} \approx 7 \times 10^3 \quad \text{at } 400^\circ\text{C}$$

Since the concentration of methylsilyl radicals is much higher than that of H atoms (cf. Section III.B.4.v) the chain will be terminated almost exclusively by methylsilyl radicals.

### (iii) Chain Termination

The metathetical reaction (5) of hydrogen atoms is highly efficient,  $k_5 \approx 10^{10.6} \exp(-3,000/RT)^{101}$ , and therefore under the experimental conditions employed in this study will go to completion. This leaves the





$\text{CH}_3\text{SiH}_2^\bullet$  radical as the chain terminating species via the bimolecular combination and disproportionation reactions,



or the heterogeneous wall reaction



The value of  $k_{7a}/k_7$  has been estimated to be 0.1 at 25°C<sup>33</sup> but at elevated temperatures it may be higher and may also be pressure dependent in the 40-400 torr range. Both reactions (7) and (7a) will be represented by a quadratic term in the overall rate equation and reaction (8), by a linear term.

No information is available on the nature of the products of reaction (8). In any case, since the chain length is large, the products of this termination step are very minor and can be neglected.

#### (iv) Formation of Dimethylsilane

Dimethylsilane, a minor product of the pyrolysis of MMS, must be formed in the radical process since (a) it can be completely scavenged by ethylene (cf.

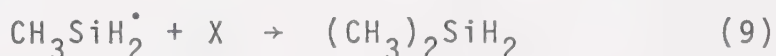
Table III-15), and



(b) there is an excellent correlation between the rates of formation of DMS and those of  $H_{2, Rad}$  and  $DMDS_{Rad}$ . The plots of  $Rate(H_2)_{Rad}$  vs.  $Rate(DMS)$  and  $Rate(DMDS)_{Rad}$  vs.  $Rate(DMS)$ , shown in Figure III-12 are linear and pass through the origin.

Since DMS is definitely not formed by the molecular process, its presence could serve as a criterion for the occurrence of radical reactions, and may also be used to estimate their importance.

At present, however, the mechanism of DMS formation is not very clear. In the reaction scheme proposed, Table III-20, reaction (9) describes the formation of DMS



but the exact nature of the species "X" cannot be defined since DMS might be formed in a partly or fully heterogeneous process. Although "X" is very likely the substrate, other species such as DMDS, the methylsilyl radical, methylsilylene or even polymer must also be considered.

If "X" is the substrate, reaction (9a) would form a silyl radical which would undergo further reactions, such as (9a-1) and (9a-2), forming monosilane and



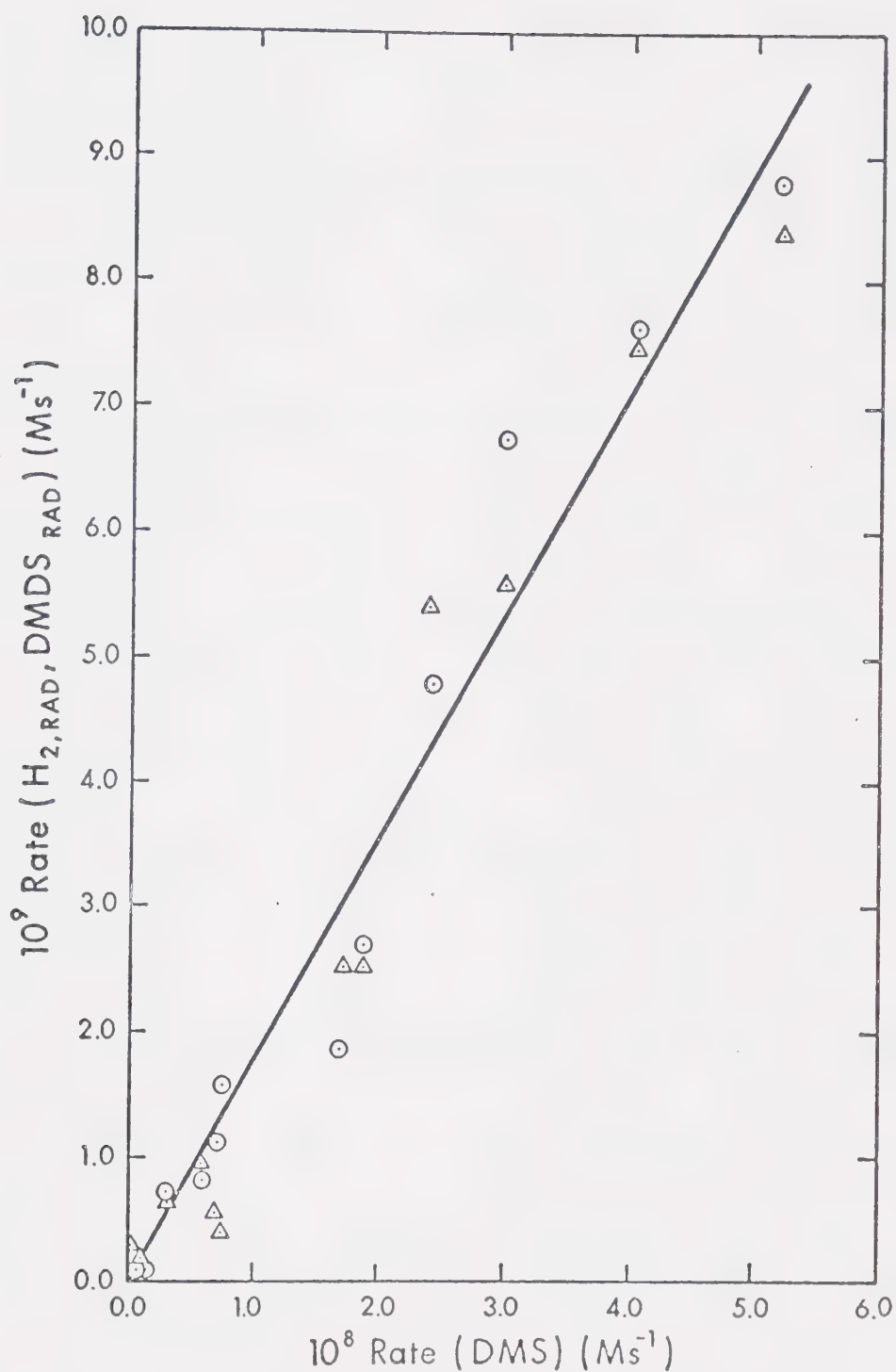
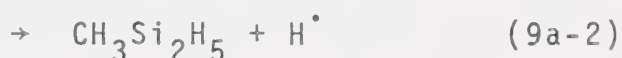
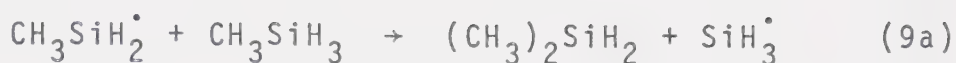


Figure III-12. Correlation Between the Products of the Radical Process in the Pyrolysis of MeSiH<sub>3</sub> at 415°C: Rate (H<sub>2</sub>)<sub>Rad</sub> (○) and Rate (DMDS)<sub>Rad</sub> (△) versus Rate (DMS).



methyldisilane:



Monosilane,  $\text{SiH}_4$ , was detected among the reaction products, and its yields were found to correlate to a certain degree with those of DMS (cf. Figure III-8 and Table III-1).

Negligible traces of methyldisilane were also detected.

If reaction (9a) is responsible for the formation of DMS, then methylsilyl radicals must be able to abstract a methyl group from the substrate. This type of metathetical reaction has been proposed by others. Thus, in early work on the pyrolysis of  $\text{Me}_6\text{Si}_2$ , Davidson and Stephenson<sup>106</sup> detected  $\text{Me}_4\text{Si}$  and suggested that it was formed by abstraction of a methyl group by a  $\text{Me}_3\text{Si}^\bullet$  radical,



Frangopol and Ingold<sup>90</sup>, however, expressed skepticism about this type of reaction, and recently Davidson et al.<sup>17</sup> offered an alternative reaction for the formation of  $\text{Me}_4\text{Si}$ :



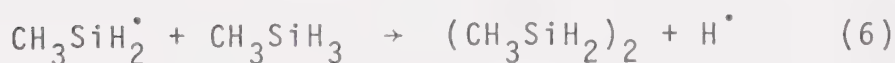
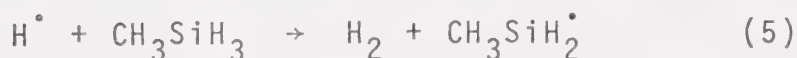
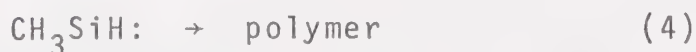




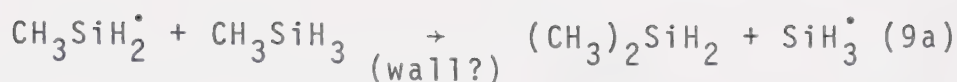
Further work is obviously needed in order to elucidate the modes of formation of DMS and  $\text{SiH}_4$  in the pyrolysis of MMS. At present, we feel that reactions (9a) and (9a-1) are the most probable sources of DMS and  $\text{SiH}_4$ , and are of the opinion that reaction (9a) is probably heterogeneous, (cf. Chapter IV).

#### (v) Rate Constants and Arrhenius Parameters for the Radical Process

It has been shown that the nature and the kinetics of formation of the products formed in the pyrolysis of MMS can be rationalized by postulating radical and molecular processes which occur simultaneously and independently. The proposed reactions are:







The rate expressions derived from this mechanism using steady-state assumptions, however, are too complex to be solved analytically. The main complication arises from the presence of two chain terminating steps, (7) and (8).

Were the radical chain terminated by only one process, i.e. quadratic or linear, the rate expressions would be more simple and amenable to kinetic interpretation. We shall now examine these two cases separately, bearing in mind that the actual situation may involve the simultaneous occurrence of both steps.

In the case that the chain is terminated quadratically, the rate expressions are:

$$R(\text{H}_2)_{\text{Total}} = (k_1 + k_2)^{\text{quad}} [\text{MMS}] + \left\{ k_6 \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{\text{quad}} [\text{MMS}]^{\frac{3}{2}} \quad (14)$$

$$R(\text{DMDS})_{\text{Total}} = (k_1 + k_2)^{\text{quad}} [\text{MMS}] + \left\{ k_6 \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{\text{quad}} [\text{MMS}]^{\frac{3}{2}} - R(\text{polymer}) \quad (15)$$

$$R(\text{DMS}) = \left\{ k_{9a} \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{\text{quad}} [\text{MMS}]^{\frac{3}{2}} \quad (16)$$



and for the case of linear termination,

$$R(H_2)_{Total} = (k_1 + k_2)^{lin} [MMS] + \{k_6 \frac{2k_2}{k_8}\}^{lin} [MMS]^2 \quad (17)$$

$$R(DMDS)_{Total} = k_1^{lin} [MMS] + \{k_6 \frac{2k_2}{k_8}\}^{lin} [MMS]^2 - R(polymer) \quad (18)$$

$$R(DMS) = \{k_{9a} \frac{2k_2}{k_8}\}^{lin} [MMS]^2 \quad (19)$$

(In the following discussion, the superscripts quad and lin will refer to the quadratic and linear termination mechanisms, respectively.)

The rate expressions for hydrogen, (14) and (17), contain two terms, one of which is first order and the other, of higher order, both with respect to MMS; it is significant that the coefficients of the first order terms are identical in both cases. The rate expressions for DMDS, (15) and (18), are very similar to those for  $H_2$ , except they contain an additional term corresponding to polymer formation. (The rate constant  $k_2$  does not appear in the first order term of eq (18) since the products of the chain termination reaction (8) have been neglected; if it is assumed that, for each two methylsilyl radicals terminated on the wall, one DMDS molecule is formed, then the first order terms of (18) and (17) will be the same.)



The kinetic expressions for  $R(H_2)$ , (14) and (17), are mathematically the most simple and since the experimental data on  $H_2$  (in Tables III-21 to III-27) are extensive and accurate, a more detailed analysis of the kinetics of  $H_2$  formation will now be attempted.

Rearranging (14) and (17) gives

$$\frac{R(H_2)_{Total}}{[MMS]} = (k_1 + k_2)^{quad} + \left\{ k_6 \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{quad} [MMS]^{\frac{1}{2}} \quad (20)$$

and

$$\frac{R(H_2)_{Total}}{[MMS]} = (k_1 + k_2)^{lin} + \left\{ k_6 \frac{2k_2}{k_8} \right\}^{lin} [MMS] \quad (21)$$

Equations (20) and (21) predict a linear relationship between  $R(H_2)_{Total}/[MMS]$  and  $[MMS]^{\frac{1}{2}}$  and  $[MMS]$ , respectively, and identical intercepts yielding  $k_1 + k_2$  directly.

The data in Tables III-21 to III-26 were used for the kinetic plots, representative examples of which are illustrated in Figure III-13.

The predicted linear relationships (20) and (21) hold, and each limiting case appears to be a reasonable approximation.

The first order rate coefficients corresponding to the intercepts of eqs (20) and (21) were determined by least mean squares analyses, and the results at different temperatures are listed in Table III-30; the values of





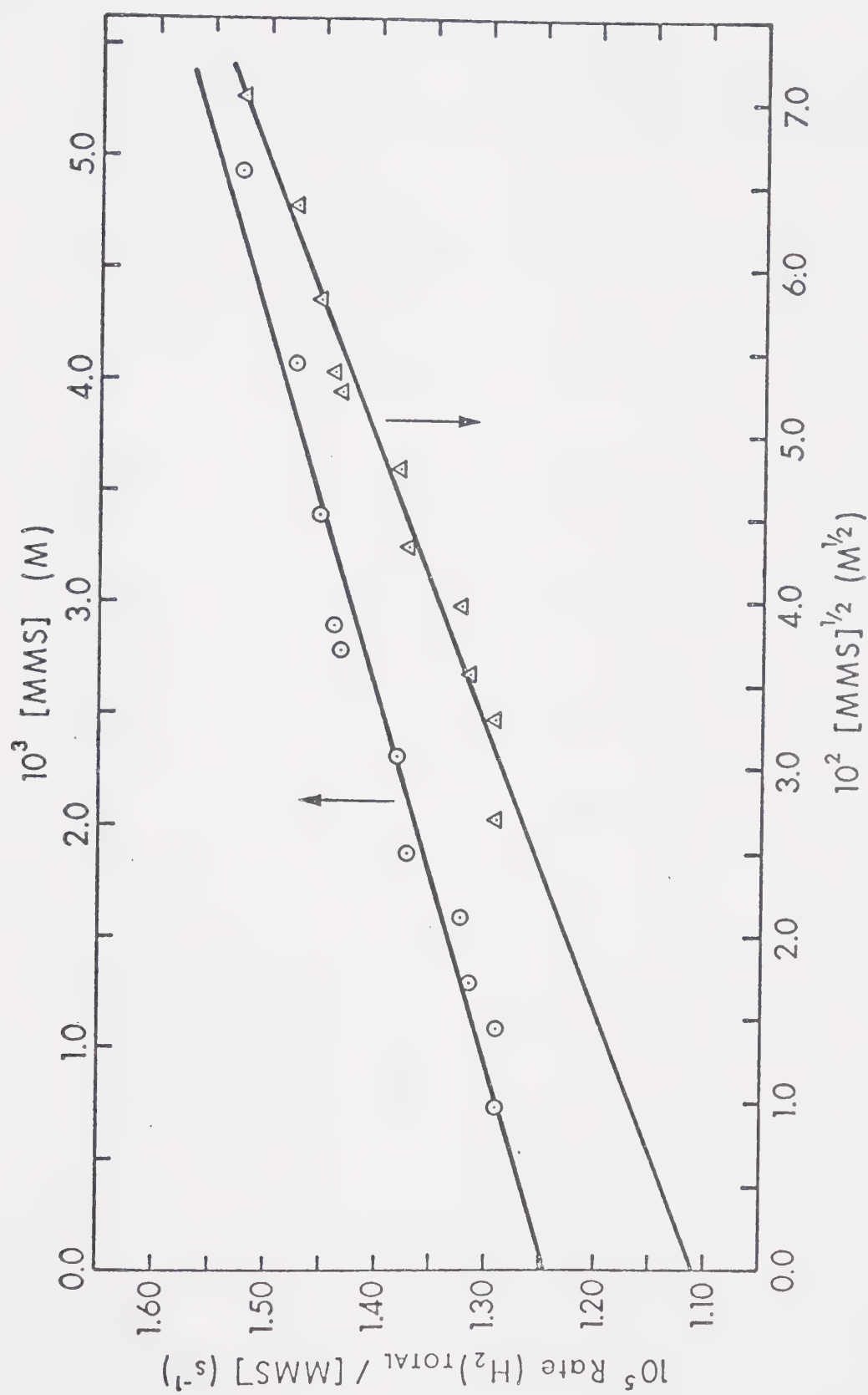


Figure III-13. Rate  $(\text{H}_2)_{\text{Total}} / [\text{MMS}]$  versus  $[\text{MMS}]^{1/2}$ ,  $(\odot)$ , and  $[\text{MMS}]$ ,  $(\triangle)$ , at  $421^\circ\text{C}$ .



TABLE III-30  
 Pyrolysis of  $\text{MeSiH}_3$  <sup>a</sup> : First-Order Rate Constants  
 for  $\text{H}_2$  Formation as a Function of Temperature

Temperature, °C	Rate Constant, $\text{s}^{-1}$		
	$k_1$ molec. <sup>b</sup>	$(k_1+k_2)$ quad <sup>c</sup>	$(k_1+k_2)$ lin <sup>d</sup>
441	$4.20 \times 10^{-5}$	$4.26 \pm 0.17 \times 10^{-5}$	$4.47 \pm 0.08 \times 10^{-5}$
429	-	$1.61 \pm 0.18 \times 10^{-5}$	$2.14 \pm 0.09 \times 10^{-5}$
421	$1.16 \times 10^{-5}$	$1.11 \pm 0.02 \times 10^{-5}$	$1.25 \pm 0.01 \times 10^{-5}$
415	$8.67 \times 10^{-6}$	$6.24 \pm 1.02 \times 10^{-6}$	$8.84 \pm 0.63 \times 10^{-8}$
400	$2.95 \times 10^{-6}$	$2.61 \pm 0.19 \times 10^{-6}$	$3.24 \pm 0.11 \times 10^{-6}$
381	$7.00 \times 10^{-7}$	$4.98 \pm 0.96 \times 10^{-7}$	$7.83 \pm 0.38 \times 10^{-7}$
361	$1.54 \times 10^{-7}$	$1.30 \pm 0.34 \times 10^{-7}$	$2.03 \pm 0.21 \times 10^{-7}$
341	$2.85 \times 10^{-8}$	$(-2.78 \pm 1.00 \times 10^{-8})$	$3.68 \pm 0.12 \times 10^{-8}$

<sup>a</sup> Unpacked vessel; 206.6 cc;  $S/V = 1.0 \text{ cm}^{-1}$ .

<sup>b</sup> In the presence of 10% ethylene (Table III-16).

<sup>c</sup> Intercept of eq. (20).

<sup>d</sup> Intercept of eq. (21).



$k_1^{\text{molec}}$ , the first order rate constant for  $\text{H}_2$  formation obtained in the presence of ethylene, are also included for comparison.

Inspection of Table III-30 shows that the kinetically derived values of  $k_1+k_2$  from either the linear or the quadratic termination mechanism are in reasonably good agreement with  $k_1^{\text{molec}}$ , except for  $(k_1+k_2)^{\text{quad}}$  at the lowest temperature,  $341^\circ\text{C}$ ; here the negative value of  $(k_1+k_2)^{\text{quad}}$  is probably due to experimental error (only three points were available for the plot). The calculated coefficients represent limiting cases, with  $(k_1+k_2)^{\text{quad}}$  and  $(k_1+k_2)^{\text{lin}}$  being lower and higher limits, respectively, of the actual case, i.e.  $(k_1+k_2)^{\text{quad}} \leq (k_1+k_2) \leq (k_1+k_2)^{\text{lin}}$ . It is significant that these rate coefficients are very close to  $k_1^{\text{molec}}$ : this implies that  $k_2$  must be relatively small. We shall return to this point later.

The logarithms of the rate coefficients  $k_1+k_2$  in Table III-30 were then plotted versus  $1/T$ , Figure III-14, and the activation energies and A factors derived by least mean squares analyses of the slopes and intercepts are given in Table III-31.

If it is assumed that the quadratic and linear termination steps participate to the same extent, the mean values of the Arrhenius parameters are



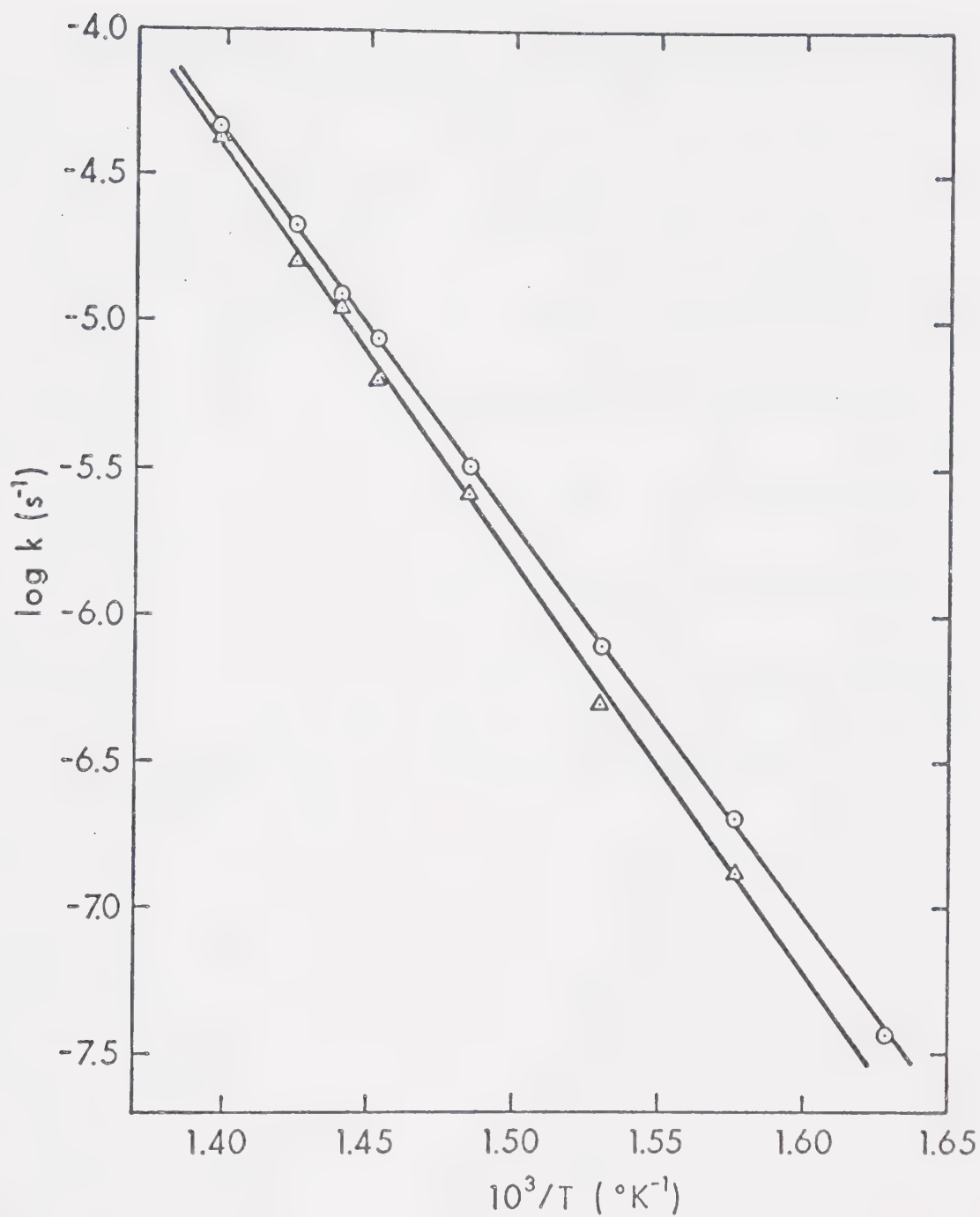


Figure III-14. Arrhenius Plots for the First Order Rate Constants  $(k_1+k_2)^{\text{lin}}$ ,  $\odot$ , and  $(k_1+k_2)^{\text{quad}}$ ,  $\triangle$ , based on Hydrogen Formation.





TABLE III-31  
Arrhenius Parameters for Hydrogen Formation in  
the Pyrolysis of Monomethylsilane

Rate Constant, $s^{-1}$	$\log A \ (s^{-1})$	$E_a$ , kcal/mol
$(k_1+k_2)^{quad}$	$15.40 \pm 0.44$	$64.75 \pm 1.37$
$(k_1+k_2)^{lin}$	$14.42 \pm 0.13$	$61.35 \pm 0.41$
$k_1^{molec. \ a}$	$15.02 \pm 0.10$	$63.27 \pm 0.31$

<sup>a</sup> From experiments with added ethylene, of Table III-18.



$$\log \bar{A}_1 (\text{s}^{-1}) = 14.91 \quad \text{and} \quad \bar{E}_1 = 63.06 \text{ kcal/mol} .$$

which are in excellent agreement with those of the molecular process (cf. Table III-18).

The rate constant  $k_2$  must therefore be small compared to  $k_1$ , and might thus be neglected in the calculations involving  $(k_1+k_2)$  without introducing any significant error. (This also implies that the chain length must be considerably long (cf. Sections IIIB.3.ii and III.B.4.vii) ).

The Arrhenius parameters of the radical chain reaction for the two extreme cases of chain termination can now be calculated. Since  $k_1 \gg k_2$ , only the higher order terms in (14) and (17) correspond to  $\text{H}_2$  formation by the radical chain process.

The rate coefficients  $\{k_6 (\frac{k_2}{k_7})^{\frac{1}{2}}\}$  <sup>quad</sup> and  $\{k_6 \frac{2k_2}{k_8}\}$  <sup>lin</sup>, obtained from least squares analyses of the slopes of the kinetic plots of equations (20) and (21), respectively, are listed in Table III-32 as a function of temperature.

If the data in Table III-32 are normalized to the same concentration units, then the rate constant ratios for the linearly and quadratically terminated chains are found to be of a comparable order of magnitude.



TABLE III-32  
Apparent Rate Constants for  $H_{2, Rad}$  as a Function of  
Temperature for Linear and Quadratic Termination  
of the Chain <sup>a</sup>

Temperature, °C	$\{k_6(k_2/k_7)^{1/2}\}^{quad}$ , $M^{-1/2} s^{-1}$	$\{k_6(2k_2/k_8)\}^{lin}$ , $M^{-1} s^{-1}$
441	$1.19 \pm 0.40 \times 10^{-4}$	$1.46 \pm 0.37 \times 10^{-3}$
429	$2.55 \pm 0.39 \times 10^{-4}$	$2.74 \pm 0.35 \times 10^{-3}$
421	$5.85 \pm 0.34 \times 10^{-5}$	$5.95 \pm 0.40 \times 10^{-4}$
415	$8.37 \pm 1.47 \times 10^{-5}$	$6.07 \pm 1.14 \times 10^{-4}$
400	$2.67 \pm 0.37 \times 10^{-5}$	$2.64 \pm 0.36 \times 10^{-4}$
381	$1.31 \pm 0.18 \times 10^{-5}$	$1.34 \pm 0.11 \times 10^{-4}$
361	$3.29 \pm 0.83 \times 10^{-6}$	$3.34 \pm 1.11 \times 10^{-5}$
341	$2.24 \pm 0.17 \times 10^{-6}$	$1.88 \pm 0.03 \times 10^{-5}$

<sup>a</sup> Cell volume 206.6 cc,  $S/V = 1.0 \text{ cm}^{-1}$ .



The Arrhenius plots of the data in Table III-32 are shown in Figure III-15 ; the values of  $E_a$  and  $\log A$  for the two limiting cases of chain termination were determined by least squares analyses and are given in Table III-33.

In spite of the relatively large errors associated with the calculated Arrhenius parameters, the overall activation energy for  $H_2$  formation by the radical process is nevertheless close to  $\sim 41$  kcal/mol and the  $A$  factor is probably between  $10^9$  ( $M^{-\frac{1}{2}}s^{-1}$ ) and  $10^{10}$  ( $M^{-1}s^{-1}$ ).

From these results it is now possible to decide whether the chain initiation step, reaction (2), is a homogeneous gas phase reaction, or whether it is a heterogeneously catalysed process.

#### (vi) Chain Initiation Step: Homogeneous or Heterogeneous?

It will be recalled that the rate of pyrolysis of MMS is strongly dependent on the nature of the surface but not on the  $S/V$  ratio. It has also been shown that the heterogeneity of the decomposition is associated with the radical process which is characterized by a long radical chain. These observations indicate that both initiation and termination of the chain are at least partly heterogeneous.





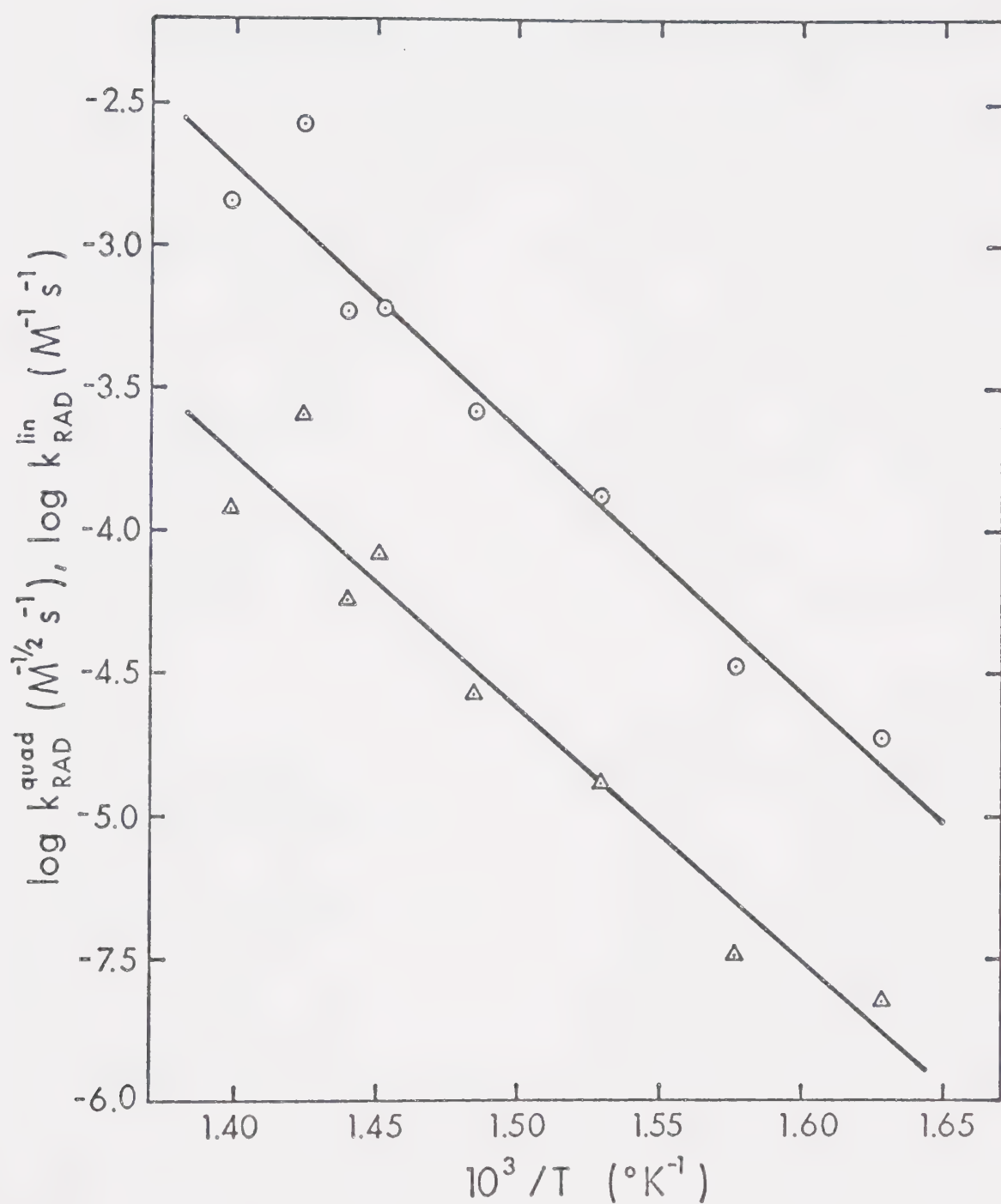


Figure III-15. Arrhenius Plots for the Rate Constants  $\{k_6 2k_2/k_8\}^{\text{lin}}$ ,  $\odot$ , and  $\{k_6 (k_2/k_7)^{1/2}\}^{\text{quad}}$ ,  $\triangle$ , based on Hydrogen Formation.



TABLE III-33  
 Apparent Arrhenius Parameters for  $H_{2, Rad}$  in the  
 Pyrolysis of  $MeSiH_3$  for Two Extreme Cases  
 of Chain Termination

Rate Constant	$\log A$	$E_a$ , kcal/mol
$\{k_6 (\frac{k_2}{k_7})^{\frac{1}{2}}\}^{quad}$	$8.8 \pm 1.5^a$	$40.9 \pm 4.4$
$\{k_6 \frac{2k_2}{k_8}\}^{lin}$	$10.3 \pm 1.3^b$	$42.4 \pm 4.0$

<sup>a</sup> In units of  $M^{-\frac{1}{2}} s^{-1}$ .

<sup>b</sup> In units of  $M^{-1} s^{-1}$ .



More compelling evidence for the heterogeneous nature of the chain initiation reaction (2)



can be obtained from the observed and estimated Arrhenius parameters for this reaction.

If (2) is a homogeneous gas phase reaction, then  $E_2$  should be approximately equal to the bond dissociation energy  $D(\text{MeSiH}_2\text{-H}) \sim 90 \text{ kcal/mol}^{13}$ , since  $E_{-2}$  will be close to zero. With regard to  $A_2$ , Benson<sup>107</sup> has estimated values of  $\text{ca. } 10^{15 \pm 1} \text{ s}^{-1}$  for this type of homogeneous gas phase decomposition.

If, on the other hand, reaction (2) is a heterogeneous process,  $E_2$  is expected to be considerably lower than  $D(\text{MeSiH}_2\text{-H})$ .

The values of  $E_2$  and  $A_2$  can be estimated from the Arrhenius parameters for the radical process, Table III-33.

First, if it is assumed that the chain is terminated quadratically, the rate constant for  $\text{H}_2$  formation by the radical process is

$$k_{\text{Rad}}^{\text{quad}} = k_6 \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}}$$

and therefore

$$E_{\text{Rad}}^{\text{quad}} = E_6 + \frac{1}{2}(E_2 - E_7) \sim 41 \text{ kcal/mol} \quad (24)$$



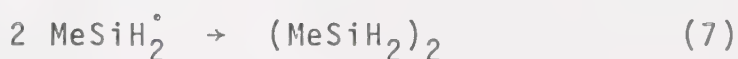
and

$$\log A_{\text{Rad}}^{\text{quad}} (\text{M}^{-\frac{1}{2}}\text{s}^{-1}) = \log A_6 + \frac{1}{2}(\log A_2 - \log A_7) \sim 9 \quad (25)$$

The Arrhenius parameters for reaction (6)



have been estimated (cf. Section III.B.3.b.ii) to be  $E_6 \sim 13$  kcal/mol and  $\log A_6 (\text{M}^{-1}\text{s}^{-1}) \sim 10$ , and those for reaction (7),



to be  $E_7 \sim 1$  kcal/mol and  $\log A_7 (\text{M}^{-1}\text{s}^{-1}) \sim 10$ , (cf. Section III.B.4.v). Thus,  $E_2^{\text{quad}}$  is calculated to be  $\sim 57$  kcal/mol, which is considerably lower than  $D(\text{MeSiH}_2\text{-H}) \sim 90$  kcal/mol; similarly  $A_2^{\text{quad}} \sim 10^8 \text{ s}^{-1}$ , which is seven orders of magnitude smaller than the preexponential factor associated with a gas phase homogeneous decomposition.

Now let us consider the second case, assuming that the free radical chain is terminated linearly: the rate constant is

$$k_{\text{Rad}}^{\text{lin}} = k_6 \frac{2k_2}{k_8}$$

and thus





$$E_{\text{Rad}}^{\text{lin}} = E_6 + E_2 - E_8 \approx 41 \text{ kcal/mol} \quad (26)$$

$$\text{and } \log A_{\text{Rad}}^{\text{lin}} (\text{M}^{-1} \text{s}^{-1}) = \log A_6 + \log A_2 - \log A_8 + \log 2 \approx 10 \quad (27)$$

Although no information is available on reaction (8),



it is very likely that the activation energy for such a process is very small, and thus  $E_8$  may be neglected in eq.(26). Since  $E_6 \sim 13 \text{ kcal/mol}$ , then  $E_2 \sim 28 \text{ kcal/mol}$ .  $A_2^{\text{lin}}$  cannot be estimated since  $A_8$  is unknown; however, for a rate of initiation comparable with a quadratic mechanism,  $A_2^{\text{lin}}$  should be several orders of magnitude smaller than  $A_2^{\text{quad}} (\sim 10^8 \text{ s}^{-1})$ .

Thus the kinetic treatment of each case of chain termination leads to the same conclusion, namely, that the activation energy  $E_2$  for the chain initiation reaction is between 28 and 57 kcal/mol which is considerably lower than  $D(\text{MeSiH}_2\text{-H}) \sim 90 \text{ kcal/mol}$ , and the preexponential factor in each case is incompatible with that normally associated with a homogeneous gas phase reaction. Therefore the chain initiation reaction (2) must be a heterogeneous process.

Further and more detailed studies of the heterogeneous reactions involved in the pyrolysis of



MMS are necessary in order to elucidate the mechanism of the radical process and particularly the formation of the minor products.

#### vii. Length of the Radical Chain

The length of the radical chain  $\lambda$  can be estimated from

$$\lambda = \frac{R_{\text{propagation}}}{R_{\text{termination}}}$$

where  $R_{\text{propagation}}$  can be approximated by  $R_{\text{H}_2, \text{Rad}}$  provided the chain is sufficiently long; only the quadratic termination rate will be considered since we have no data on the rate of linear termination.

The steady state concentration of methylsilyl radicals is given by

$$[\text{MeSiH}_2^\bullet]_{\text{quad}} = \left\{ \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{\text{quad}} [\text{MMS}]^{\frac{1}{2}}$$

$$\text{and } [\text{MeSiH}_2^\bullet]_{\text{lin}} = \left\{ \frac{2k_2}{k_8} \right\}^{\text{lin}} [\text{MMS}]$$

Using the data in Table III-32 and since

$k_6 = 10^{10} \exp(-13000/RT) \text{ M}^{-1}\text{s}^{-1}$ , one can calculate

$[\text{MeSiH}_2^\bullet]_{\text{quad}} = 3 \times 10^{-13} \text{ M}$  and  $[\text{MeSiH}_2^\bullet]_{\text{lin}} = 2 \times 10^{-11} \text{ M}$

at  $400^\circ\text{C}$  and  $[\text{MMS}] = 5 \times 10^{-3} \text{ M}$ . The average value of

$\sim 3 \times 10^{-12} \text{ M}$  will be used in the following calculations.



$R_{\text{termination}}$  can now be estimated from the Arrhenius parameters of reaction (7),



$E_7 \sim 1 \text{ kcal/mol}$  and  $A_7 \sim 10^{10} \text{ M}^{-1} \text{ s}^{-1}$  33,36,37,89,90

Thus at  $400^\circ\text{C}$

$$R_{\text{termination}} = k_7 [\text{MeSiH}_2^\bullet]^2 \approx 5 \times 10^9 [3 \times 10^{-12}]^2 \approx 5 \times 10^{-14} \text{ M s}^{-1}$$

and since, from Table III-23,  $R_{\text{propagation}} \approx R_{\text{H}_2, \text{Rad}} \approx 8 \times 10^{-8}$ , the chain length  $\lambda$  is approximately  $10^6$ .

##### 5. Some Thermochemical Implications of the Arrhenius Parameters for the Molecular Process

It has been shown that the rate data for  $\text{H}_2$  and DMDS obtained in the pyrolysis of MMS in the presence of ethylene refer to the molecular step



having the following average rate parameters (cf. Table III-18):

$$\log k_1 (\text{s}^{-1}) = (14.95 \pm 0.11) - (63200 \pm 330) / 2.3RT$$

Let us now consider the thermochemical implications of these results.



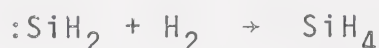
## (i) The Activation Energy

The enthalpy change for reaction (1),  $\Delta H_1^0$ , is related to the activation energies ( $E_1, E_{-1}$ ) of the forward and reverse reactions by

$$\Delta H_1^0 = \Delta E + \Delta nRT = (E_1 - E_{-1}) + \Delta nRT \approx E_1 - E_{-1} \quad (28)$$

where the term  $\Delta nRT$  allows for the change in the number of moles, but it is approximately compensated for by the temperature correction which should be applied to  $E_1$ .

Unfortunately the activation energy  $E_{-1}$  for insertion of methylsilylene into hydrogen, reaction (-1), has not been measured; it can be estimated however on the basis of the analogous reaction,



for which the rate constant has been determined<sup>66</sup>:

$$\log k (\text{M}^{-1}\text{s}^{-1}) = (9.1 \pm 0.4) - (5500 \pm 1000)/2.3RT$$

Thus, if it is assumed that  $E_{-1} \sim 6$  kcal/mol, then

$$\Delta H_1^0 = E_1 - E_{-1} = 63 - 6 = 57 \text{ kcal/mol}$$

Alternatively, the enthalpy change  $\Delta H_1^0$  is related to the enthalpies of formation by

$$\Delta H_1^0 = \Delta H_f^0(\text{MeSiH:}) + \Delta H_f^0(\text{H}_2) - \Delta H_f^0(\text{MeSiH}_3) \quad (29)$$





Using the reported values of  $\Delta H_f^0(\text{MeSiH}_3)$ , - 4 kcal/mol<sup>13, 14, 18</sup> and  $\Delta H_f^0(\text{MeSiH:})$ , 53.1 kcal/mol<sup>77</sup>,

$$\Delta H_1^0 = 53 + 4 = 57 \text{ kcal/mol},$$

which is consistent with the above calculation.

The enthalpies of formation used above may not be very accurate however, since Vanderwielen, Ring and O'Neal<sup>77</sup>, in their calculation of  $\Delta H_f^0(\text{MeSiH:}) = 53.1$  kcal/mol, used  $\Delta H_f^0(\text{MeSiH}_3) = 1.0$  kcal/mol, suggested by Potzinger and Lampe<sup>11</sup> for the bond additivity scheme. Using this value for  $\Delta H_f^0(\text{MeSiH}_3)$ ,

$$\Delta H_1^0 = 53 - 1 = 52 \text{ kcal/mol}$$

which in turn implies that  $E_{-1}$  should be approximately 11 kcal/mol, a considerably higher value than the one assumed before.

Since the present thermochemical data are obviously inaccurate, the mean value

$$\Delta H_1^0 \approx \frac{1}{2}(57 + 52) = 55 \text{ kcal/mol}$$

will be used in the following discussion.

Reaction (1) involves splitting of two Si-H bonds in monomethylsilane and formation of a hydrogen molecule, and thus the enthalpy change  $\Delta H_1^0$  is related to the bond dissociation energies by



$$\Delta H_1^0 = D(\text{MeSiH}_2\text{-H}) + D(\text{MeSiH-H}) - D(\text{H-H}) \quad (30)$$

The value of  $D(\text{H-H}) = 104.2$  kcal/mol is well established<sup>108</sup>, and  $D(\text{MeSiH}_2\text{-H})$  can be estimated from recently published data as follows.

From electron impact studies, Potzinger et al.<sup>13</sup> concluded that the first (Si-H) bond dissociation energies in  $\text{SiH}_4$ ,  $\text{MeSiH}_3$ ,  $\text{Me}_2\text{SiH}_2$  and  $\text{Me}_3\text{SiH}$  are approximately the same and equal to  $\sim 89 \pm 4$  kcal/mol. These results are in excellent agreement with those of Berkley et al.<sup>61</sup> who reported that the activation energies for H atom abstraction by methyl radicals from the Si-H bond in silane, mono-, di-, and trimethylsilane are the same but that for  $\text{SiH}_4$  is  $\sim 1$  kcal/mol lower. Walsh and Wells<sup>19</sup> have investigated the gas phase reaction between iodine and trimethylsilane and measured  $D(\text{Me}_3\text{Si-H}) = 90.0 \pm 2.6$  kcal/mol; a similar value,  $D(\text{Me}_3\text{Si-H}) = 88$  kcal/mol, has been determined by Davidson and Howard<sup>17</sup> from the pyrolysis of  $\text{Me}_6\text{Si}_2$ . Thus an average value of  $D(\text{MeSiH}_2\text{-H})$  of  $90 \pm 3$  kcal/mol can be used with a high degree of confidence.

Using eq (30) we can therefore calculate the second bond dissociation energy  $D(\text{MeSiH-H})$ :

$$\Delta H_1^0 = D(\text{MeSiH}_2\text{-H}) + D(\text{MeSiH-H}) - D(\text{H-H}) \quad (30)$$

$$55 = 90 + D(\text{MeSiH-H}) - 104$$

$$D(\text{MeSiH-H}) = 69 \text{ kcal/mol}$$



Although the error might be as high as 6 kcal/mol (but probably less), this value nevertheless indicates a large drop from the first to the second BDE in monomethylsilane, of approximately 20 kcal/mol.

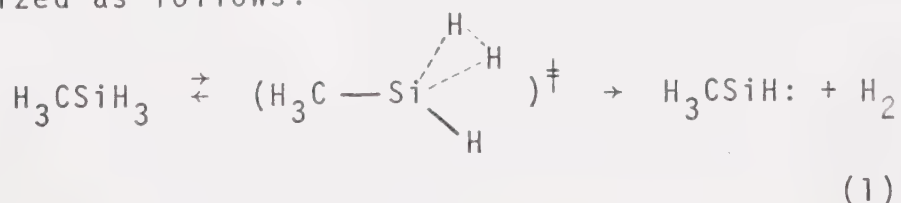
This large decrease appears to be a general trend in silicon chemistry, and has not been observed for carbon compounds. Thus in the cases of  $\text{SiH}_4$ ,  $\text{SiCl}_4$ <sup>19</sup> and  $\text{Me}_4\text{Si}$ <sup>27</sup>, differences of approximately 35, 55 and 65 kcal/mol, respectively, have been calculated.

Some specific stabilizing effect must therefore be present in divalent silicon species, a qualitative explanation of which has been suggested by Walsh and Wells<sup>19</sup>.

## (ii) The Preexponential Factor

The preexponential factor of reaction (1),  $\log A(\text{s}^{-1}) = 14.95$ , may yield some information about the nature of the transition state.

The most probable configuration of the transition state is a three-centered cyclic intermediate which may be visualized as follows:





A similar transition state has been suggested by Purnell and Walsh <sup>38</sup> for the pyrolysis of  $\text{SiH}_4$ , which is assumed to decompose molecularly, and the preexponential factor,  $\log A(\text{s}^{-1}) = 15.18 \pm 0.16$ , is practically the same as that obtained for the molecular process of MMS. Some problems, however, still persist with respect to the mechanism of pyrolysis of  $\text{SiH}_4$  (cf. Section I.A.6.ii.d).

A three-centered cyclic transition state has also been suggested for the thermal decompositions of disilane and methylidisilanes <sup>58,65,77</sup> which produce silylenes <sup>27</sup>, and for the reverse reaction, insertion of silylene into Si-H bonds <sup>68</sup>.

It is interesting to note that the A factor for the molecular process in the pyrolysis of MMS,  $\log A(\text{s}^{-1}) = 15.0$ , is of the same order of magnitude as those for pyrolyses of small ring compounds <sup>109</sup>.

Transition state theory predicts the following relationship between the entropy of activation  $\Delta S_1^\ddagger$  and the A factor for unimolecular reactions at high pressures <sup>107</sup>:

$$A_1 = \left(\frac{ekT}{h}\right) e^{\Delta S_1^\ddagger / R} \quad (31)$$

where





$A_1 = 10^{14.95} \text{ s}^{-1}$  - Preexponential factor of reaction (1)

$e = 2.718$  - Base of natural logarithms

$k = 1.358 \times 10^{-16} \text{ erg deg}^{-1}$  - Boltzmann constant

$h = 6.626 \times 10^{-27} \text{ erg s}$  - Planck constant

$\bar{T} = 670^\circ\text{K}$  - Mean reaction temperature

$R = 1.987 \text{ cal deg}^{-1} \text{ mol}^{-1}$  - gas constant

from which  $\Delta S_1^\ddagger = 6.3 \text{ e.u.}$

Since the activation entropy is rather large and positive, the transition state may be classified as "loose".

The activation entropy,  $\Delta S_1^\ddagger$ , is the difference between the molar entropy of the transition state,  $S_\ddagger^0$ , and that of the reactant,  $S_{\text{MMS}}^0$ , i.e.

$$\Delta S_1^\ddagger = S_\ddagger^0 - S_{\text{MMS}}^0 \quad (32)$$

The molar entropies can be calculated directly from the known molecular parameters by the methods of statistical mechanics. The absolute value of  $S_{\text{MMS}}^0$  can be therefore determined "exactly", but the same is not possible for  $S_\ddagger^0$  since the required molecular data (e.g. structural parameters, fundamental vibrational frequencies, symmetry, etc.) are not available for the transition state. One may nevertheless estimate these transition state parameters and calculate the corresponding activation entropy in order to verify the correctness of the assumed model.



On the basis of the suggested configuration of the transition state, let us first examine which degrees of freedom will contribute the most to the activation entropy.

From statistical mechanics, we know that the molar entropy  $S$  can be expressed in terms of the molar partition function  $Q$  as

$$S = k \ln Q + k \left( \frac{\partial \ln Q}{\partial \ln T} \right)_V \quad (33)$$

and

$$Q = \frac{q_{\text{tran}}}{N!} q_{\text{rot}}^N q_{\text{vib}}^N q_{\text{elec}}^N e^{-E_0/kT} \quad (34)$$

where  $k$  is the Boltzmann constant,  $N$  is Avogadro's number,  $E_0$  is the zero point energy and  $q_{\text{tran}}$ ,  $q_{\text{rot}}$ ,  $q_{\text{vib}}$ ,  $q_{\text{elec}}$  are the molecular partition functions for translation, rotation, vibration and electronic excitation. The standard molar entropy will therefore be the sum of the contributions from the different degrees of freedom,

$$S^0 = S_{\text{tran}}^0 + S_{\text{rot}}^0 + S_{\text{vib}}^0 + S_{\text{elec}}^0$$

and similarly from eq (32) we obtain

$$\Delta S_1^\ddagger = \Delta S_{\text{tran}}^\ddagger + \Delta S_{\text{rot}}^\ddagger + \Delta S_{\text{vib}}^\ddagger + \Delta S_{\text{elec}}^\ddagger$$



Since both monomethylsilane and the transition state complex are expected to remain in their singlet ground electronic states, there will be no contribution from electronic excitation to  $\Delta S_1^\ddagger$ .

The translational contribution to  $\Delta S_1^\ddagger$  will also be zero since no change in the molecular weight has taken place in the formation of the transition state:

$$\Delta S_{\text{tran}}^\ddagger = \frac{3}{2}R \ln \frac{M_1^\ddagger}{M_{\text{MMS}}} = \frac{3}{2}R \ln 1 = 0 \quad (37)$$

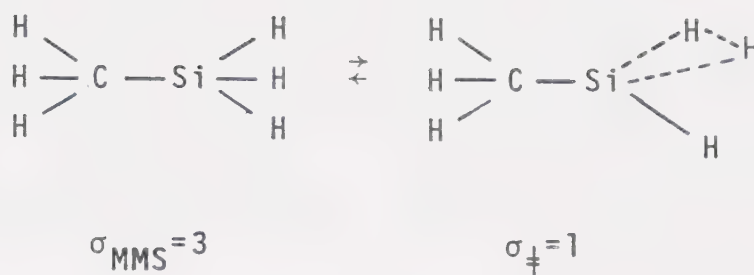
External rotation of a nonlinear molecule will contribute to the entropy of activation by

$$\Delta S_{\text{rot}}^\ddagger = R \ln \left[ \frac{(I_A I_B I_C)_{1^\ddagger}^{\frac{1}{2}}}{(I_A I_B I_C)_{\text{MMS}}^{\frac{1}{2}}} \frac{\sigma_{\text{MMS}}}{\sigma_{1^\ddagger}} \right] \quad (38)$$

where  $I_A I_B I_C$  is the product of the principal moments of inertia and  $\sigma$  is the total symmetry number. Since the mass of a hydrogen atom is extremely small, the moments of inertia of the transition state complex  $(I_A, I_B, I_C)_{1^\ddagger}$  will not be very different from those of the reactant  $(I_A, I_B, I_C)_{\text{MMS}}$ , and thus rotation will not contribute significantly to  $\Delta S_1^\ddagger$  except if some change in the symmetry numbers  $\sigma_{1^\ddagger}$ ,  $\sigma_{\text{MMS}}$  occurs. The  $\text{CH}_3\text{SiH}_3$  molecule has one threefold symmetry axis and hence  $\sigma_{\text{MMS}} = 3$ ; since this symmetry is destroyed when the transition state is formed,



$$\sigma_{\ddagger} = 1.$$



From eq (38) we therefore obtain

$$\Delta S_{\text{rot}}^{\ddagger} \approx R \ln \left( \frac{\sigma_{\text{MMS}}}{\sigma_{\ddagger}} \right) = R \ln \frac{3}{1} = +2.2 \text{ e.u.}$$

Finally, we will examine the contribution from the vibrational modes (including hindered rotation) to  $\Delta S_1^{\ddagger}$ . From statistical mechanics the following expression can be derived for the vibrational entropy of a harmonic oscillator of frequency  $\omega$  ( $\text{cm}^{-1}$ ):

$$S_{\text{vib}}^0 = R \left[ \frac{x}{e^x - 1} - \ln(1 - e^{-x}) \right] \quad (39)$$

where  $x = hc\omega/kT$ . To calculate the total vibrational entropy of the molecule, the contribution from each fundamental vibrational frequency must be considered, and the summation must be taken over all vibrational modes.

To estimate the vibrational contribution  $\Delta S_{\text{vib}}^{\ddagger}$  to the activation entropy, however, we may consider only those vibrational frequencies of the reactant which will





be most likely affected by formation of the transition state (i.e. the stretching and bending frequencies of the Si-H bonds,  $\omega_{\text{SiH}}$ ) and leave the other frequencies unchanged.

Since the transition state is "loose", we expect a lowering of these vibrational frequencies and estimate

$$\omega_{\text{SiH},\ddagger} \approx \frac{2}{3} \omega_{\text{SiH},\text{MMS}}$$

According to transition state theory, one vibrational mode in the activated complex corresponds to the "reaction coordinate" and must be omitted in the calculation of  $\Delta S_{\text{vib}}^{\ddagger}$ .

The data used for the calculation of  $\Delta S_{\text{vib}}^{\ddagger}$  are shown in Table III-34; the fundamental frequencies of  $\text{CH}_3\text{SiH}_3$  were taken from the literature<sup>110</sup>. Benson<sup>111</sup> has tabulated the absolute entropies of a harmonic oscillator using eq (39), and these data have been used to estimate how the frequency shifts will contribute to the vibrational entropy of activation.

From Table III-34 it is seen that the main contribution to the vibrational entropy of activation comes from the weakened bending modes of the Si-H bonds of the transition state.

The individual contributions to the entropy of activation are summarized in Table III-35 where it is



TABLE III-34  
Estimated Contributions from some Fundamental Vibrations of  $\text{CH}_3\text{SiH}_3$  to the  
Entropy of Activation at 670°K

Mode	Degeneracy	Frequency, $\text{cm}^{-1}$ MMS <sup>a</sup>	(MMS) <sup>b</sup>	Vib. Entropy, $\text{e.u.}$ $\frac{S^\circ}{\text{MMS}}$	$\Delta S^\ddagger$ vib., $\text{e.u.}$
$\text{CH}_3$ sym.str.	1	2928			
$\text{SiH}_3$ sym.str.	1	2169 $\rightarrow$ 1450		0.2 $\rightarrow$ 0.4	+0.2
$\text{CH}_3$ sym.def.	1	1266			
$\text{SiH}_3$ sym.def.	1	946 $\rightarrow$ 630		1.0 $\rightarrow$ 1.7	+0.7
Si-C stretch	1	701			
Torsion	1	200			
$\text{CH}_3$ asym.str.	2	2982			
$\text{SiH}_3$ asym.str.	2	2166 $\rightarrow$ 1450	R.C. <sup>d</sup>	0.2 $\rightarrow$ 0	-0.2
$\text{CH}_3$ asym.def.	2	1412		0.2 $\rightarrow$ 0.4	+0.2
$\text{SiH}_3$ asym.def.	2	943 $\rightarrow$ 630		2.0 $\rightarrow$ 3.4	+1.4
$\text{CH}_3$ rock	2	870			
$\text{SiH}_3$ rock	2	540 $\rightarrow$ 360		3.6 $\rightarrow$ 5.2	+1.6
				Total	+3.9

<sup>a</sup> Taken from Reference 110.

<sup>b</sup> Estimated:  $\omega_1 = \frac{2}{3} \omega_{\text{MMS}}$

<sup>c</sup> Determined from the tabulated data of Benson 111.

<sup>d</sup> One of these doubly degenerate modes is taken as the reaction coordinate.



TABLE III-35  
Contributions to the Entropy of Activation  
 $\Delta S_1^\ddagger$  at 670°K <sup>a</sup>

Modes	$\Delta S_1^\ddagger$ e.u.
Translation	0
Rotation	unimportant
Symmetry <sup>b</sup>	+2.2
Electronic excitation	0
<u>Vibration <sup>c</sup></u>	<u>+3.9</u>
Total, calculated	+6.1
observed	+6.3

<sup>a</sup> Mean Reaction Temperature.

<sup>b</sup> Calculated from the symmetry numbers  $\sigma$  in the rotational partition function and may be interpreted as the degeneracy of the reaction path.

<sup>c</sup> Cf. Table III-34.



seen that the major factors responsible for the large increase in entropy are the changes in the symmetry numbers and vibrational frequencies..

The calculated entropy of activation is in good agreement with the experimental value and therefore the suggested structure of the transition state appears to be a reasonable model.





## CHAPTER IV

### PYROLYSIS OF DIMETHYLSILANE

#### A. Results

A preliminary study of the pyrolysis of dimethylsilane (DMS) has been carried out in the temperature and pressure ranges 440 - 500°C and 41 - 395 torr respectively, using the same static system as described previously. The effects of reaction time, surface and addition of ethylene have been investigated.

#### 1. The Reaction Products

The following products have been observed in the initial stages of the pyrolysis: hydrogen, 1,1,2,2-tetramethyldisilane (TMDS), trimethylsilane (TMS), monomethylsilane (MMS), methane, and a solid polymeric deposit.

Hydrogen and TMDS were the major reaction products, TMS and MMS were minor products; methane was formed only in traces, its yield being approximately 1% of those of the major products. Reproducible reaction rates were observed only in a vessel which was well coated by polymer from previous runs.



## 2. Time Study

The variation of the yields of the gaseous products with time has been investigated at 490°C and at  $\sim 125$  torr dimethylsilane. The reaction vessel (206.6 cc,  $S/V = 1.0 \text{ cm}^{-1}$ ), coated by a polymer from previous runs, was heated at 510°C and evacuated overnight before each experiment in order to minimize thermal decomposition of the polymer. The rate of degassing from the coated vessel was monitored after each run for at least 30 min and found to be negligible.

The results of the time study, listed in Table IV-1 and plotted in Figure IV-1, show that the yields of  $\text{H}_2$ , TMDS, TMS and MMS were all linear functions of time at conversions below  $\sim 0.8\%$ . Furthermore, a close correspondence between the yields of  $\text{H}_2$  and TMDS and between those of TMS and MMS was observed.

## 3. Effect of the Nature of the Surface

As in the thermal decomposition of MMS (cf. Section III.A.3), the rate of pyrolysis of DMS was found to be dependent on the conditions of the reactor surface, particularly on the extent of polymer deposition.



TABLE IV-1  
Product Yields as a Function of Time in the Pyrolysis of  $\text{Me}_2\text{SiH}_2$  at 490°C<sup>a</sup>

Time, min	P(DMS), torr	Yields, $\mu$ moles				Conversion %
		H <sub>2</sub>	TMDS	TMS	CH <sub>4</sub>	
5.00	125.6	1.27	1.23	0.274	0.201	0.233
5.00	127.1	1.28	1.24	0.273	0.227	0.232
10.00	126.3	2.56	2.59	0.698	0.651	0.467
15.00	124.7	3.94	3.90	0.928	0.823	0.729
15.60	125.3	4.09	4.07	1.16	1.06	0.753
20.00	124.3	6.27	5.65	2.56	2.07	1.162
20.00	122.9	5.93	5.39	2.68	2.10	1.011

<sup>a</sup> Cell volume 206.6 cc,  $S/V = 1.0 \text{ cm}^{-1}$ .

<sup>b</sup> Calculated from H<sub>2</sub> yield.



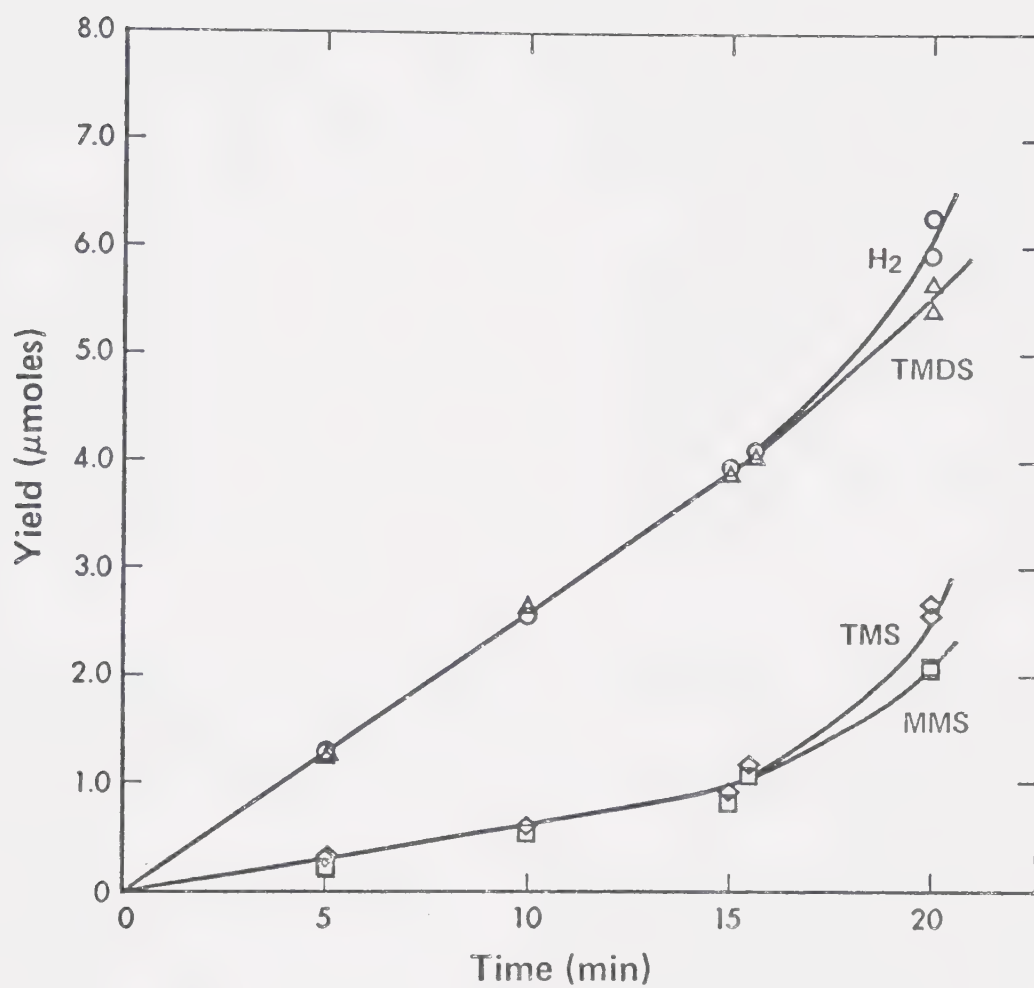


Figure IV-1. Product Yields as a Function of Time in the Pyrolysis of  $\sim 125$  torr  $\text{Me}_2\text{SiH}_2$  at  $490^\circ\text{C}$ .





Thus, it was observed that the rate of pyrolysis in a reaction vessel which had been heated and evacuated for several days (up to a week) was always high; after 2 or 3 experiments performed in rapid succession, however, the reaction rates decreased to reasonably reproducible values.

The effect of polymer deposition on the product yields is evident from the data in Table IV-2. The yields of TMS and MMS were profoundly influenced by the mode of pretreatment of the vessel, which suggests that these two products might be of heterogeneous origin. In contrast, those of  $H_2$  and TMDS were virtually unaffected.

#### 4. Determination of the Reaction Orders, and the Effect of Ethylene on the Reaction Rates

The rates of product formation as a function of DMS pressure (in the range 41 - 395 torr) have been measured between 440 and 500°C, and the results are listed in Tables IV-3 - IV-5; the conversions did not exceed 0.6% and were generally in the range of 0.1 - 0.3%. The effect of added ethylene is also shown in these Tables where it is seen that the yields of  $H_2$  and TMDS are unaffected by the presence of a radical scavenger but those of TMS and particularly MMS are greatly reduced. Some new products were formed, the most predominant of which was tentatively identified as dimethylethylsilane from its mass spectrum



TABLE IV-2

The Effect of Polymer Deposition on the Product Yields  
in the Pyrolysis of  $\text{Me}_2\text{SiH}_2$  at  $490^\circ\text{C}$  <sup>a</sup>

Run No.	P(DMS), torr	Yields, $\mu$ moles			
		H <sub>2</sub>	TMDS	TMS	MMS CH <sub>4</sub>
1 <sup>b</sup>	125.7	3.40	3.34	3.65	3.60 0.025
2 <sup>c</sup>	127.2	2.69	2.71	1.11	1.03 0.029
3 <sup>c</sup>	126.3	2.56	2.59	0.698	0.651 0.020

<sup>a</sup> Reaction time 10.00 min; cell volume 206.6 cc;  $S/V = 1.0 \text{ cm}^{-1}$ .

<sup>b</sup> The cell was heated at  $510^\circ\text{C}$  and evacuated for  $\sim 1$  month.

<sup>c</sup> The cell was heated at  $510^\circ\text{C}$  and evacuated for  $\sim 16$  hours.



TABLE IV-3

Product Yields and Rates of Formation as a Function of Dimethylsilane  
Pressure at 500°C and 480°C; Effect of Added Ethylene<sup>a</sup>

P(DMS), torr	Time, s	[DMS], M x 10 <sup>3</sup>	C <sub>2</sub> H <sub>4</sub> %	Yields, $\mu$ moles			Rate, M s <sup>-1</sup> x 10 <sup>9</sup>				
				H <sub>2</sub>	TMDS		H <sub>2</sub>	TMDS			
					TMS	MMS		TMS	MMS		
T=500°C											
212.8	240	4.400	-	3.06	3.04	0.77	0.78	61.7	61.3	15.5	15.7
149.8	240	3.096	-	2.10	2.09	0.42	0.41	42.35	42.2	8.47	8.27
105.9	240	2.196	-	1.44	1.444	0.172	0.168	29.0	29.1	3.47	3.29
41.4	300	0.858	9.14	0.695	0.684	0.022	0.021	11.2	11.0	0.36	0.34
T=480°C											
296.2	300	6.302	-	1.82	1.77	1.34	1.32	29.4	28.6	21.6	21.25
98.6	600	2.099	-	1.057	1.03	0.182	0.156	8.53	8.31	1.41	1.26
53.6	900	1.139	-	0.809	0.82	0.127	0.117	4.35	4.41	0.68	0.63

<sup>a</sup> Cell volume 206.6 cc, S/V = 1.0 cm<sup>-1</sup>. The cell, freshly coated by polymer, was heated at 510°C and evacuated for ~ 16 hours.



TABLE IV-4  
Product Yields and Rates of Formation as a Function of Dimethylsilane  
Pressure at 490°C; Effect of Added Ethylene<sup>a</sup>

P(DMS), torr	Time, s	[DMS], M x 10 <sup>3</sup>	C <sub>2</sub> H <sub>4</sub> %	Yields, $\mu$ moles			Rate, M s <sup>-1</sup> x 10 <sup>9</sup>		
				H <sub>2</sub>	TMDS	TMS	H <sub>2</sub>	TMDS	TMS
						MMS			MMS
214.0	300	4.494	-	2.47	2.44	1.77	39.85*	39.4*	28.6*
									26.5*
156.6	300	3.288	-	1.57	1.53	0.455	25.3	24.7	7.34
									7.49
127.1	300	2.668	-	1.28	1.24	0.273	20.65	20.0	4.40
									3.66
125.6	300	2.637	-	1.27	1.23	0.274	20.5	19.85	4.42
									3.24
125.5	300	2.636	0.89	1.25	1.20	0.263	20.2	19.4	4.24
									3.05
109.8	420	2.305	-	1.51	1.47	0.297	17.4	17.2	3.42
									2.32
78.8	600	1.654	-	1.52	1.485	0.220	12.3	12.0	1.78
									2.05
75.1	306	1.576	-	0.725	0.724	0.076	11.5	11.5	1.20
									1.19

<sup>a</sup> Cell Volume 206.6 cc, S/V = 1.0 cm<sup>-1</sup>. The cell, freshly coated by polymer, was heated at 510°C and evacuated for ~ 16 hours before each run, unless stated otherwise.

\* This experiment was performed in a surface-active cell and the resulting high rates are not included in the order plots.





TABLE IV-5  
Product Yields and Rates of Formation as a Function of Dimethylsilane  
Pressure at 460 and 440°C; Effect of Added Ethylene<sup>a</sup>

P(DMS), torr	Time, s	[DMS], M $\times 10^3$	C <sub>2</sub> H <sub>4</sub> %	Yields, $\mu$ moles			Rate, M s <sup>-1</sup> $\times 10^9$				
				H <sub>2</sub>	TMDS	TMS	MMS	H <sub>2</sub>	TMDS	TMS	MMS
T=460°C											
282.5	720	6.172	-	1.26	1.28	1.39	1.35	8.47	8.61	9.34	9.08
242.7	960	5.306	9.14	1.44	1.38	0.261	0.120	7.26	6.96	1.32	0.61
143.1	1800	3.060	-	1.43	1.42	1.17	1.16	3.85	3.82	3.15	3.12
119.0	1920	2.602	9.14	1.245	1.22	0.159	0.095	3.14	3.08	0.40	0.24
58.0	4200	1.268	9.14	1.27	1.25	0.123	0.059	1.46	1.44	0.14	0.07
47.4	4800	1.036	-	1.19	1.20	0.307	0.285	1.20	1.21	0.31	0.29
T=440°C											
394.6	1800	8.872	-	2.17	2.06	7.41	7.29	5.83*	5.54*	19.9*	19.6*
340.2	2850	7.644	9.14	2.025	1.86	0.601	0.122	3.44	3.16	1.02	0.21
197.9	2700	4.448	-	0.954	0.921	1.15	1.14	1.71	1.65	2.06	2.04
169.1	3000	3.801	9.14	0.908	0.855	0.197	0.087	1.465	1.38	0.32	0.14
82.4	9000	1.851	9.14	1.21	1.14	0.236	0.075	0.651	0.613	0.127	0.040
68.5	15600	1.540	-	1.67	1.68	1.06	1.00	0.519	0.521	0.338	0.304

<sup>a</sup> Cell volume 206.6 cc, S/V = 1.0 cm<sup>-1</sup>. The cell freshly coated by polymer was heated at 500°C and evacuated for ~ 16 hours before each run, unless stated otherwise.

\* This experiment was performed in a surface-active cell and the resulting high rates are not included in the order plots.



(cf. Appendix II). Since ethylene begins to decompose around  $500^{\circ}\text{C}$ <sup>76</sup>, experiments performed in the presence of ethylene were carried out at lower temperatures (440 and  $460^{\circ}\text{C}$ ), and at relatively low concentrations of ethylene.

The rate data for  $\text{H}_2$  and TMDS from Tables IV-3 to IV-5 in the presence and absence of ethylene are plotted in Figure IV-2 in logarithmic form. The plots were linear at all temperatures and the orders of  $\text{H}_2$  and TMDS formation, determined by standard least mean square analyses of the slopes, are listed in Table IV-6.

The rate data for TMS and MMS formation in the absence of ethylene, Tables IV-3 to IV-5, are plotted logarithmically in Figures IV-3 and IV-4, and the orders, determined by standard least square analyses, and listed in Table IV-6, are approximately 2.0 .

## B. Discussion

### 1. Comparison of the Pyrolysis of DMS and MMS: Similarities and Differences

When comparing the overall thermal behavior of dimethylsilane (DMS) with that of monomethylsilane (MMS) one can notice that some striking similarities are apparent. In both cases, hydrogen and substituted disilane (TMDS, DMDS) were the major products, and the minor products were



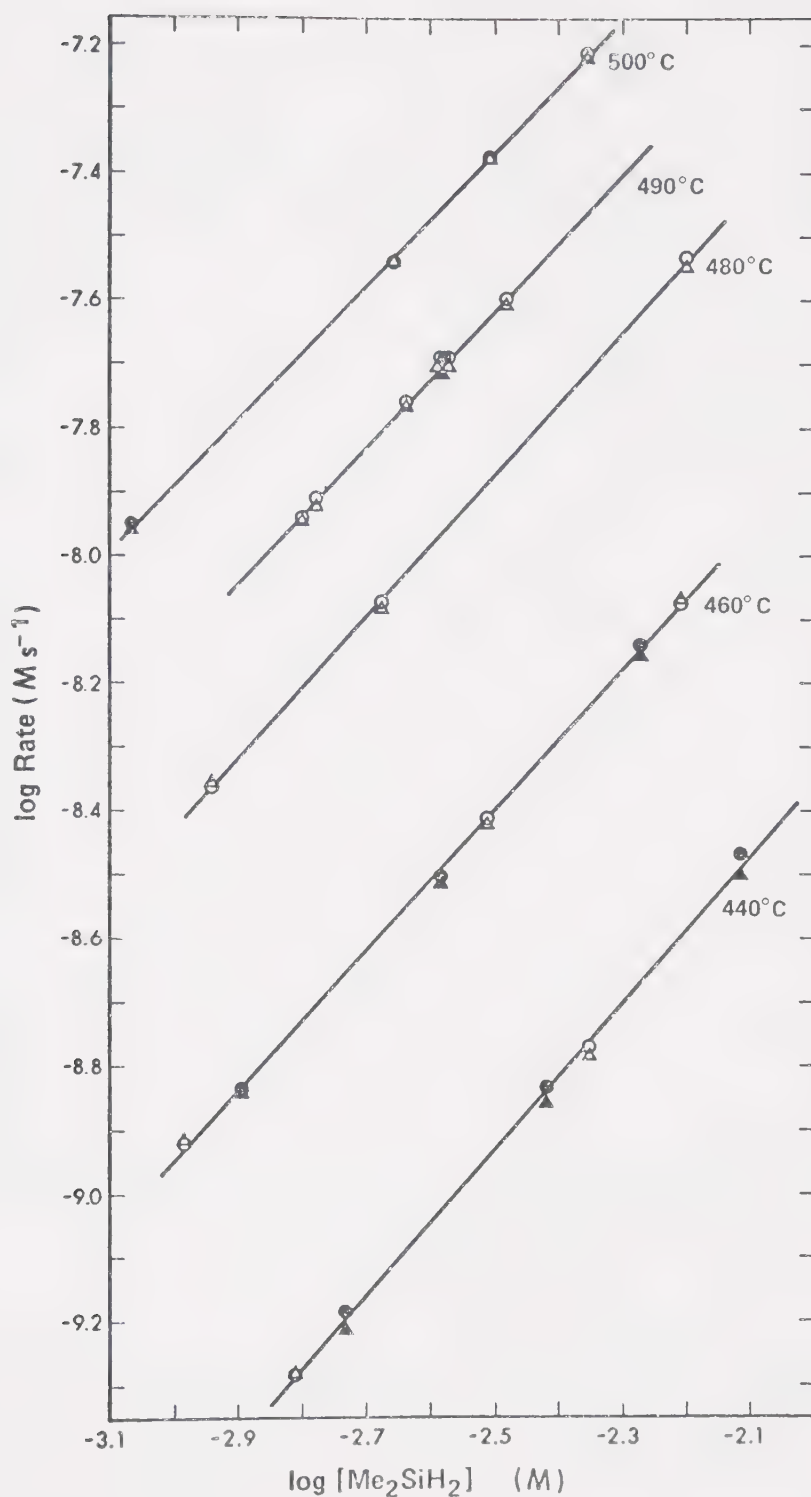


Figure IV-2. Order Plots for  $\text{H}_2$  and TMS Formation in the Pyrolysis of  $\text{Me}_2\text{SiH}_2$  at Different Temperatures.  
 ○ -  $\text{H}_2$ , △ - TMS in the Absence of Ethylene;  
 ● -  $\text{H}_2$ , ▲ - TMS in the Presence of Ethylene.



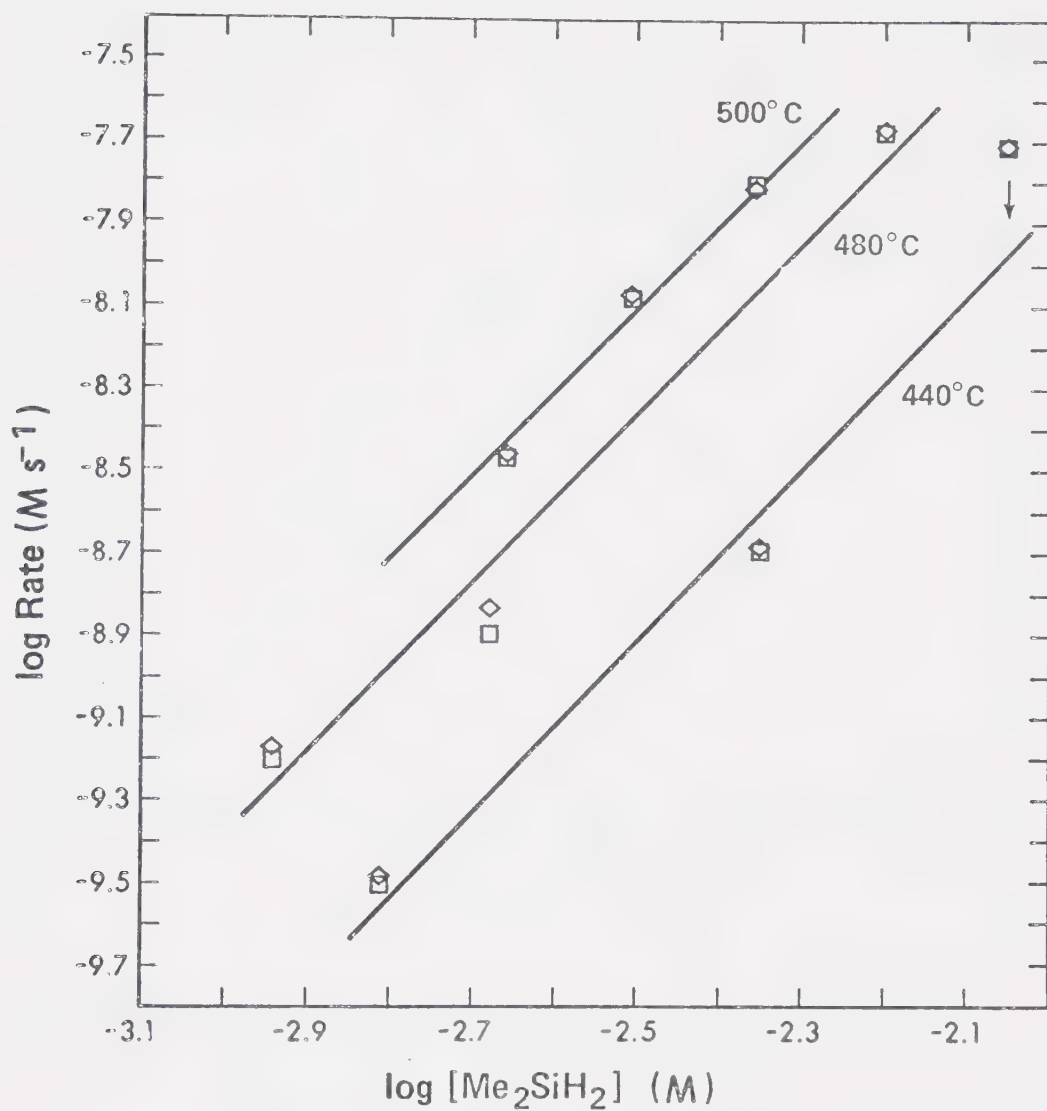


Figure IV-3. Order Plots for TMS and MMS Formation in the Pyrolysis of  $\text{Me}_2\text{SiH}_2$  in the Absence of Ethylene at 440, 480 and 500°C.

◇ - TMS, □ - MMS.





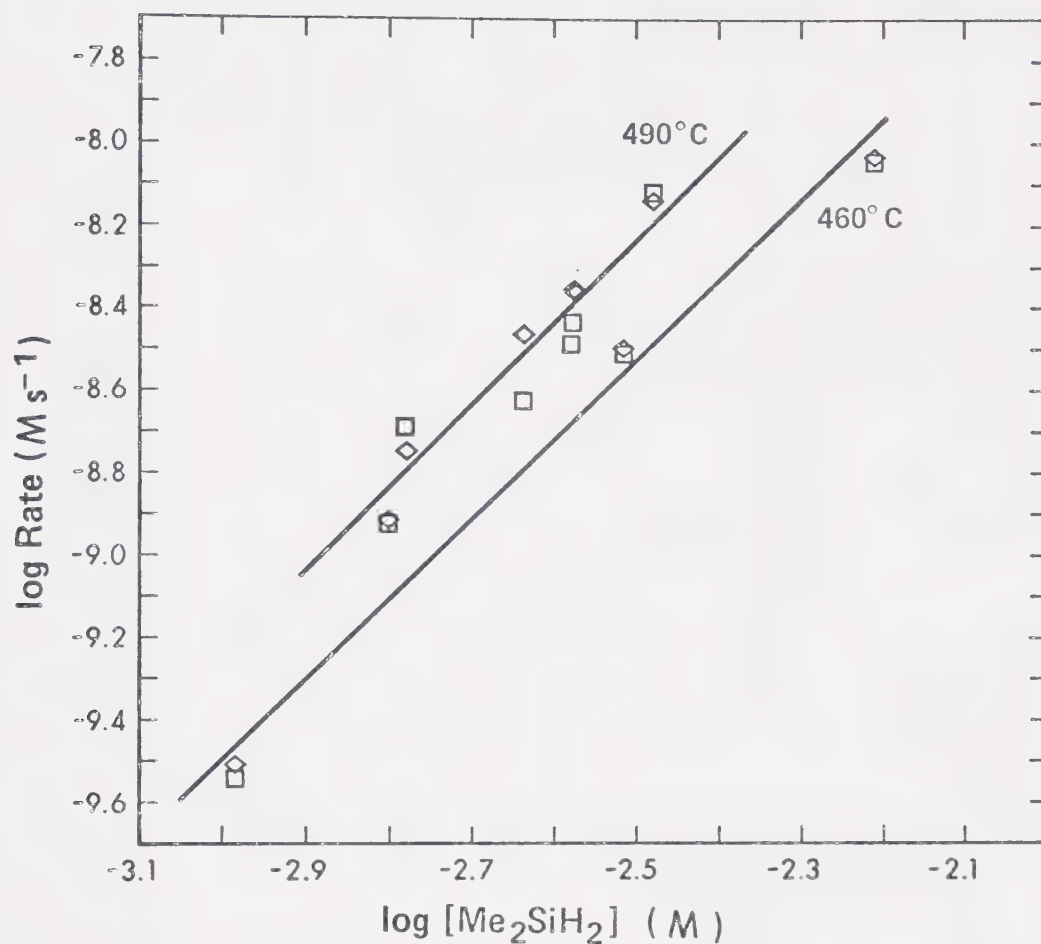


Figure IV-4. Order Plots for TMS and MMS Formation in the Pyrolysis of Me<sub>2</sub>SiH<sub>2</sub> in the Absence of Ethylene at 460 and 490°C.

◇ - TMS, □ - MMS.



TABLE IV-6  
Reaction Orders for Product Formation in the Pyrolysis of  
Dimethylsilane at Different Temperatures

Temperature, °C	Order <sup>a</sup>					
	H <sub>2</sub> <sup>b</sup>	TMDS	b	TMS <sup>c</sup>	MMS <sup>c</sup>	c
500.0	1.04+0.01	(4)	1.05+0.01	(4)	2.15+0.25	(3) 2.20+0.22 (3)
490.0	1.08+0.02	(7)	1.05+0.01	(7)	2.27+0.16	(6) 2.00+0.39 (6)
480.0	1.12+0.01	(3)	1.10+0.02	(3)	2.07+0.31	(3) 2.12+0.37 (3)
460.0	1.11+0.01	(6)	1.10+0.02	(6)	1.94+0.16	(3) 1.97+0.18 (3)
440.0	1.16+0.02	(5)	1.13+0.02	(5)	1.73	(2) 1.77 (2)

<sup>a</sup> The number of experimental points is given in parentheses.

<sup>b</sup> Based on experimental data (in Tables IV-3 to IV-5) both in the presence and absence of ethylene.

<sup>c</sup> Using the experiments in the absence of ethylene only.



two silanes which differed by one methyl group from the substrate molecules, i.e.  $\text{Me}_3\text{SiH}$  and  $\text{MeSiH}_3$  from  $\text{Me}_2\text{SiH}_2$  and  $\text{Me}_2\text{SiH}_2$  and  $\text{SiH}_4$  from  $\text{MeSiH}_3$ . Methane was a negligible reaction product in both cases, which indicated that the splitting of the Si-C bond was not an important primary step.

In the pyrolyses of MMS and DMS, the reaction rates, particularly those of the minor products, were affected by the nature of the surface, especially by the extent of polymer deposition. Finally, in both cases, the minor products were strongly affected by the addition of ethylene and this suggests that silyl radicals are present in the DMS system as well, and participate in the formation of the minor products. It would appear therefore that the thermal decompositions of MMS and DMS proceed by similar reaction mechanisms.

Some important differences in the pyrolysis of DMS however, should be noted:

#### (i) Different Thermal Stability

At  $440^\circ\text{C}$ , the rate of decomposition was slower by more than two orders of magnitude than in the pyrolysis of MMS. Thus, assuming that the reaction mechanism is similar to that of MMS, one or more of the rate determining steps in the pyrolysis of DMS must have either



a higher activation energy or lower A-factor (or both) than the corresponding reactions in the pyrolysis of MMS.

## (ii) Effect of Added Ethylene

Whereas  $C_2H_4$  affected the rates of formation of all the products formed in the pyrolysis of MMS (cf. Figure III-9 , and Table III-15 ), it does not seem to have any significant effect on the rates of  $H_2$  and TMS formation in the pyrolysis of DMS (cf. Figure IV-2).

Assuming that the reaction mechanisms for the pyrolyses of DMS and MMS are formally similar, these results seem to indicate that:

(a) in the pyrolysis of DMS the contribution of the radical process to the yields of the major products is less important than it was in the case of MMS, i.e., the length of the radical chain by which these products might be formed must be much shorter.

(b) at the highest ethylene concentrations used, 9%, some TMS and MMS are still formed whereas in the case of MMS, under the same conditions, the minor product DMS is completely suppressed. Assuming that TMS and MMS are also formed by silyl radical precursors, ethylene must scavenge dimethylsilyl radicals much less efficiently than methylsilyl radicals. In fact, the rate of addition





of silyl radicals to ethylene has been reported to decrease with increasing methylation of the silicon atom <sup>40</sup> .

The higher reaction temperatures used in the DMS pyrolysis may have also decreased the scavenging ability of ethylene.

### (iii) The Reaction Orders

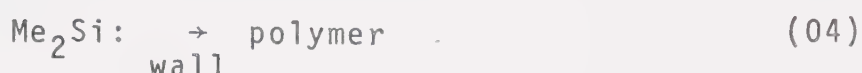
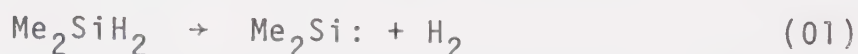
The reaction orders for the radical yields in the pyrolysis of MMS were between 1.5 and 2.0 and it was concluded that both linear and quadratic termination of the chain was occurring. In the case of DMS, however, the orders for the apparent radical products, TMS and MMS, are  $\sim 2.0$  indicating that only a linear chain termination may be operative.

Since the orders of  $H_2$  and TMDS in the pyrolysis of DMS were slightly higher than unity (see Table IV-6), some contribution from the radical process to the yields of these major products has to be considered, in spite of the fact that there was no apparent suppression of the yields in the presence of ethylene. The following reaction scheme can now be suggested for the pyrolysis of DMS.

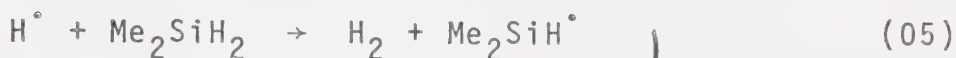


## 2. Reaction Scheme for the Pyrolysis of Dimethylsilane

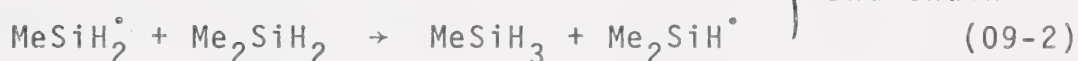
### Molecular:



### Radical:



} 1st chain



} 2nd chain

This reaction scheme is formally similar to that of MMS, except that only linear heterogeneous termination of the chain and two types of propagation chains are assumed to take place. The first is propagated by reactions (05) and (06) and leads to the formation of  $\text{H}_2$  and TMS, and the second chain, propagated by (09-1) and (09-2) is responsible for the formation of the minor products, TMS and MMS. Although there is some evidence



that the metathetical reaction step,



is heterogeneous, further studies would be required to define the nature of this reaction.

### 3. Determination of the Rate Constants for the Molecular and Radical Processes in the Pyrolysis of DMS

Steady-state treatment of the reaction sequence (01)-(09) yields the following rate expressions:

$$R(\text{H}_2) = (k_{01} + k_{02})[\text{DMS}] + k_{06} \frac{2k_{02}}{k_{08}} [\text{DMS}]^2 \quad (10)$$

$$R(\text{TMDS}) = k_{01}[\text{DMS}] + k_{06} \frac{2k_{02}}{k_{08}} [\text{DMS}]^2 - R(\text{Polymer}) \quad (11)$$

$$R(\text{TMS}) = k_{09-1} \frac{2k_{02}}{k_{08}} [\text{DMS}]^2 \quad (12)$$

$$R(\text{MMS}) = k_{09-1} \frac{2k_{02}}{k_{08}} [\text{DMS}]^2 \quad (13)$$

Formally, these rate expressions resemble those for  $\text{H}_2$  and DMDS in the pyrolysis of MMS for the case of linear termination of the chain. The rate expression for TMDS, e.g. (11), is similar to that for  $\text{H}_2$ , eq. (10), but contains one additional term,  $R(\text{Polymer})$ . However, since the rates of formation of  $\text{H}_2$  and of TMDS were essentially the same (cf. Tables IV-3 to IV-5 and Figure IV-2), the



formation of polymer in the pyrolysis of DMS at low conversions must be very minor and this term can therefore be neglected. The coefficient of the first order term in eq. (11) contains only the rate constant  $k_{01}$ . This is a consequence of the fact that the chain termination step, reaction (08)



was assumed not to produce any significant TMDS.

The reaction orders for  $\text{H}_2$  and TMDS formation were very close to unity (cf. Table IV-6), and thus the relative contribution of the first order terms in rate expressions (10) and (11) must be considerably more important than that of the second order terms.

The reaction scheme predicts that the rates of TMS and MMS formation should be the same, and be second order with respect to the substrate. Experimentally, the reaction orders for both products were  $\sim 2.0$  but the yields of MMS were always somewhat lower than those of TMS. However, thermal decomposition of MMS is certain to take place at the temperatures used in this study and this could explain the smaller yields. Hence the data on TMS will be used for the following kinetic treatments.

Since  $R(\text{polymer})$  in eq. (11) can be neglected, equations (10)-(12) can be rearranged to give:





$$\frac{R(H_2)}{[DMS]} = (k_{01} + k_{02}) + k_{06} \frac{2k_{02}}{k_{08}} [DMS] \quad (14)$$

$$\frac{R(TMDS)}{[DMS]} = k_{01} + k_{06} \frac{2k_{02}}{k_{08}} [DMS] \quad (15)$$

$$\frac{R(TMS)}{[DMS]} = k_{09-1} \frac{2k_{02}}{k_{08}} [DMS] \quad (16)$$

The kinetic plots of equations (14) and (15), using the rate data for  $H_2$  and TMDS both in the presence and absence of ethylene given in Tables IV-3 to IV-5 (excluding those denoted by asterisks) are shown in Figure IV-5.

The plots are linear and the first and second order coefficients at different temperatures, determined from the intercepts and slopes, respectively, are listed in Tables IV-7 and IV-8. From Table IV-7,  $k_{01} + k_{02} \approx k_{01}$  and therefore the radical contribution to the  $H_2$  and TMDS yields must be very small.  $k_{02}$  will henceforth be neglected in the first order coefficient term.

There is an alternative and probably more accurate method for evaluating these rate constant ratios.

It will be recalled (cf. Section III.B.4.iv) that in the pyrolysis of MMS, there is a good correlation between the rates of formation of the products formed in the radical process, i.e.  $DMS$ ,  $H_{2,Rad}$  and  $DMDS_{Rad}$  and that this correlation is actually predicted by the reaction mechanism. A similar correlation between the minor



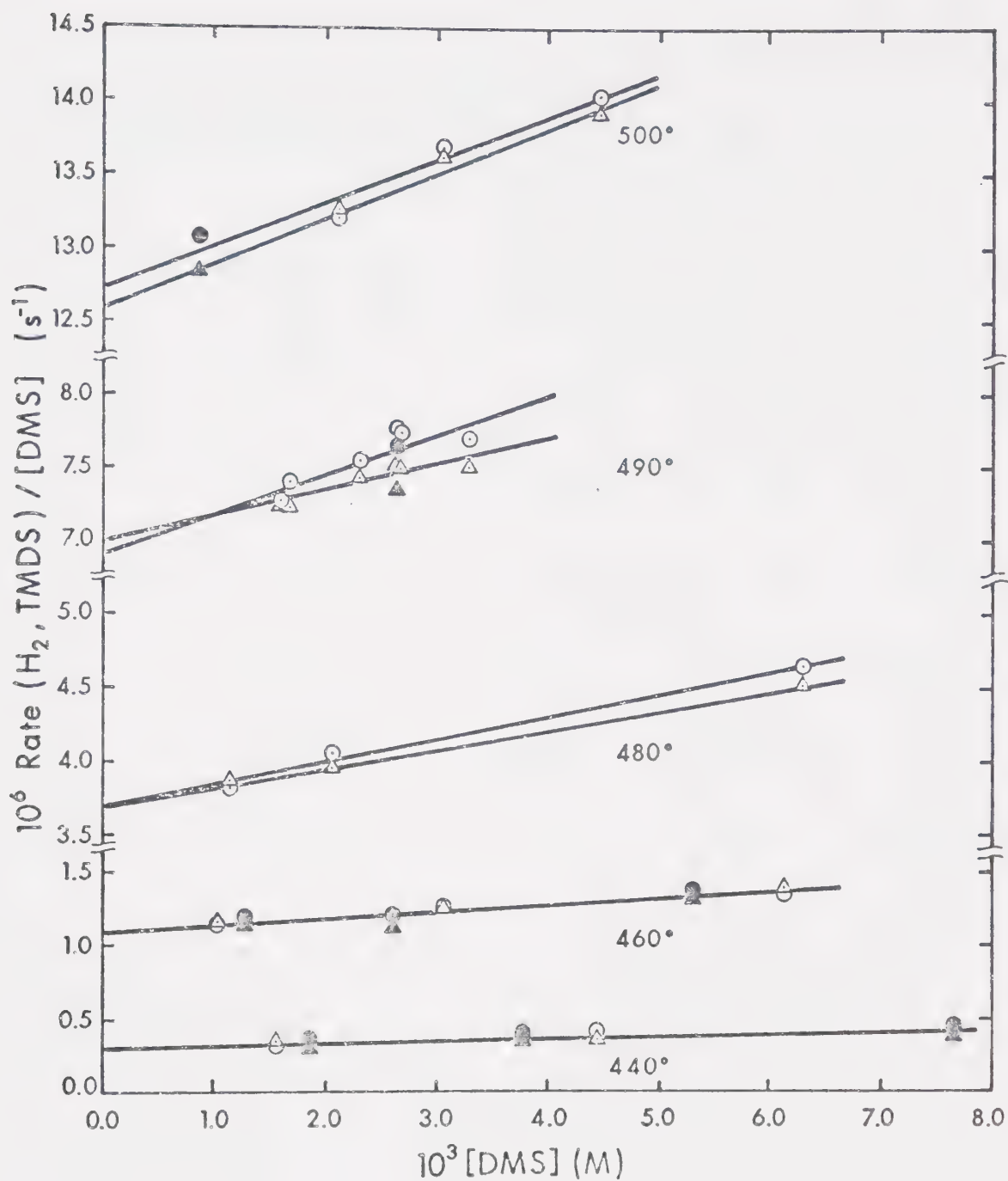


Figure IV-5. Plots of Equations (14) and (15) at Different Temperatures.

○, ● -Rate (H<sub>2</sub>)/[DMS] *versus* [DMS];  
 △, ▲ -Rate (TMS)/[DMS] *versus* [DMS].  
 The Closed Symbols (●, ▲) Refer to  
 Experiments in the Presence of Ethylene.



TABLE IV-7  
First Order Rate Constants <sup>a</sup> for H<sub>2</sub> and TMDS Formation  
in the Pyrolysis of DMS

Temp., °C	First Order Rate Coefficients, s <sup>-1</sup>			
	(k <sub>01</sub> +k <sub>02</sub> ) H <sub>2</sub> <sup>b</sup>	(k <sub>01</sub> ) TMDS <sup>c</sup>	(k <sub>01</sub> ) H <sub>2</sub> <sup>d</sup>	(k <sub>01</sub> ) TMDS <sup>e</sup>
500	1.3x10 <sup>-5</sup>	1.3x10 <sup>-5</sup>	1.3x10 <sup>-5</sup>	1.3x10 <sup>-5</sup>
490	7.0x10 <sup>-6</sup>	7.0x10 <sup>-6</sup>	7.2x10 <sup>-6</sup>	7.0x10 <sup>-6</sup>
480	3.7x10 <sup>-6</sup>	3.7x10 <sup>-6</sup>	3.8x10 <sup>-6</sup>	3.8x10 <sup>-6</sup>
460	1.1x10 <sup>-6</sup>	1.1x10 <sup>-6</sup>	1.1x10 <sup>-6</sup>	1.1x10 <sup>-6</sup>
440	3.1x10 <sup>-7</sup>	3.1x10 <sup>-7</sup>	3.1x10 <sup>-7</sup>	3.1x10 <sup>-7</sup>

<sup>a</sup> Since few points were available, error limits are not quoted.

<sup>b</sup> From equation (14), Figure IV-5.

<sup>c</sup> From equation (15), Figure IV-5.

<sup>d</sup> From equation (17), Figure IV-6.

<sup>e</sup> From equation (18), Figure IV-6.



TABLE IV-8  
Rate Constant Ratios  $k_{06}^{2k_{02}}/k_{08}$ , for  $H_2$  and TMDS  
Formation by the Radical Process in the Pyrolysis  
of DMS at Different Temperatures <sup>a</sup>

Temperature, °C	$k_{06} \frac{2k_{02}}{k_{08}}, M^{-1}s^{-1}$	
	$H_2$ <sup>b</sup>	TMDS <sup>c</sup>
500.0	$2.9 \times 10^{-4}$	$3.1 \times 10^{-4}$
490.0	$2.7 \times 10^{-4}$	$1.6 \times 10^{-4}$
480.0	$1.6 \times 10^{-4}$	$1.3 \times 10^{-4}$
460.0	$4.7 \times 10^{-5}$	$4.5 \times 10^{-5}$
440.0	$1.8 \times 10^{-5}$	$1.3 \times 10^{-5}$

<sup>a</sup> Error limits are not quoted since few points were available.

<sup>b</sup> Slope of the plot of eq (14).

<sup>c</sup> Slope of the plot of eq (15).





products TMS and MMS and  $H_{2, \text{Rad}}$  and  $\text{TMDs}_{\text{Rad}}$  is also predicted by the proposed mechanism for the pyrolysis of DMS. Thus substitution of eq. (16) into (14) and (15) yields

$$\frac{R(H_2)}{[DMS]} = k_{01} + \frac{k_{06}}{k_{09-1}} \frac{R(TMS)}{[DMS]} \quad (17)$$

$$\frac{R(TMDs)}{[DMS]} = k_{01} + \frac{k_{06}}{k_{09-1}} \frac{R(TMS)}{[DMS]} \quad (18)$$

The plots of equations (17) and (18), using the data in Tables IV-3 to IV-5 (in the absence of ethylene) are illustrated in Figure IV-6; significantly, even the abnormally high rate data denoted by an asterisk in Tables IV-3 and IV-5 could be included in these plots. The rate data derived from the slopes and intercepts are listed in Table IV-7 and IV-9, respectively. The results are in good agreement with those derived from the slopes and intercepts of equations (14) and (15) and thus support the proposed mechanism.



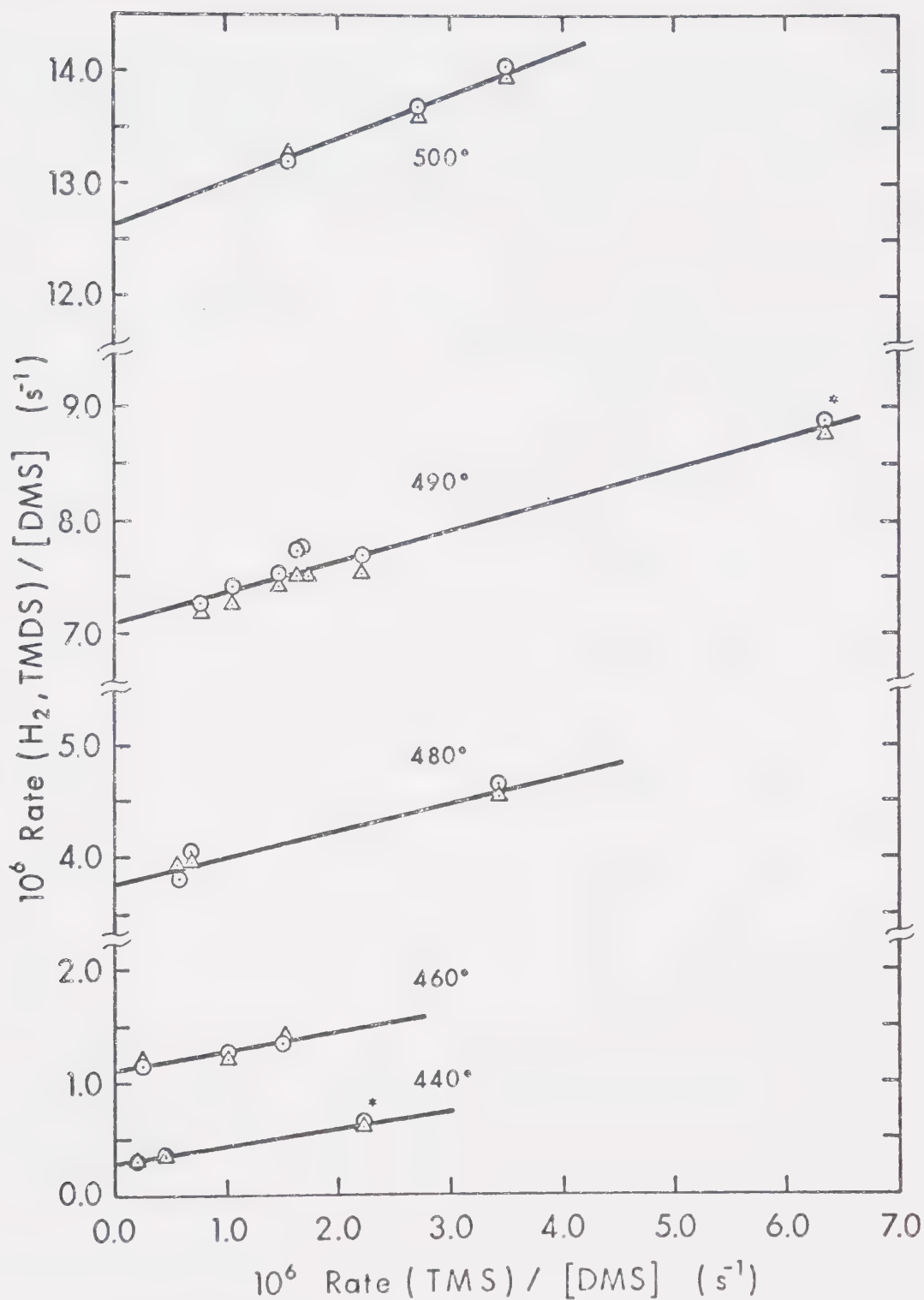


Figure IV-6. Plots of Equations (17) and (18) at Different Temperatures.  
 ○ -Rate (H<sub>2</sub>)/[DMS] *versus* Rate(TMS)/[DMS]  
 △ -Rate (TMDS)/[DMS] *versus* Rate(TMS)/[DMS]  
 \* -Experiments in the "surface-active" cell (cf. Tables IV-4 and IV-5).



TABLE IV-9  
Rate Constant Ratios <sup>a</sup>  $k_{06}/k_{09-1}$  for H<sub>2</sub> and TMDS Formation  
by the Radical Process in the Pyrolysis of DMS  
at Different Temperatures

Temperature, °C	Rate Constant Ratio $k_{06}/k_{09-1}$	
	H <sub>2</sub> <sup>b</sup>	TMDS <sup>c</sup>
500	0.42	0.34
490	0.27	0.27
480	0.26	0.22
460	0.17	0.18
440	0.16	0.14

<sup>a</sup> Error limits are not quoted since few points were available.

<sup>b</sup> Slope of the plot of eq. (17).

<sup>c</sup> Slope of the plot of eq. (18).



#### 4. Arrhenius Parameters for the Molecular and Radical Processes in the Pyrolysis of Dimethylsilane

##### (i) Molecular Process

The first order rate constant  $k_{01}$  has been derived from four kinetic plots using two slightly different methods of treating the experimental data. All four values, listed in Table IV-7, are in excellent agreement at all temperatures and are plotted in the Arrhenius form in Figure IV-7. From the intercept and slope,

$$\log k_{01} \text{ (s}^{-1}\text{)} = 14.3 - (68,000)/2.3 \text{ RT} \quad ,$$

with estimated errors of

$$\Delta \log k_{01} \text{ (s}^{-1}\text{)} = \pm 0.3 \pm (1,000)/2.3 \text{ RT}$$

The activation energy and the A-factor for reaction (01) are higher and lower, respectively, than the corresponding values in the pyrolysis of MMS, 63.2 kcal/mol and  $10^{15.0} \text{ s}^{-1}$ , which is in agreement with the higher thermal stability of DMS (vide supra).

##### (ii) Radical Process

The rate constant ratios  $k_{06}/k_{09-1}$  and  $k_{06}$  ( $2k_{02}/k_{08}$ ) obtained by different kinetic treatments are





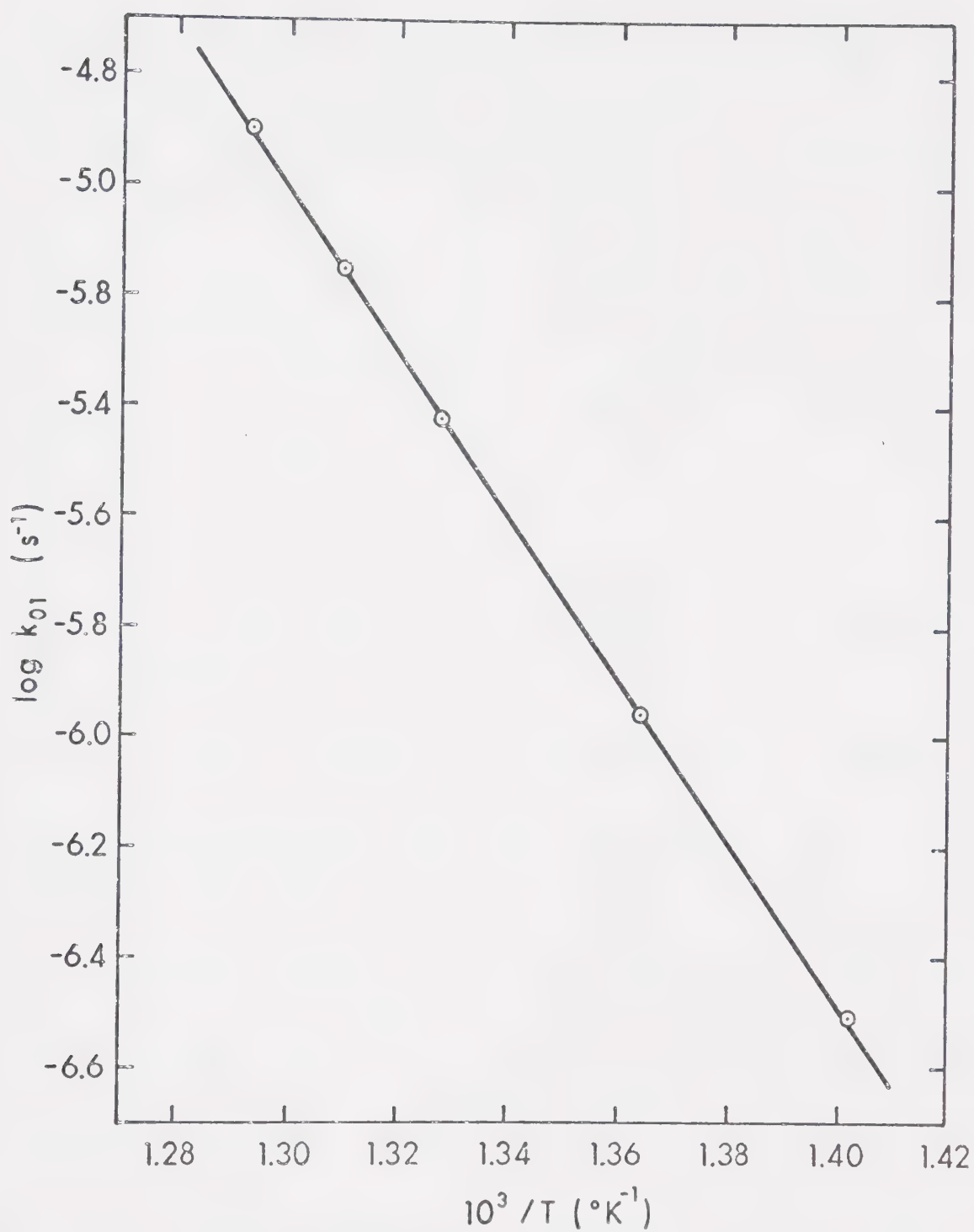


Figure IV-7. Arrhenius Plot for the First Order Rate Constant  $k_{01}$  .



given in Tables IV-8 and IV-9, and the corresponding Arrhenius plots are shown in Figures IV-8 and IV-9. The plots are reasonably linear but there is considerable scatter which, however, is not surprising in view of the fact that the radical process is largely heterogeneous and relatively few experimental points could be used.

The apparent Arrhenius parameters for the radical process are given in Table IV-10.

Thus  $E_{06} - E_{09-1} = 16 \pm 2$  kcal/mol, which indicates that the reaction



requires a considerably high activation energy in comparison with that of reaction (09-1)



It may be noted that  $E_a$  for the analogous reaction involving methylsilyl radicals



has been estimated to be 13-15 kcal/mol (cf. Section III.B.3.ii.b). If abstraction of a methyl group by



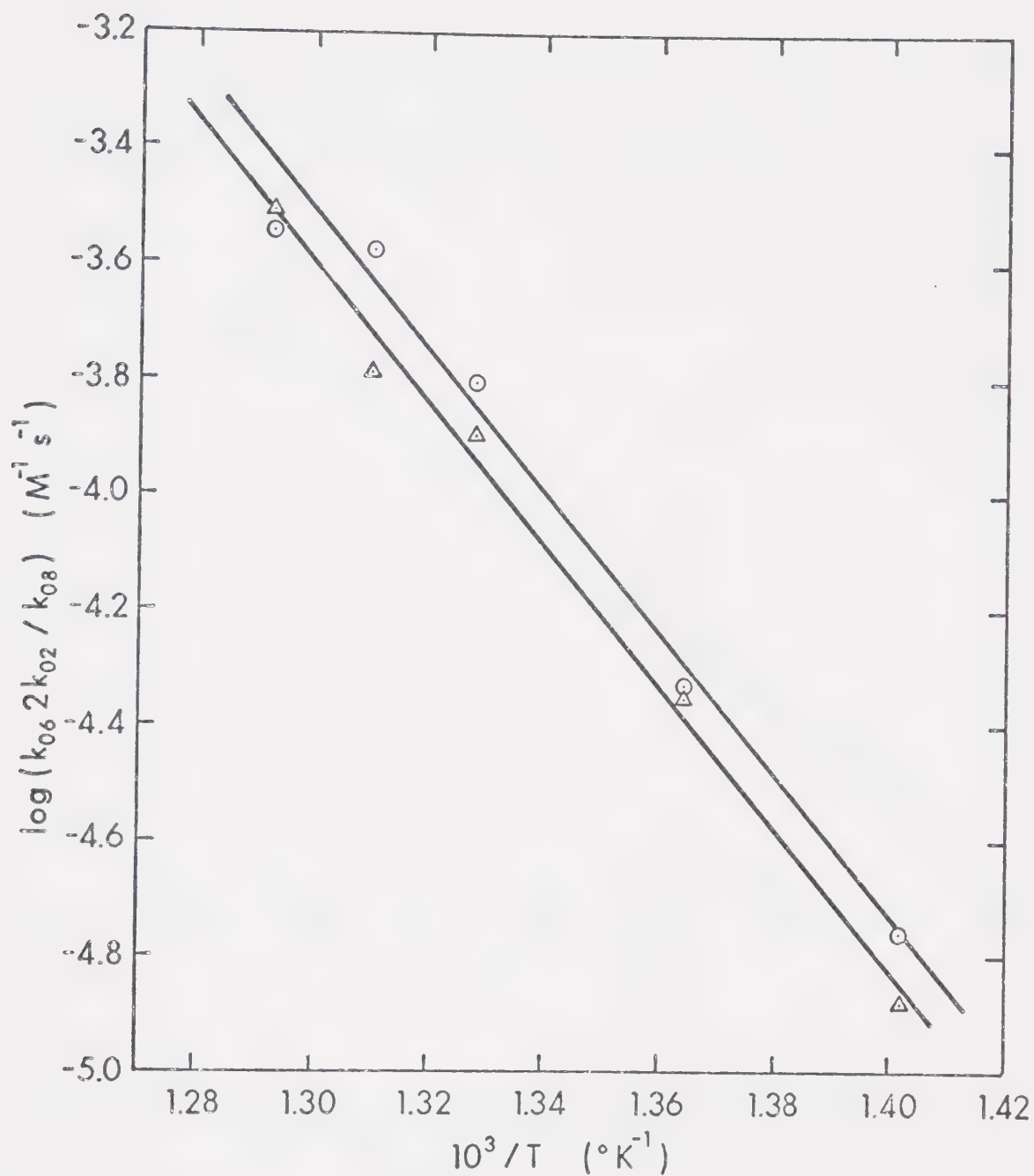


Figure IV-8. Arrhenius Plots for the Rate Constant Ratio  $k_{06}(2k_{02}/k_{08})$ , based on  $\text{H}_2$ , ( $\odot$ ), and TMS, ( $\triangle$ ) Formation in the Pyrolysis of DMS.



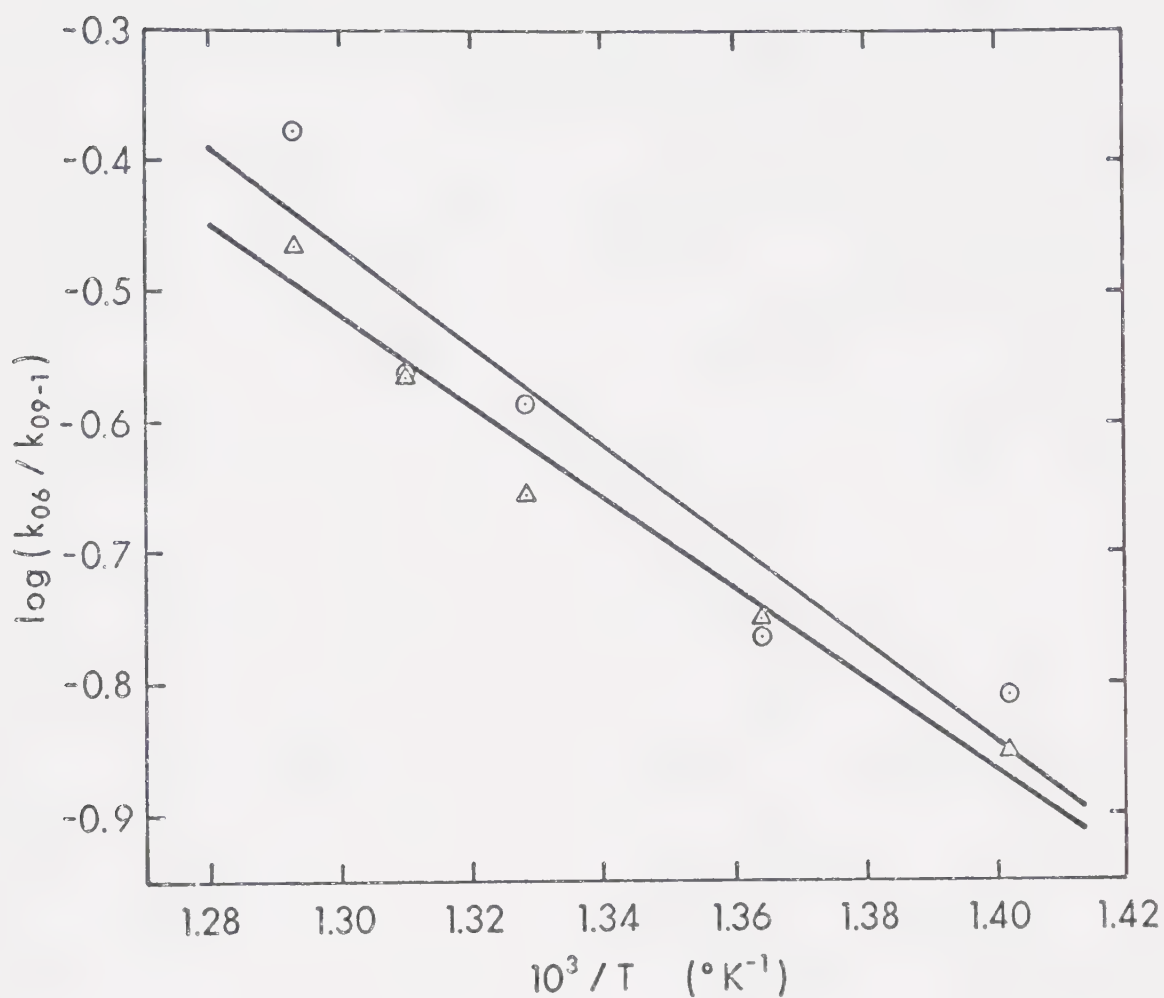


Figure IV-9. Arrhenius Plots for the Rate Constant Ratio  $k_{06}/k_{09-1}$ , based on  $\text{H}_2$ , ( $\odot$ ), and TMS, ( $\Delta$ ) Formation in the Pyrolysis of DMS.





TABLE IV-10  
Arrhenius Parameters for the Rate Constant  
Ratios of the Radical Process in the  
Pyrolysis of DMS

Rate Constant Ratio	log A	E <sub>a</sub> , kcal/mol
$(k_{06}/k_{09-1})_{H_2}^a$	4.4±1.1	17.0±3.5
$(k_{06}/k_{09-1})_{TMDS}^b$	3.9±0.5	15.6±1.7
$\{k_{06}(2k_{02}/k_{08})\}_{H_2}^c$	12.0±1.2 <sup>e</sup>	54.6±4.2
$\{k_{06}(2k_{02}/k_{08})\}_{TMDS}^d$	12.4±0.8 <sup>e</sup>	56.2±2.8

<sup>a</sup> Slope of the plot of eq. (17).

<sup>b</sup> Slope of the plot of eq. (18).

<sup>c</sup> Slope of the plot of eq. (14).

<sup>d</sup> Slope of the plot of eq. (15).

<sup>e</sup> A is in units of M<sup>-1</sup>s<sup>-1</sup>.



a dimethylsilyl radical is heterogeneous then  $E_{09-1}$  might indeed be very small. In any case  $E_{06}$  will be at least 16-20 kcal/mol, and could in fact be much higher.

Since  $E_{06}$  is relatively high and since reaction (06) is a chain propagating step, it follows that the chain length must be shorter than that in the case of MMS and consequently  $R(H_2)_{Rad}$  and  $R(TMDS)_{Rad}$  will not contribute very much to the overall rates. This may explain, at least partly, why ethylene has no observable effect on the  $H_2$  and TMDS yields.

From the data in Table IV-10,

$$E_{06} + E_{02} - E_{08} \approx 55 \text{ kcal/mol}.$$

Since  $E_{06} \geq 16 \text{ kcal/mol}$  and the activation energy  $E_{08}$  for the heterogeneous chain termination reaction



is probably very small and can be neglected in comparison with  $E_{02}$  and  $E_{06}$ , the activation energy  $E_{02}$  for the chain initiation step



can be estimated to be

$$E_{02} \leq 39 \text{ kcal/mol}$$

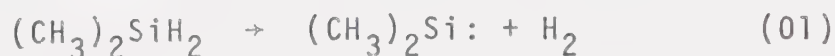


Since the first bond dissociation energy in dimethylsilane,  $D(\text{Me}_2\text{SiH-H})$ , is very close or equal to that of  $D(\text{MeSiH}_2\text{-H}) \sim 90 \text{ kcal/mol}$  (cf. Section III.B.5.i) it must be concluded that the primary reaction step (02) is heterogeneous, just as in the pyrolysis of MMS.

It is significant that the data from experiments performed in a highly surface active vessel could be incorporated in the linear plots of eqs (17) and (18), Figure IV-6. It would appear therefore that wall effects are compensated for in this particular kinetic treatment. Further, more detailed experiments should be very instructive in the elucidation of the nature of these radical processes.

##### 5. Some thermochemical Implications of the Arrhenius Parameters for the Molecular Process

It has been shown that  $k_{01} \gg k_{02}$  and therefore the Arrhenius coefficients  $E_a = 68.0 \text{ kcal/mol}$  and  $\log A(\text{s}^{-1}) = 14.3$ , refer to the primary molecular step,





## (i) Activation Energy

Assuming that the activation energy for the reverse reaction (-01) is approximately 8 kcal/mol (i.e. the same as that estimated for the analogous reaction  $\text{CH}_3\text{SiH:} + \text{H}_2$ , see Section III.B.5.i), the enthalpy change for reaction (01),  $\Delta H_{01}^0$ , will be:

$$\Delta H_{01}^0 = E_{01} - E_{-01} = 68 - 8 = 60 \text{ kcal/mol}$$

Since

$$\Delta H_{01}^0 = \Delta H_f^0(\text{Me}_2\text{Si:}) - \Delta H_f^0(\text{Me}_2\text{SiH}_2) + \Delta H_f^0(\text{H}_2)$$

and  $\Delta H_f^0(\text{Me}_2\text{SiH}_2)$  is approximately  $-16 \pm 1$  kcal/mol<sup>13,14</sup>,

$$\Delta H_f^0(\text{Me}_2\text{Si:}) \approx 44 \text{ kcal/mol} ;$$

this value is considerably higher than earlier estimates, e.g. 33<sup>17</sup>, 29<sup>112</sup>, and 16 kcal/mol<sup>27</sup>. Even though the estimated activation energy  $E_{-01}$  used in the calculation of the reaction enthalpy  $\Delta H_{01}^0$  may be somewhat higher than 8 kcal/mol, it is unlikely to be as high as 36 kcal/mol, implied in the low value of 16 kcal/mol for  $\Delta H_f^0(\text{Me}_2\text{Si:})$ .

$\Delta H_{01}^0$  is related to the bond dissociation energies by





$$\Delta H_{01}^0 = D(\text{Me}_2\text{SiH-H}) + D(\text{Me}_2\text{Si-H}) - D(\text{H-H})$$

and since  $D(\text{H-H}) = 104 \text{ kcal/mol}$ <sup>108</sup> and  $D(\text{Me}_2\text{SiH-H}) \approx 90 \text{ kcal/mol}$ , the second bond dissociation energy  $D(\text{Me}_2\text{Si-H})$  is  $D(\text{Me}_2\text{Si-H}) = 104+60-90 = 74 \text{ kcal/mol}$ . This is lower by approximately 16 kcal/mol than the first BDE, and is about 5 kcal/mol higher than the corresponding second BDE in MMS ( $D(\text{MeSiH-H}) \sim 69 \text{ kcal/mol}$ , cf. Section III.B.5.i).

Since the first BDEs in MMS and DMS are identical, it would therefore appear that the differences in the activation energies of the molecular processes occurring in the pyrolyses of DMS and MMS, 68 and 63 kcal/mol, respectively, reflect the differences in the second (Si-H)BDEs.

It should be noted, however, that the activation energies for insertion of  $\text{Me}_2\text{Si:}$  and  $\text{MeSiH:}$  into  $\text{H}_2$  were assumed to be the same and this might not be the case. Thus if it is assumed, for example, that  $E_{-01} \sim 13 \text{ kcal/mol}$ , which is quite plausible, then the second BDEs (Si-H) in both compounds become identical and the observed differences in the activation energies  $E_{01}$  and  $E_1$  would simply reflect the differences in  $E_{-01}$  and  $E_{-1}$ .



## (ii) The Preexponential Factor

The A factor for reaction (01),  $A_{01} = 10^{14.3} \text{ s}^{-1}$ , can be used to calculate the entropy of activation,  $\Delta S_{01}^\ddagger$  from the relation

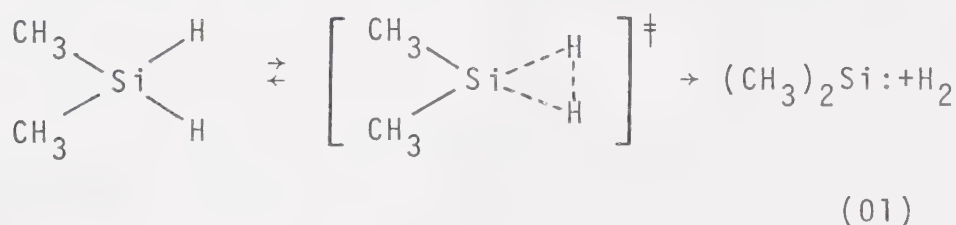
$$A_{01} = \left( \frac{ekT}{h} \right) e^{\Delta S_{01}^\ddagger / R} \quad (19)$$

Thus, at the mean reaction temperature,  $460^\circ\text{C}$ ,

$$\Delta S_{01}^\ddagger = 3.15 \text{ e.u.}$$

indicating a somewhat more rigid transition state than in the case of MMS.

By analogy with the primary molecular reaction (1) in the pyrolysis of MMS, reaction (01) is assumed to proceed via a three-centered cyclic transition state,



and the activation entropy  $\Delta S_{01}^\ddagger$  can be calculated in the same manner as before for MMS (cf. Section III.B.5.ii).



Again, since  $\Delta S_{\text{tran}}^\ddagger$  and  $\Delta S_{\text{elec}}^\ddagger$  are zero and  $\Delta S_{\text{rot}}^\ddagger \approx 0$  (no change in symmetry numbers), the only significant contribution to  $\Delta S_{01}^\ddagger$  is expected to arise from  $\Delta S_{\text{vib}}^\ddagger$ , in particular from the changed stretching and bending frequencies of the Si-H bonds.

The calculation of  $\Delta S_{\text{vibs}}^\ddagger$  is shown in Table IV-11; the Si-H bond frequencies in DMS were taken from the literature<sup>113</sup>. The new frequencies for the transition state were estimated as

$$\omega_{\text{Si-H},\ddagger} \approx 2/3 \omega_{\text{Si-H,DMS}}$$

and the corresponding absolute vibrational entropies,  $S_{\text{DMS}}^0$ ,  $S_{\ddagger}^0$ , were calculated from Benson's tabulated data<sup>111</sup>.

From Table IV-11 is seen that the calculated activation entropy,

$$\Delta S_{01,\text{calc}}^\ddagger \approx \Delta S_{\text{vib}}^\ddagger = 3.1 \text{ e.u.}$$

is in excellent agreement with the experimental value of 3.15 e.u.



TABLE IV-11  
Estimated Contribution of the Si-H Vibrational Modes in Me<sub>2</sub>SiH<sub>2</sub> to the  
Entropy of Activation at 730°K

Mode Description	Frequency, cm <sup>-1</sup>		Vib. Entropy <sup>c</sup> , e.u.		$\Delta S^\ddagger_{\text{vib}}$ , e.u.
	DMS <sup>a</sup>	(DMS) <sup>†</sup> <sup>b</sup>	S <sup>o</sup> <sub>DMS</sub>	S <sup>o</sup> <sub>‡</sub>	
SiH <sub>2</sub> sym.str.	2150 →	R.C. <sup>d</sup>	0.2 →	0	-0.2
SiH <sub>2</sub> bend	950 →	630	1.0 →	1.7	+0.7
SiH <sub>2</sub> twist	600 →	400	1.8 →	2.6	+0.8
SiH <sub>2</sub> wag	900 →	600	1.1 →	1.8	+0.7
SiH <sub>2</sub> antisym.str.	2150 →	1430	0.2 →	0.5	+0.3
SiH <sub>2</sub> rock	470 →	313	2.2 →	3.0	+0.8
				Total	+3.1

<sup>a</sup> Taken from reference 113.  
<sup>b</sup> Estimated,  $\omega_{\ddagger} \approx \frac{2}{3}\omega_{\text{DMS}}$ .  
<sup>c</sup> Estimated from the tabulated data of Benson<sup>111</sup>.  
<sup>d</sup> Reaction coordinate.





It seems therefore very likely that the transition state leading to elimination of molecular hydrogen in the pyrolysis of DMS and MMS is a three-centered cyclic complex. This may also apply to the unimolecular decomposition of other silicon hydrides.



## CHAPTER V

### SUMMARY AND CONCLUSIONS

Between 340 and 440°C monomethylsilane pyrolyzes to form hydrogen and dimethyldisilane as major products and dimethylsilane and polymer as minor products. The orders of formation of  $H_2$  and DMDS vary between 1.1 at 441°C and 1.6 at 340°C. The rate of decomposition is strongly affected by the nature of the surface but relatively little by the surface to volume ratio of the reaction vessel.

In the presence of ~ 10% added ethylene the formation of hydrogen and dimethyldisilane is strongly suppressed and that of dimethylsilane is completely inhibited. The orders of formation of  $H_2$  and DMDS were both 1.0 at all temperatures. It is proposed that the  $H_2$  and DMDS yields formed under these conditions arise solely from a molecular process:

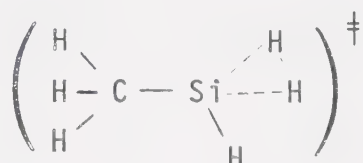


The kinetic data for  $H_2$  and DMDS yielded identical Arrhenius parameters, within experimental error:



$$\log k_1^{\text{molec}} (\text{s}^{-1}) = (14.95 \pm 0.11) - (63200 \pm 330)/(2.3RT)$$

The second bond dissociation energy in monomethylsilane is calculated to be 69 kcal/mol and  $\Delta H_f^0(\text{CH}_3\text{SiH:}) \approx 53$  kcal/mol. The entropy of activation is  $\Delta S_1^\ddagger = 6.3$  e.u.. Assuming a three-centered activated complex,

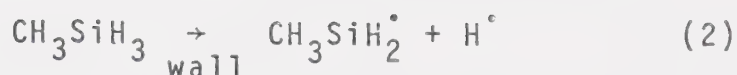


the individual contributions to  $\Delta S_1^\ddagger$  were estimated using established procedures and the close agreement between the calculated value, 6.1 e.u., and the experimental one supports the suggested structure.

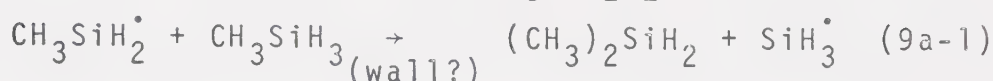
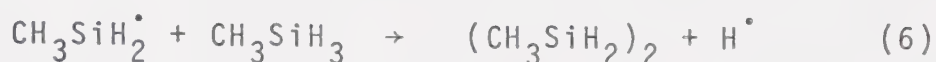
The molecular product yields calculated from  $k_1^{\text{molec}}$  were then subtracted from the total yields (in the absence of ethylene) to obtain the following reaction orders for the products formed in the radical process at 415°C: 1.6 ( $\text{H}_2$ ); 1.5 (DMDS) and 1.5 (DMS). These values are indicative of a radical chain mechanism which is proposed to consist of



## initiation



## propagation



## termination



The reaction sequence (1)-(9) cannot be solved since two types of chain termination steps are possible. Kinetic treatments performed for the two extreme cases of quadratic termination, i.e. reaction (7) and linear termination, (8) led to the following relations for  $R(\text{H}_2)$ :

$$\frac{R(\text{H}_2)_{\text{Total}}}{[\text{MMS}]} = (k_1 + k_2)^{\text{quad}} + \left\{ k_6 \left( \frac{k_2}{k_7} \right)^{\frac{1}{2}} \right\}^{\text{quad}} [\text{MMS}]^{\frac{1}{2}} \quad (\text{I})$$

$$\frac{R(\text{H}_2)_{\text{Total}}}{[\text{MMS}]} = (k_1 + k_2)^{\text{lin}} + \left\{ k_6 \frac{2k_2}{k_8} \right\}^{\text{lin}} [\text{MMS}] \quad (\text{II})$$

The experimental data obey the predicted linearity of these plots, from which it is concluded that  $(k_1 + k_2)^{\text{lin}} \sim (k_1 + k_2)^{\text{quad}} \sim k_1^{\text{molec}}$ . Thus  $k_1 \gg k_2$  and the second





terms in eqs ( I ) and (II) correspond solely to  $H_2$  formation by the radical process.

From the Arrhenius parameters of the second term coefficients for the radical process obtained from the slopes of the plots of eqs (I ) and (II) the following rate parameters can be estimated for the initiation reaction (2) for the two cases of quadratic and linear termination:

$$\log k_2^{\text{quad}} (s^{-1}) \approx 8 - (57,000)/(2.3RT)$$

$$\log k_2^{\text{lin}} (s^{-1}) \approx (? < 8) - (28,000)/(2.3RT)$$

Since the activation energy for each of these cases is much less than  $D(CH_3SiH_2-H)$  and the preexponential factors are several orders of magnitude less than the value  $10^{15 \pm 1} s^{-1}$  normally associated with a unimolecular homogeneous decomposition, it is concluded that the radical initiation step (2) is heterogeneous.

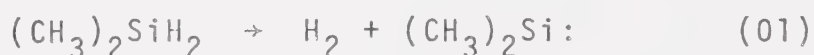
The chain length of the radical process is estimated to be  $\sim 10^6$  and the chain termination step (8) is probably heterogeneous. Most of the products arising from radical precursors are formed in the chain propagation reactions.

The results obtained from the pyrolysis of dimethylsilane are not as extensive but still allow meaningful conclusions. Dimethylsilane pyrolyses between



440 and 500°C to yield hydrogen and 1,1,2,2-tetramethyldisilane (TMDS) as major products and trimethylsilane (TMS), monomethylsilane (MMS) and polymer as minor products.

As in the case of monomethylsilane the rate of decomposition depends on the nature of the surface, but to a lesser degree. The orders of formation are  $\sim 1.1$  ( $H_2$ ),  $\sim 1.1$  (TMDS),  $\sim 2.0$  (TMS) and  $\sim 2.0$  (MMS). Ethylene has no apparent effect on the  $H_2$  and TMDS yields but those of the minor products TMS and MMS are strongly suppressed. A mechanism formally similar to that in the pyrolysis of monomethylsilane is proposed, consisting of two parallel molecular and radical processes. From the data on  $H_2$  and TMDS the following rate parameters were measured for the molecular primary step:



$$\log k_{01}(s^{-1}) = 14.3 - (68,000)/(2.3RT)$$

The second bond dissociation energy in dimethylsilane,  $\approx 74$  kcal/mol, is again considerably lower than the first and the calculated entropy of activation, 3.1 e.u., is in agreement with the experimentally observed value 3.2 e.u. when a three-centered transition state is assumed.  $\Delta H_f^0((CH_3)_2Si:)$  is estimated to be  $\sim 44$  kcal/mol. The radical component of the overall rate was estimated in a manner similar to the



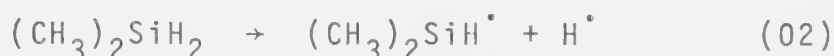
case of monomethylsilane. Since only linear termination of the chain is assumed to take place, kinetic treatment is simplified and leads to the relations

$$\frac{R(H_2)}{[DMS]} = (k_{01} + k_{02}) + k_{06} \frac{2k_{02}}{k_{08}} [DMS] \quad (III)$$

$$\frac{R(TMDS)}{[DMS]} = k_{01} + k_{06} \frac{2k_{02}}{k_{08}} [DMS] \quad (IV)$$

$$\frac{R(TMS)}{[DMS]} = \frac{R[MMS]}{[DMS]} = k_{09-1} \frac{2k_{02}}{k_{08}} [DMS] \quad (V)$$

where  $k_{02}$  refers to the radical initiation step



and the higher order rate constant terms refer to the chain propagation and termination steps. From the temperature dependence of these ratios it is concluded that  $E_{02} < 39$  kcal/mol and therefore reaction (02) is heterogeneous. Similarly to the case of monomethylsilane,  $k_{01} \gg k_{02}$ .

The radical chain length is several orders of magnitude less than that in the pyrolysis of monomethylsilane because one of the chain propagating steps features a relatively high activation energy.

These results are in excellent agreement with the earlier prediction that molecular decomposition of



silicon compounds becomes increasingly important as the energy available decreases. The use of ethylene as a silyl radical scavenger in thermal systems has demonstrated how the radical and molecular processes can be elucidated and how the notorious surface effects can be minimized. Caution must be exercised however since the yields of the major products from the pyrolysis of dimethylsilane were not suppressed by ethylene. Either ethylene cannot scavenge dimethylsilyl radicals, or, because of the shorter chain length, the radical yields of  $H_2$  and TMDS are very small. Further work is obviously necessary.

By analogy, it is highly probable therefore that monosilane,  $SiH_4$ , also decomposes by two independent molecular and radical processes and the present controversy in fact revolves around their relative importance. If the radical chain length is long, then the results often quoted (cf. Section I.A.6.ii) in support of radical initiation may be misleading since they tend to point to a highly overestimated importance for this reaction. The use of ethylene as a radical scavenger in this system should unambiguously resolve this problem.

Finally, it has been shown that heterogeneous reactions play a very important role in the pyrolysis of monomethyl- and dimethylsilane. In both cases the initial





Si-H cleavage is definitely heterogeneous and there is strong evidence that one or more of the chain terminating steps are heterogeneous as well. These reactions are responsible for the formation of the minor products which, in future work, might be suitable as monitors for heterogeneous processes.



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APPENDIX I  
MASS SPECTRUM OF METHYLETHYLSILANE

m/e	Relative Intensity <sup>a</sup>	Postulated Ion
74	18	$\text{MeEtSiH}_2^+$
73	45	$\text{MeEtSiH}^+$
72	54	$\text{MeEtSi}^+$
59	23	$\text{EtSiH}_2^+$ , $\text{Me}_2\text{SiH}^+$
58	14	$\text{EtSiH}^+$ , $\text{Me}_2\text{Si}^+$
57	8	$\text{EtSi}^+$
55	7	
53	8	
46	12	$\text{MeSiH}_3^+$
45	<u>100</u>	$\text{MeSiH}_2^+$
44	76	$\text{MeSiH}^+$
43	42	$\text{MeSi}^+$
42	16	
41	5	
31	17	$\text{SiH}_3^+$
29	16	
28	16	
27	13	
15	5	

<sup>a</sup> Ionization voltage of ca 70 volts; the peaks with a relative intensity of less than 5% of the base peak (100) were omitted.



APPENDIX II  
MASS SPECTRUM OF DIMETHYLETHYLSILANE

m/e	Relative Intensity <sup>a</sup>	Postulated Ion
88	4	$\text{Me}_2\text{EtSiH}^+$
87	15	$\text{Me}_2\text{EtSi}^+$
73	26	$\text{MeEtSiH}^+$
72	7	$\text{MeEtSi}^+$
60	11	$\text{Me}_2\text{SiH}_2^+$
59	<u>100</u>	$\text{Me}_2\text{SiH}^+$ , $\text{EtSiH}_2^+$
58	35	$\text{Me}_2\text{Si}^+$ , $\text{EtSiH}^+$
54	9	
45	42	$\text{MeSiH}_2^+$
44	8	$\text{MeSiH}^+$
43	24	$\text{MeSi}^+$
42	7	
31	10	$\text{SiH}_3^+$
29	8	
28	5	

<sup>a</sup> Ionization voltage of ca 70 volts; the peaks with a relative intensity of less than 5% of the base peak (100 were omitted.



## APPENDIX III

## CORRECTION PROCEDURE FOR DECOMPOSITION OF POLYMER

The polymer formed in the pyrolysis of monomethylsilane is thermally unstable and decomposes slowly to yield hydrogen and methane as major products. The rate of decomposition increases with the extent of polymer deposition and the observed hydrogen yields from the pyrolysis of monomethylsilane must therefore be corrected for degassing of the polymer. The correction procedure is illustrated in Figure AIII-1.





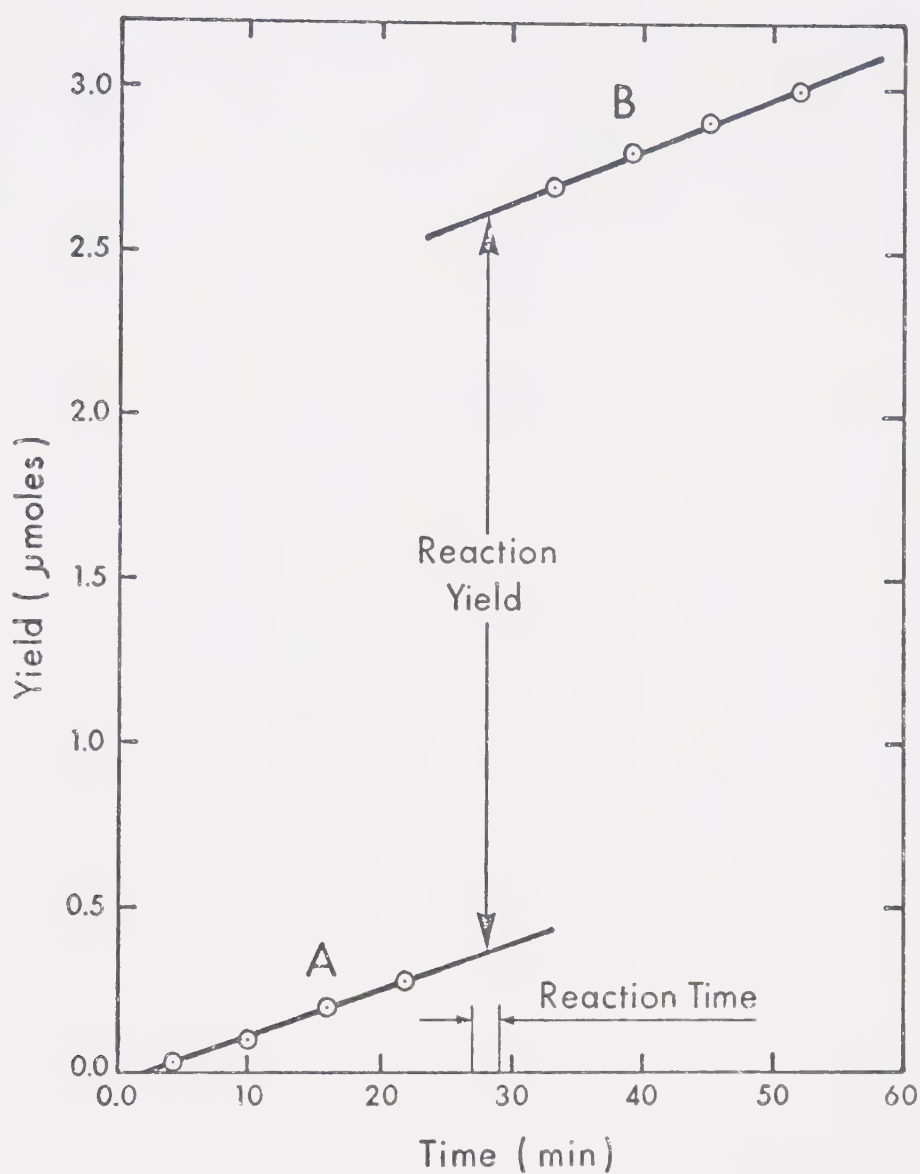


Figure AIII-1. Correction of the Observed  $H_2$  Yields for Decomposition of the Polymer.  
 A-degassing before the experiment,  
 B-after the experiment.  
 The difference between A and B at the midpoint of the reaction time corresponds to the actual yield.















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